

# **Solution-processed semiconductor oxide photoelectrodes for solar fuel production**

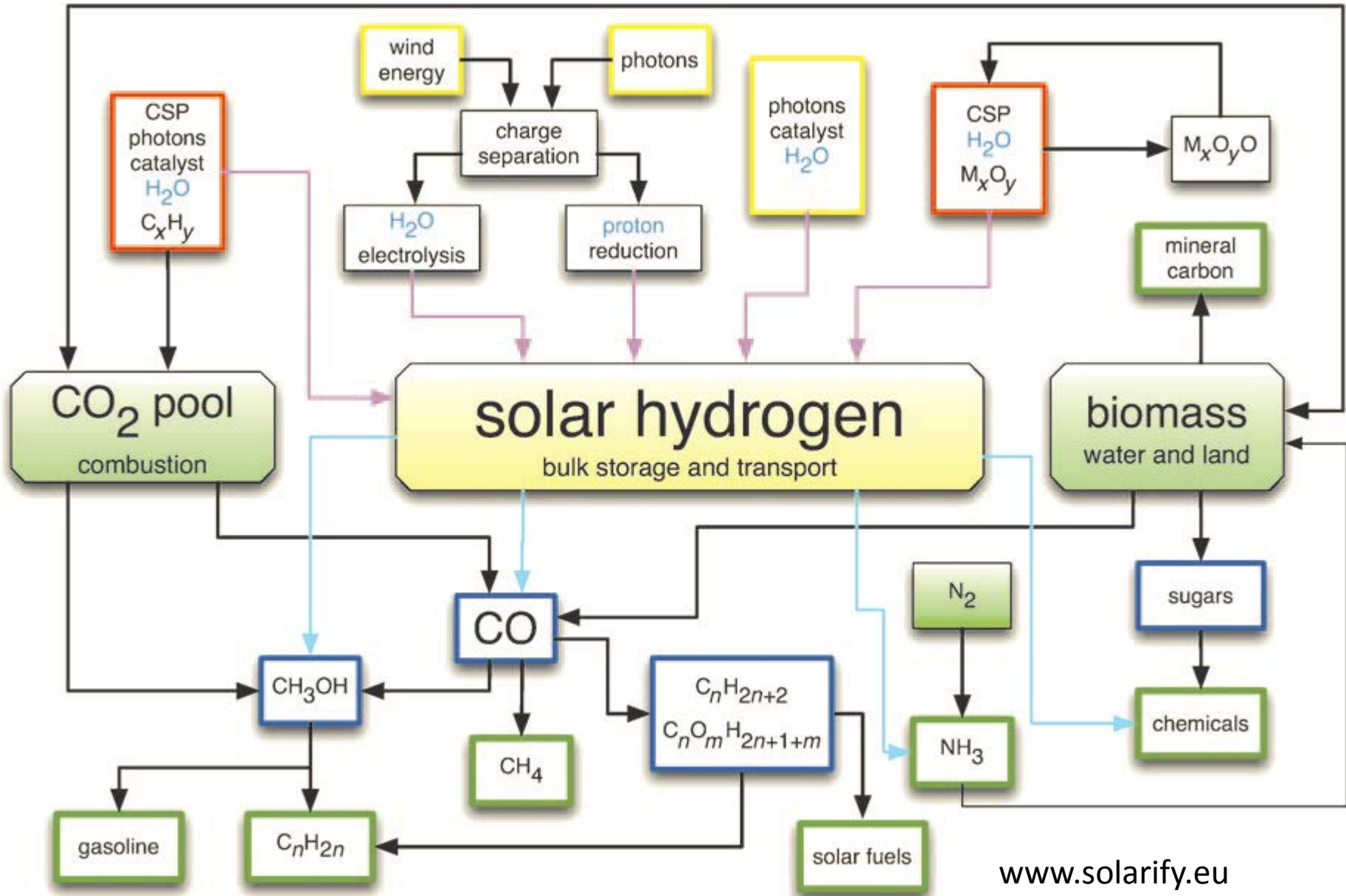
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École Polytechnique Fédérale de Lausanne

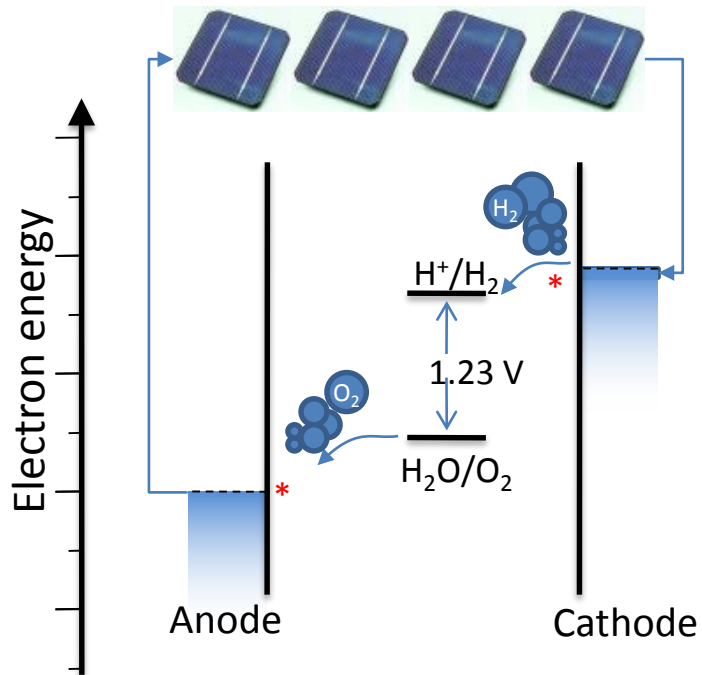
20 May 2014, ICTP Workshop, Trieste

# Chemical storage of solar energy



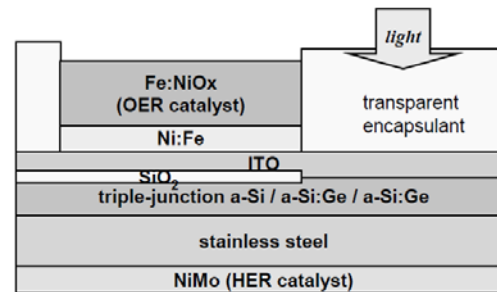
# Technologies for Solar-to-chemical conversion

- Traditional photovoltaic + electrolyzer

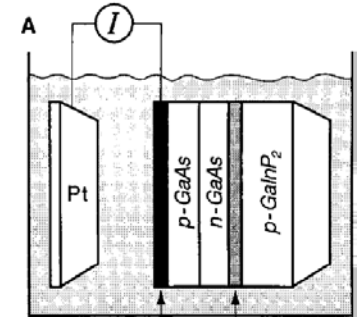


- Limited by price, availability of traditional photovoltaics
- Voltage output of Si PV strongly dependent on irradiation intensity
- Up to 50% energy loss
- Current cost under ideal conditions:  
~\$10/kg H<sub>2</sub> (Si PV costs ~\$200-300/m<sup>2</sup>)

- Direct water decomposition using a photoelectrochemical (PEC) device



Solar-to-Hydrogen  
efficiency = 7.8%



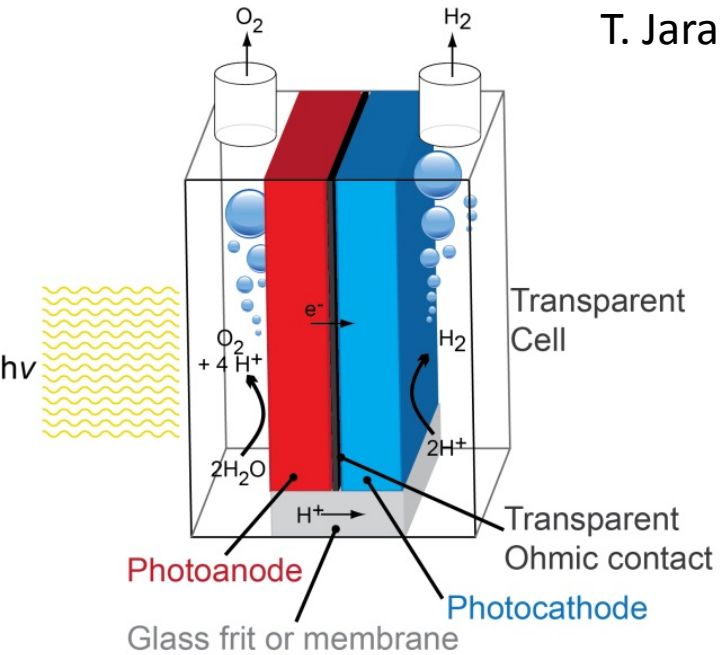
Solar-to-hydrogen  
efficiency = 12-16%

R. E. Rocheleau, E. L. Miller and A. Misra, *Energy and Fuels*, 1998, **12**, 3-10.

O. Khaselev, J. Turner. *Science*, **1997**, 280, 425.

D. G. Nocera, and coworkers *Science*, **2011**.

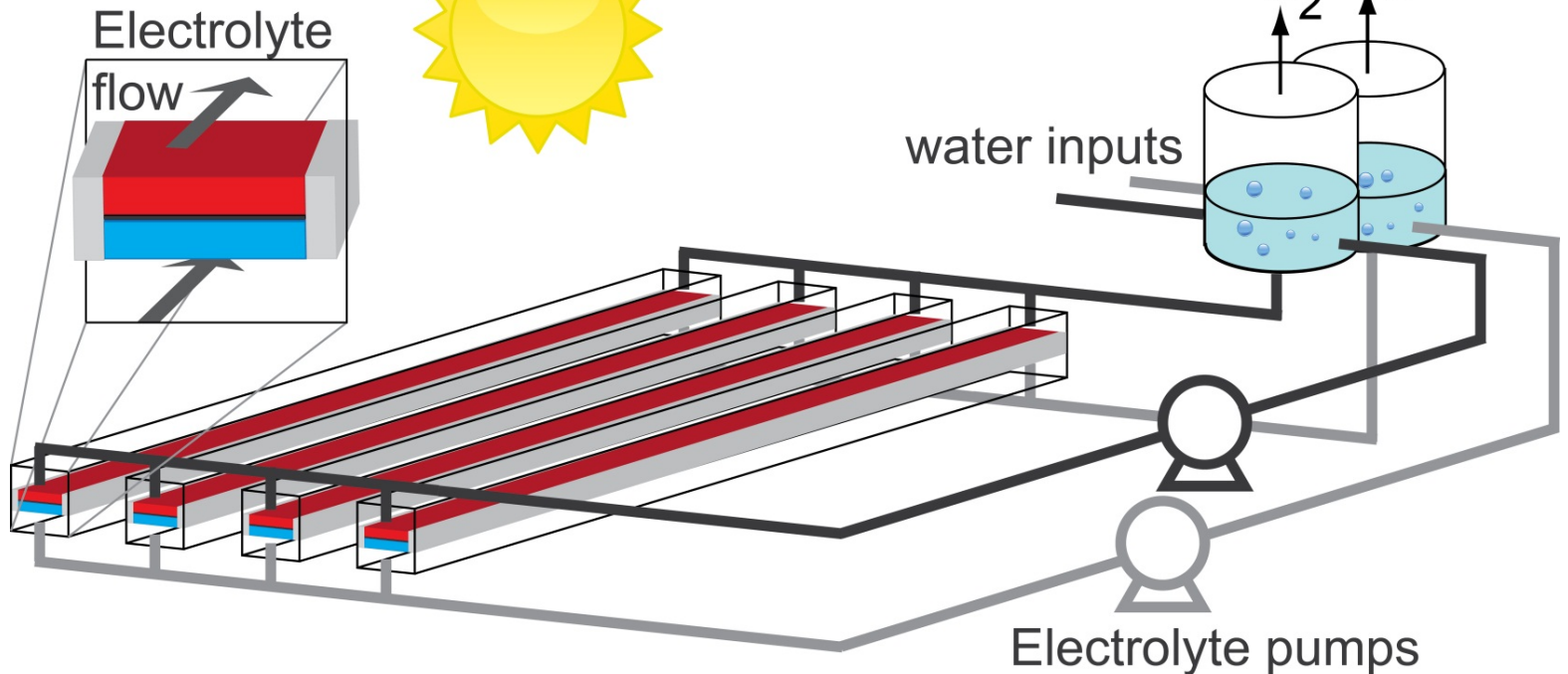
- A direct semiconductor-liquid junction reduces losses and can increase conversion efficiency
- promising performance demonstrations have been achieved
- Remaining challenges are to meet cost competitiveness with traditional approach
- \$10/kg H<sub>2</sub> ~ 10% efficiency, 10 year lifetime and \$100/m<sup>2</sup>



Net production (kg H <sub>2</sub> per day, yearly average)	1000
PEC cell efficiency (solar to hydrogen %)	10 %
Cost of PEC cell (per m <sup>2</sup> )	153 USD\$
PEC cell lifetime (years)	10

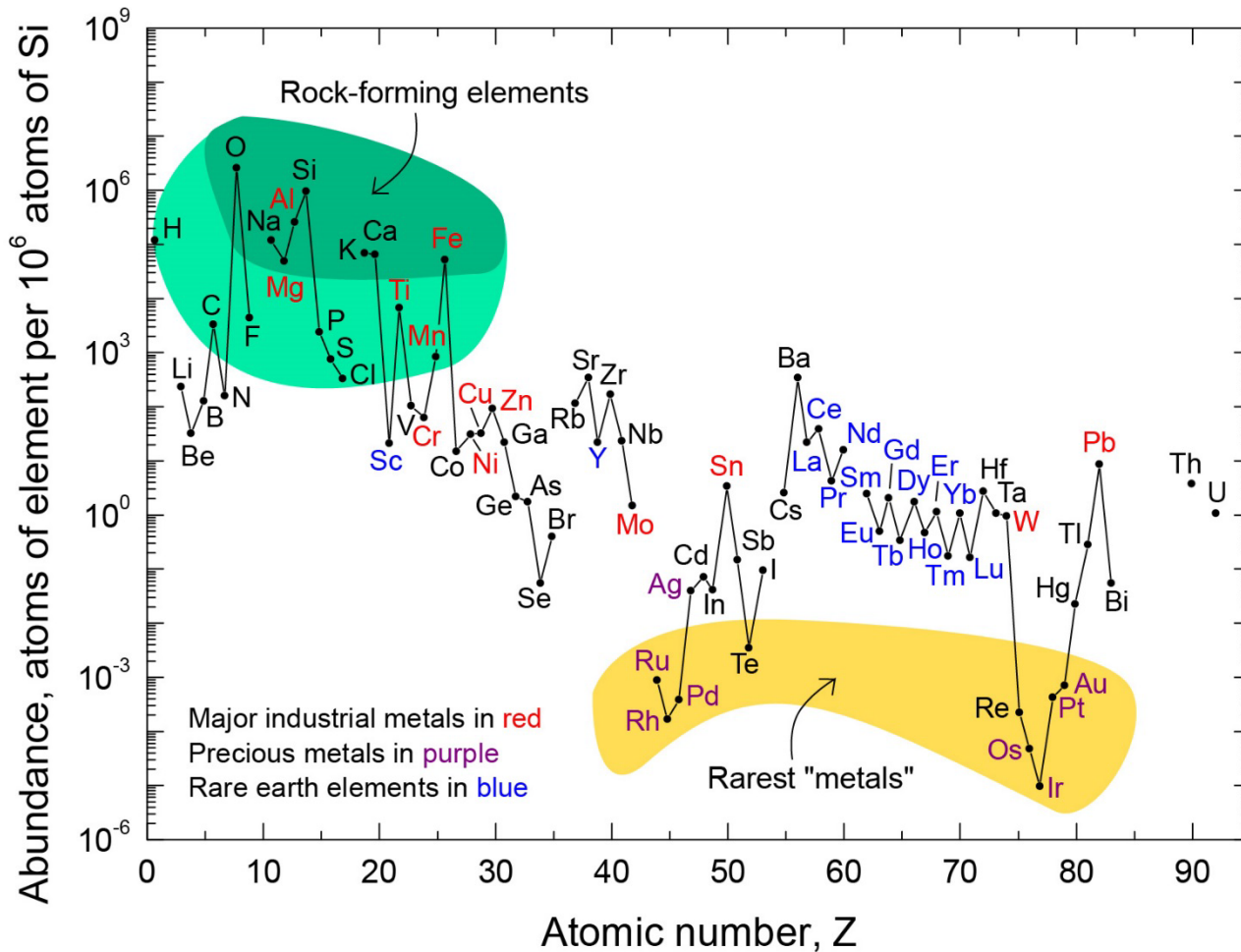


**Cost of H<sub>2</sub> produced 10.40 \$/kg**





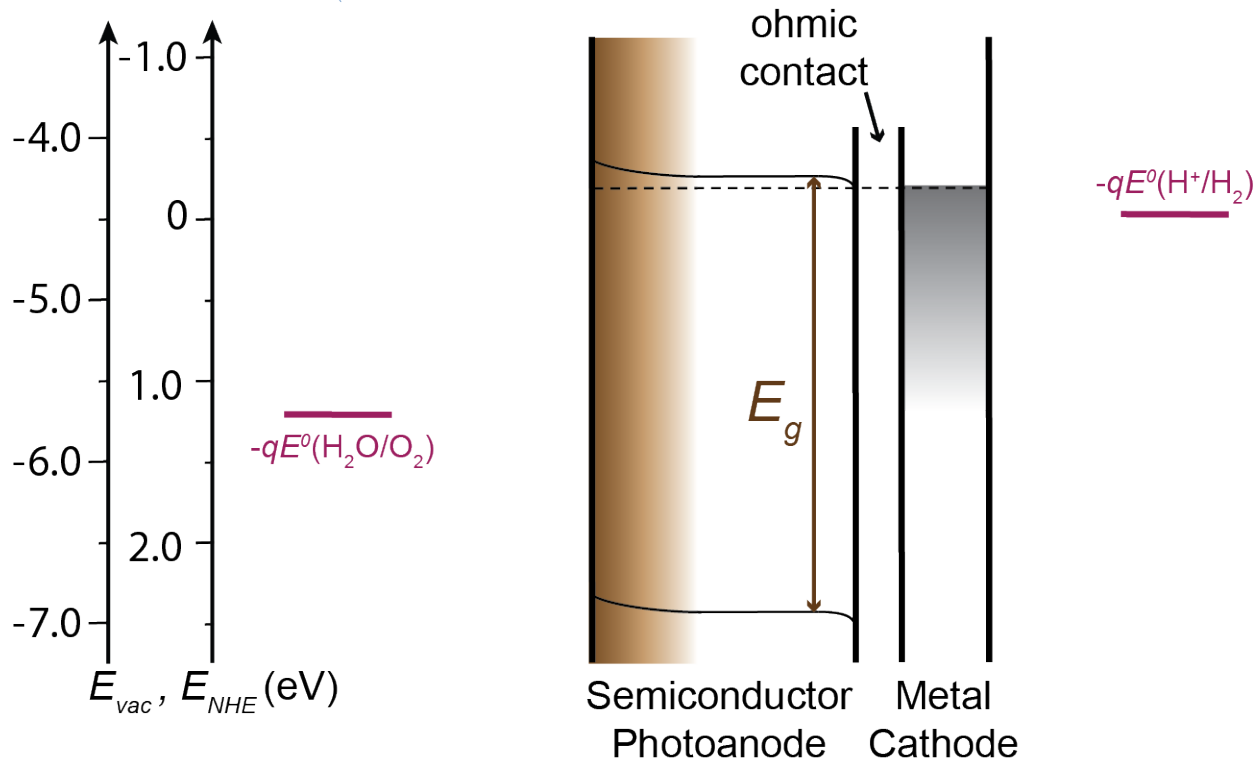
# Strategy for inexpensive PEC cells



Solution based  
processing  
Cost = \$10/m<sup>2</sup>

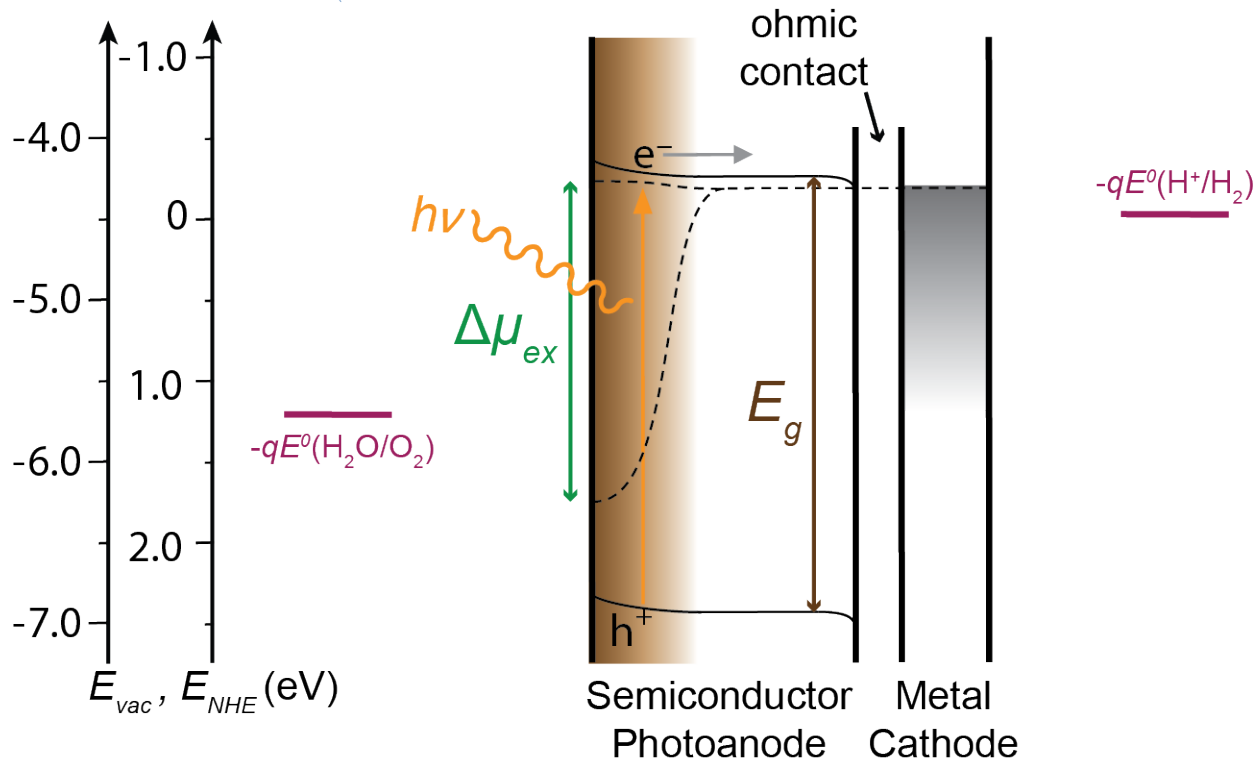
# Chemical storage of solar energy

- The brute force approach
- The direct water decomposition using photoelectrochemistry
- The integrated tandem cell approach



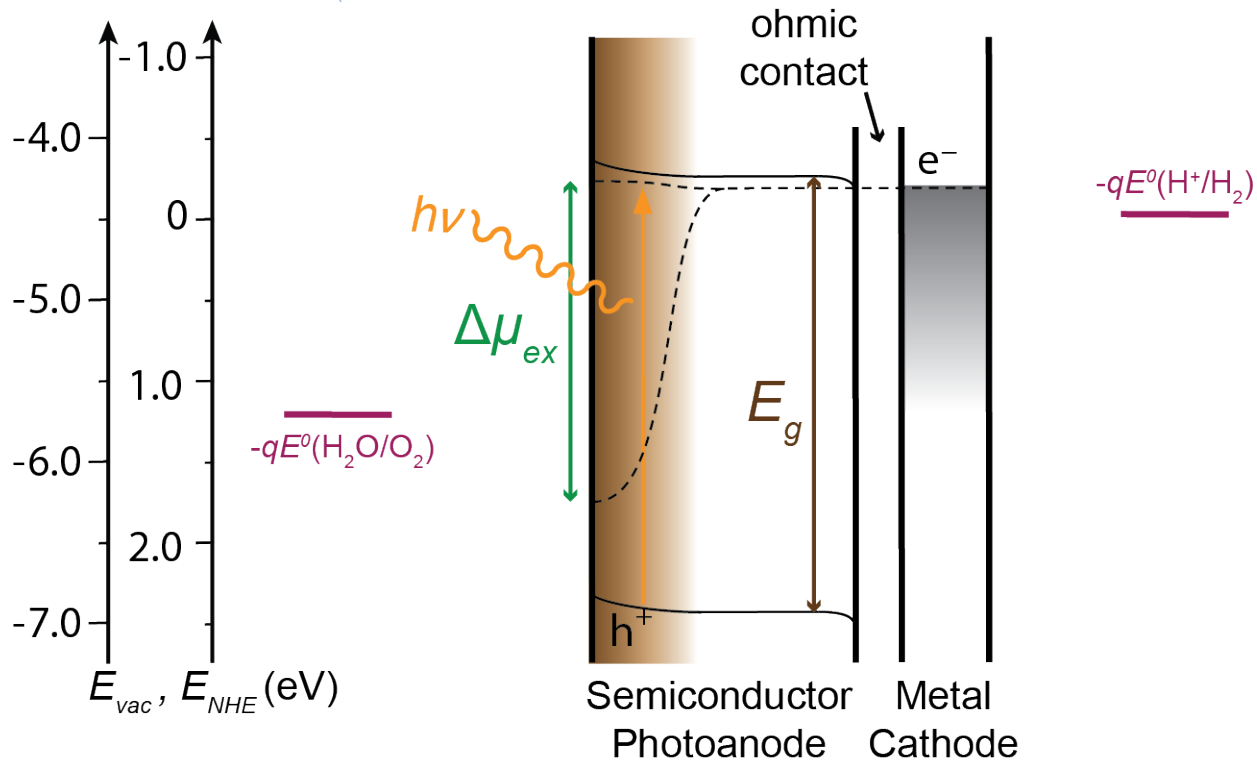
# Chemical storage of solar energy

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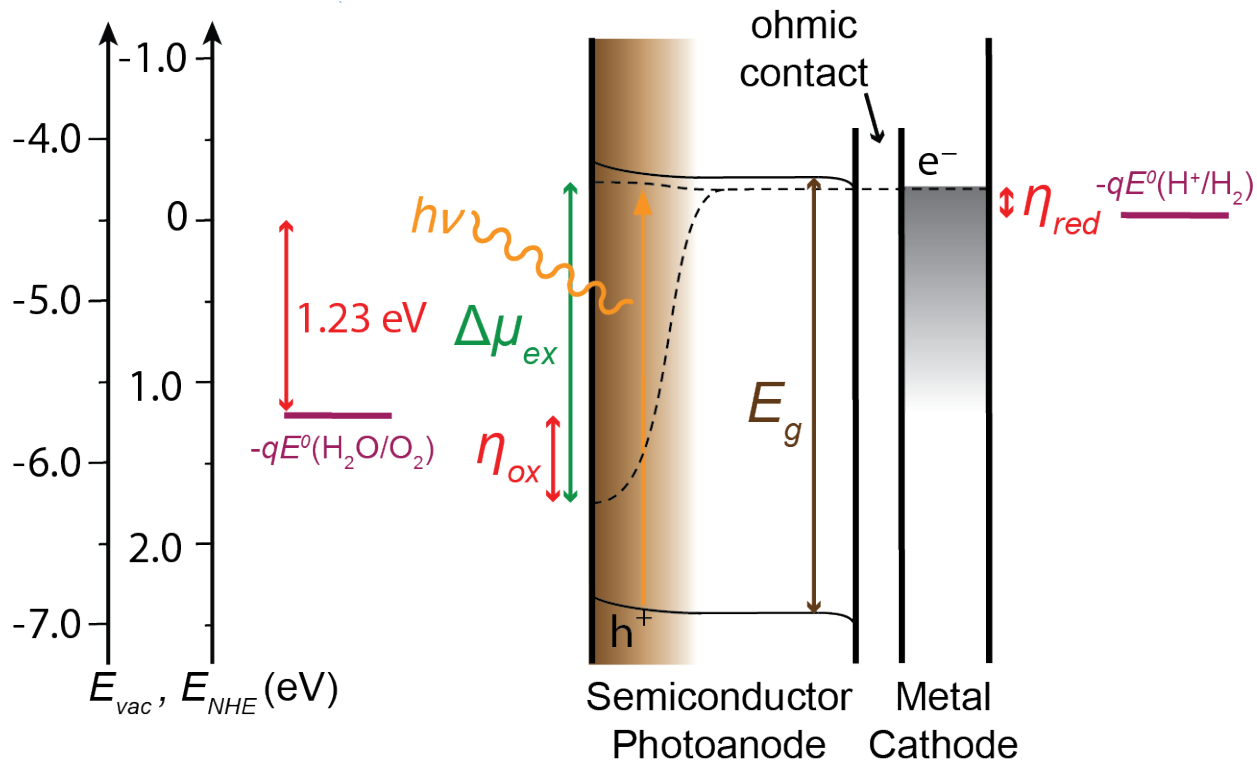
# Chemical storage of solar energy

- The brute force approach
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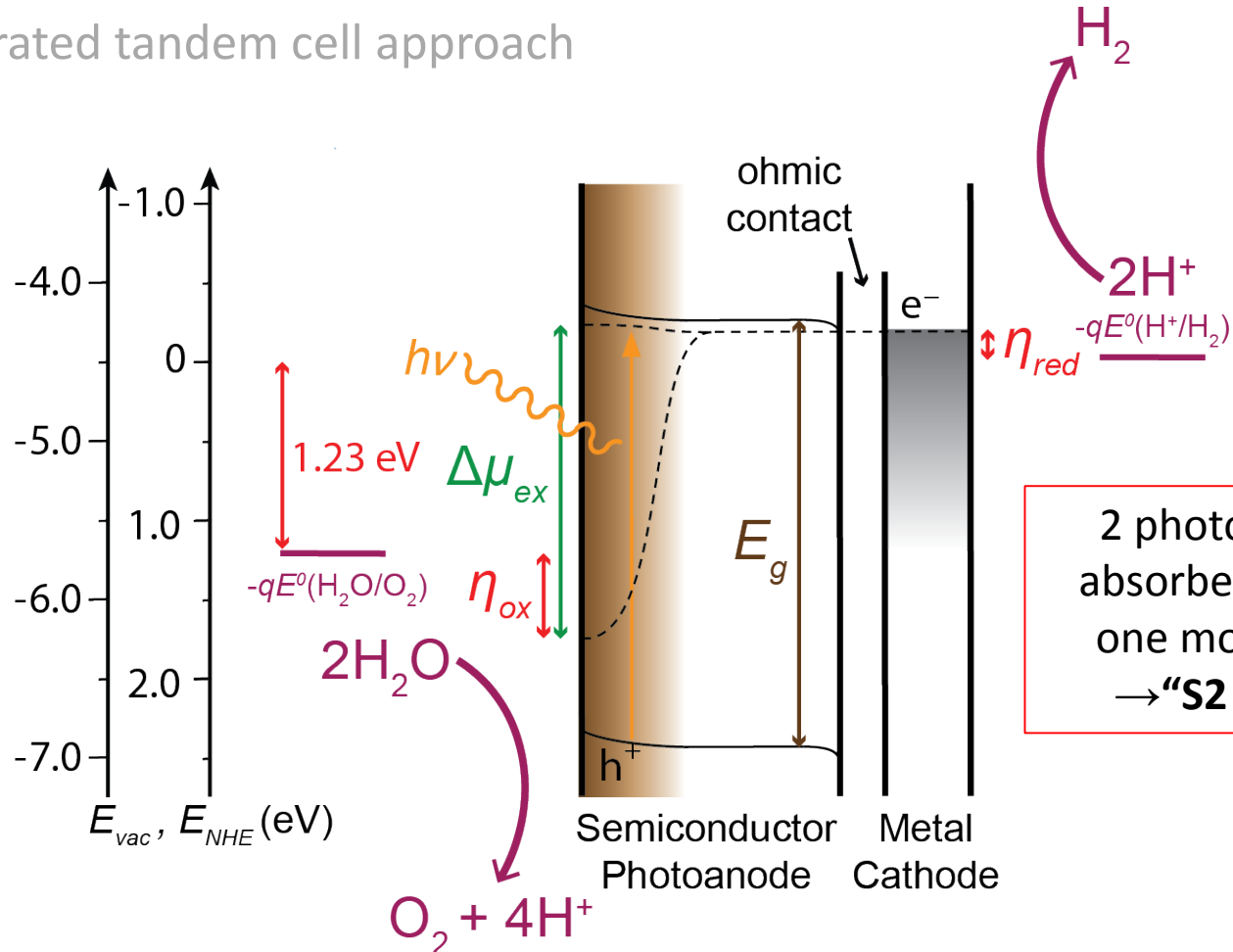
# Chemical storage of solar energy

- The brute force approach
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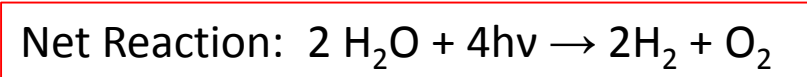


# Chemical storage of solar energy

- The brute force approach
- The direct water decomposition using photoelectrochemistry
- The integrated tandem cell approach

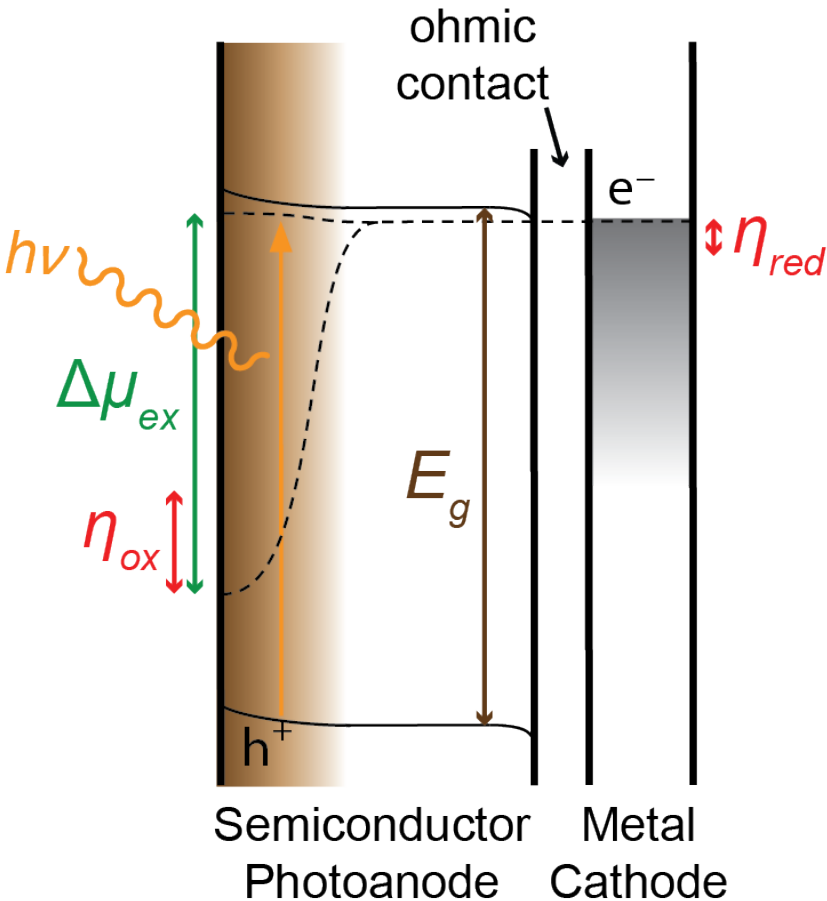


2 photons must be absorbed to produce one molecule of  $H_2$   
→ "S2 approach"





# Limitations of the S2 approach



Under 1 sun illumination:

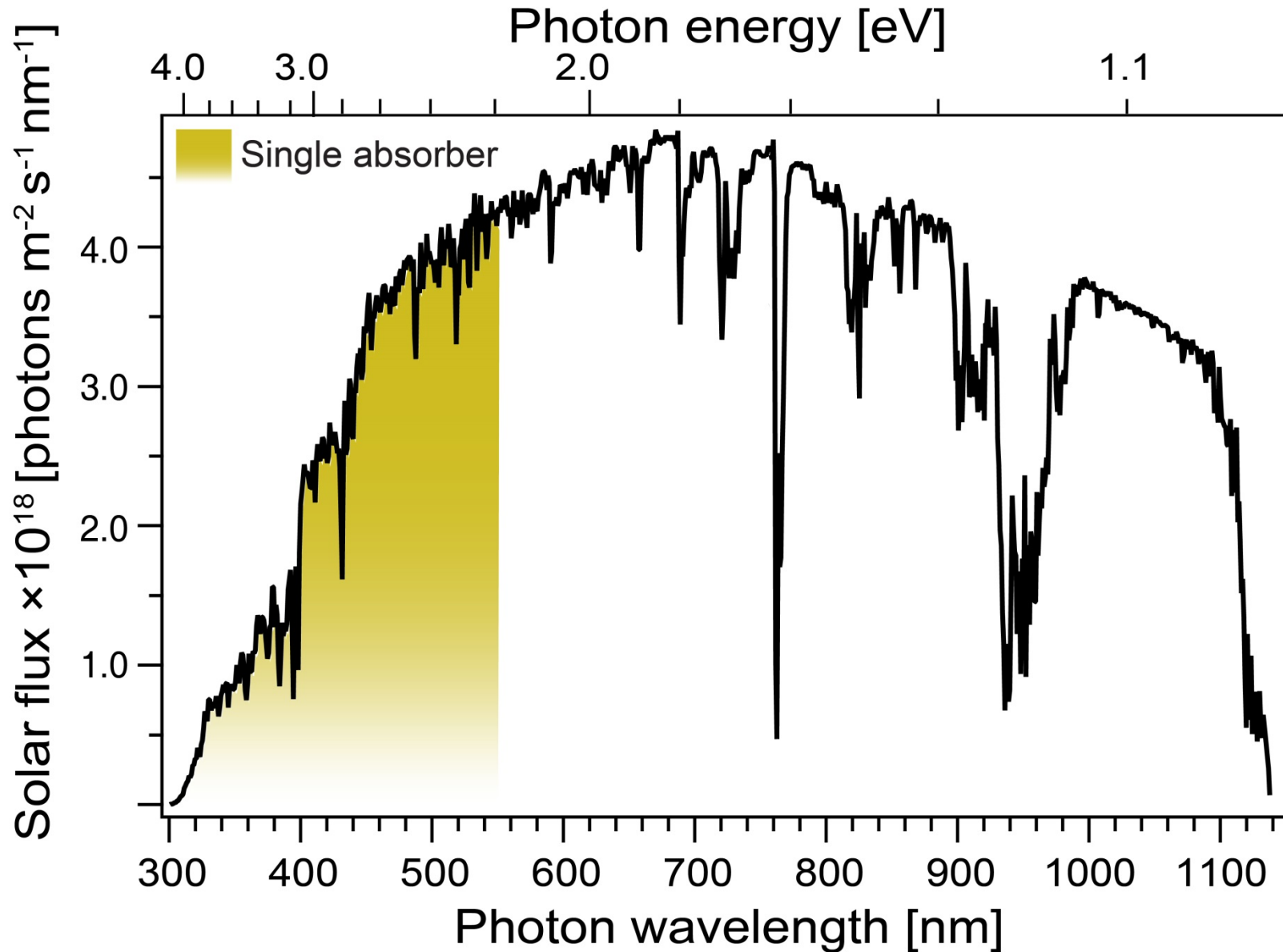
$$\Delta\mu_{ex} \approx 0.75 E_g.$$

$\eta_{ox}$  is large (0.2 – 0.4 eV) for  
ca.  $10 \text{ mA cm}^{-2}$

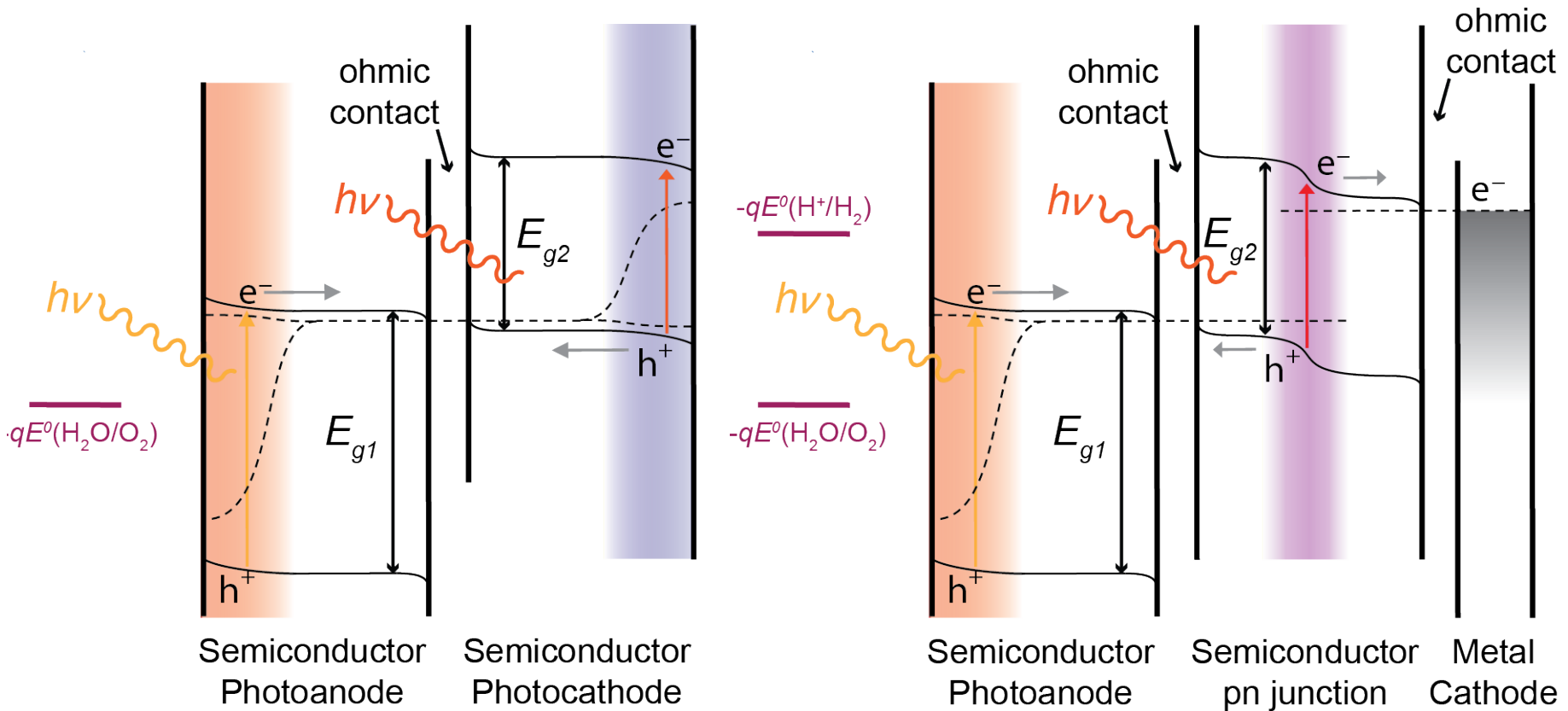
$U_{loss}$  can be up to 1.0 eV per  
photon

**Maximum Solar to hydrogen  
conversion efficiency (STH) is  
12.7 % (with  $E_g = 2.23 \text{ eV}$ )**

# Limitations of the S2 approach



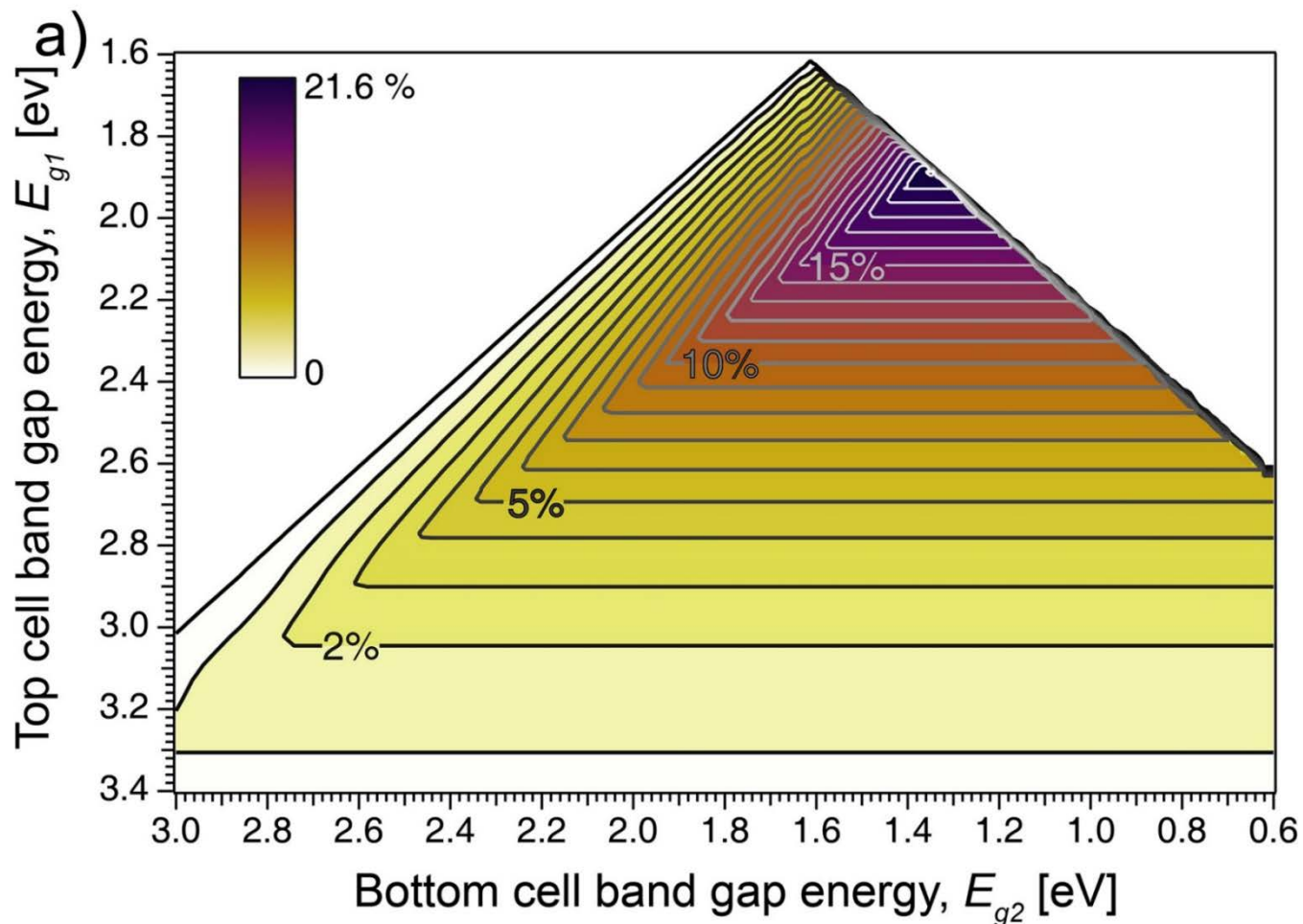
# Tandem cell approach



4 photons must be absorbed to produce one molecule of  $\text{H}_2$   
 → "D4 approach"

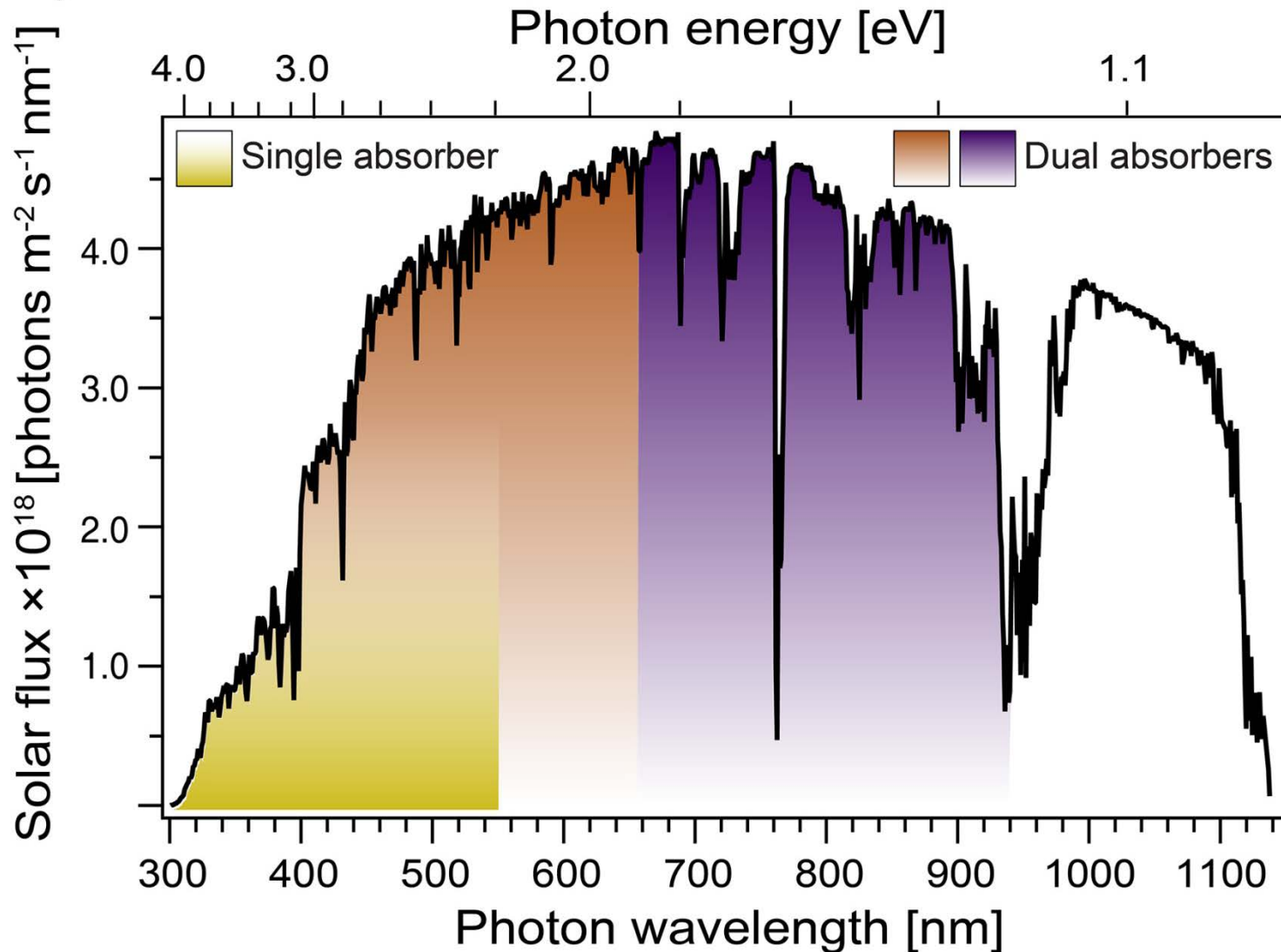
# Limitations of the D4 approach

Assumption of 1.0 eV per photon energy loss



# Limitations of the D4 approach

Using similar assumption of  $U_{loss}$  can be up to 1.0 eV per photon

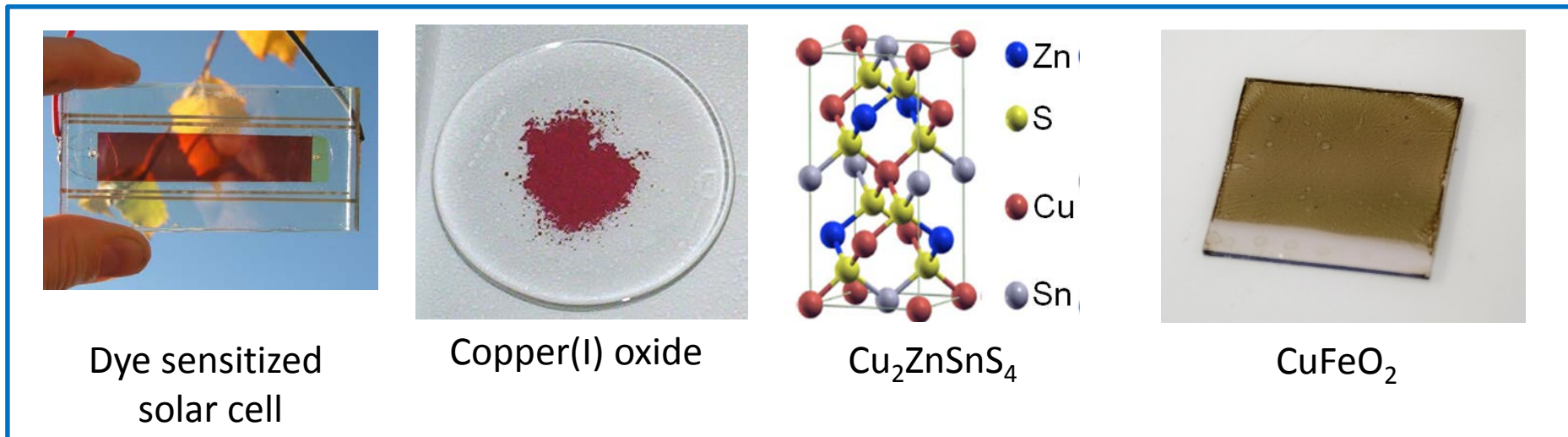


# Materials for the tandem cell

## Photoanode



## Photocathode





# $\alpha\text{-Fe}_2\text{O}_3$ (hematite) as a promising material

## Advantages

Cheap and abundant

Stable

Environmentally benign

Absorbs over 16 % of AM1.5 solar spectrum



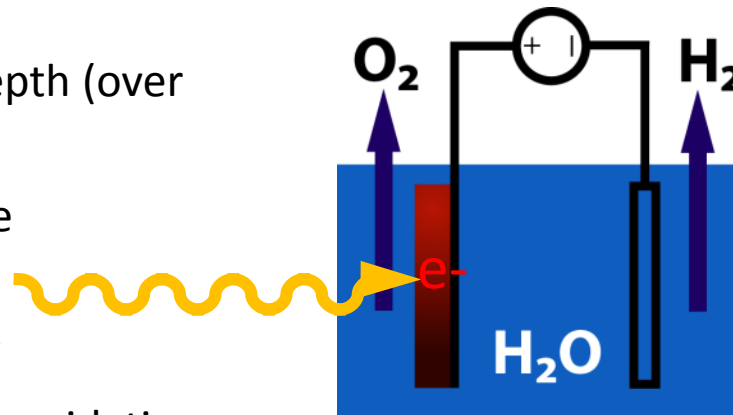
## Challenges

Long photon penetration depth (over 100 nm @ 500 nm)

Short hole diffusion distance ( $L_D = 5$  nm)

Poor electronic conductivity

High overpotential for water oxidation



12.6 mA/cm<sup>2</sup>  
Possible

0.5 mA/cm<sup>2</sup>  
Observed\*

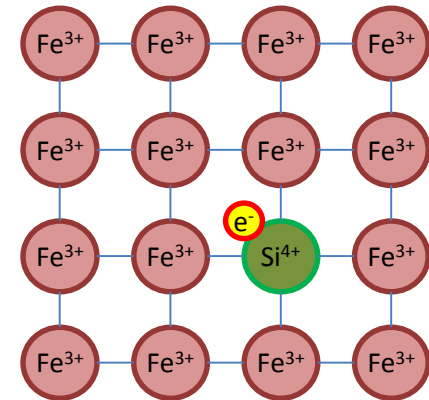
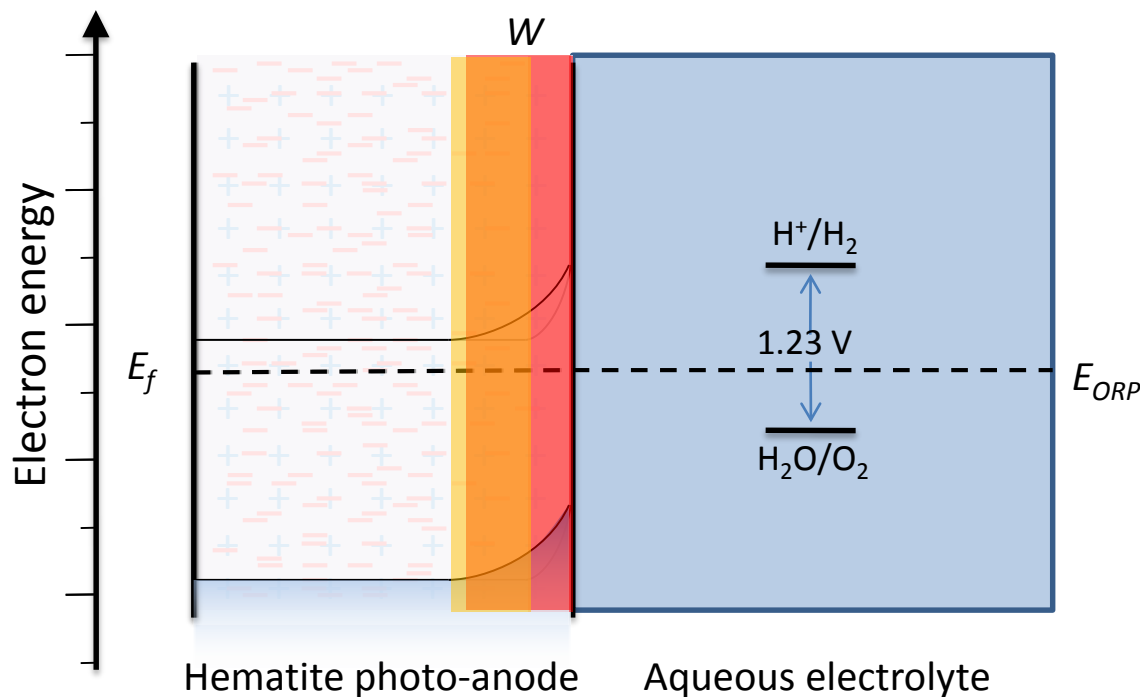
Single Crystal  
Hematite photoanode

\*Sanchez, et al., *J. Electroanal. Chem.* **1988**, 252, 269-290.

# Overcoming challenges of hematite

**Challenge:** Poor electronic conductivity

**Resolution:** Aggressive substitutional doping



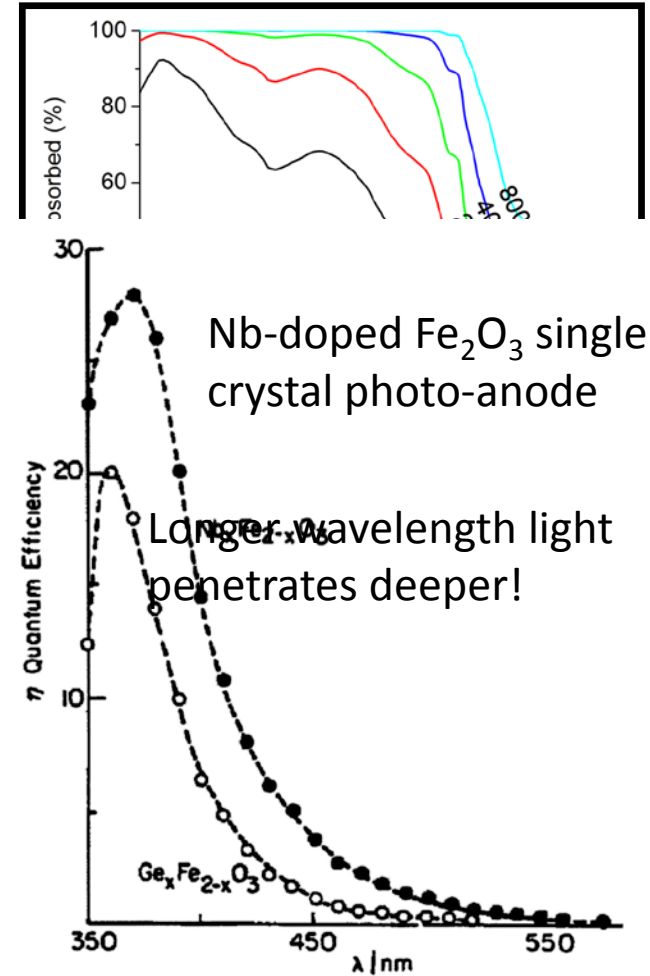
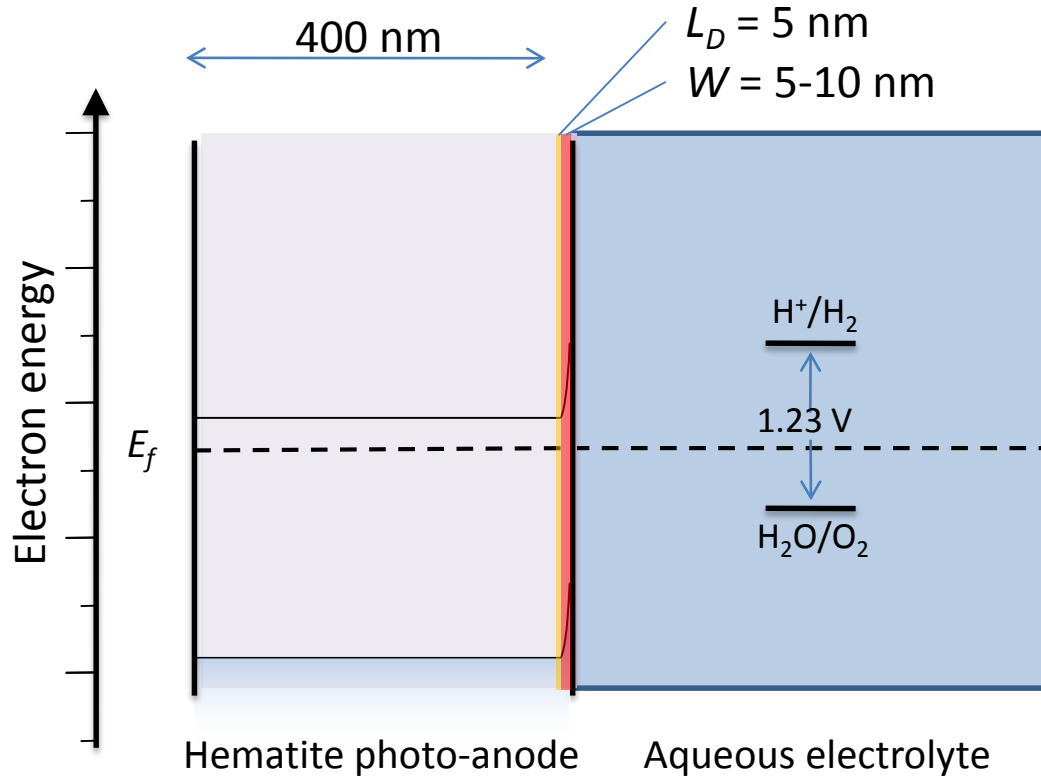
$$W = \sqrt{\frac{2\varepsilon\varepsilon_0(V - V_{fb})}{qN_d}}$$

$$L_d = \sqrt{D\tau}$$

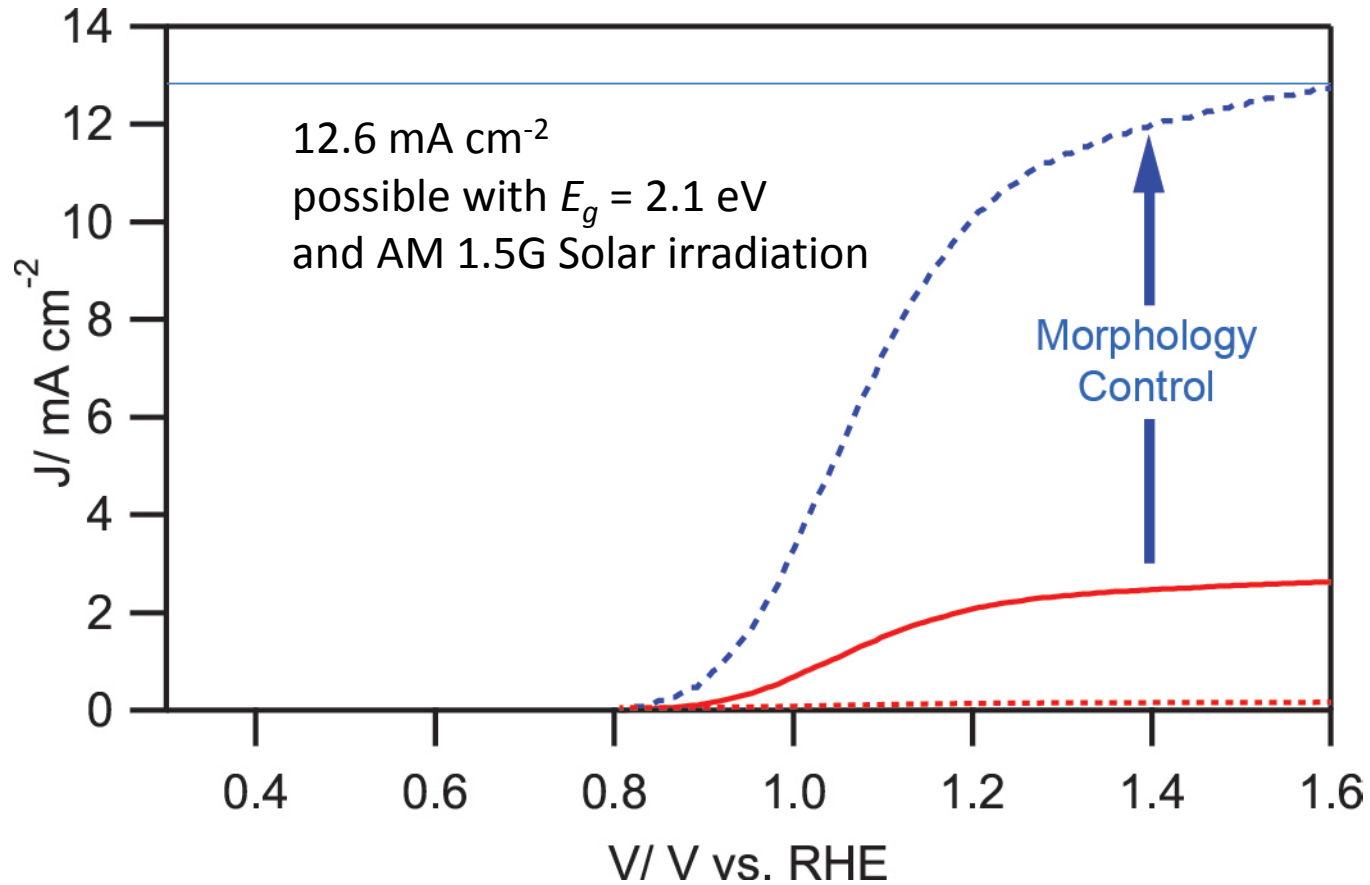
# Overcoming challenges of hematite

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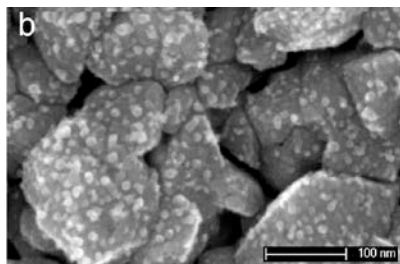
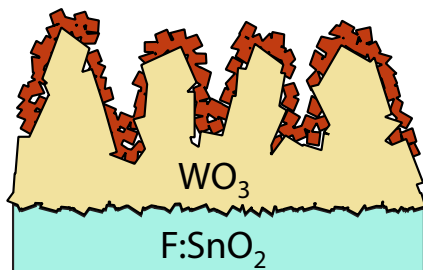


# A strategy for improvement

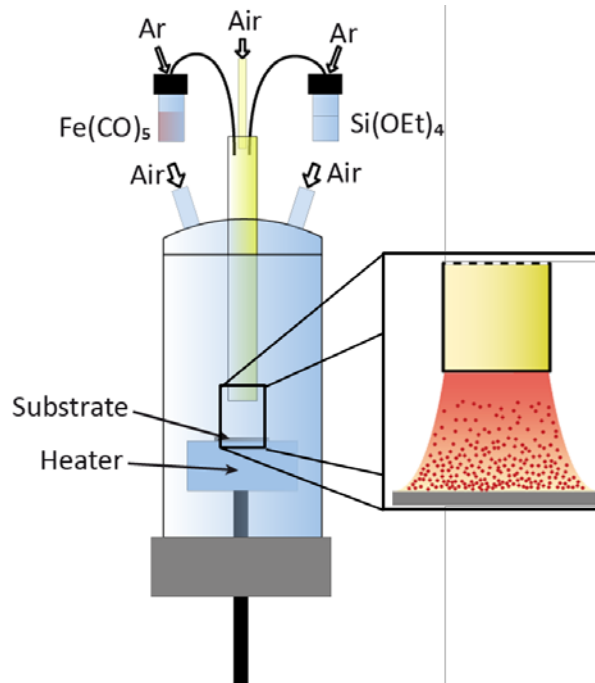


# Nanostructuring approaches for Fe<sub>2</sub>O<sub>3</sub>

## Extremely thin absorber (ETA) approach

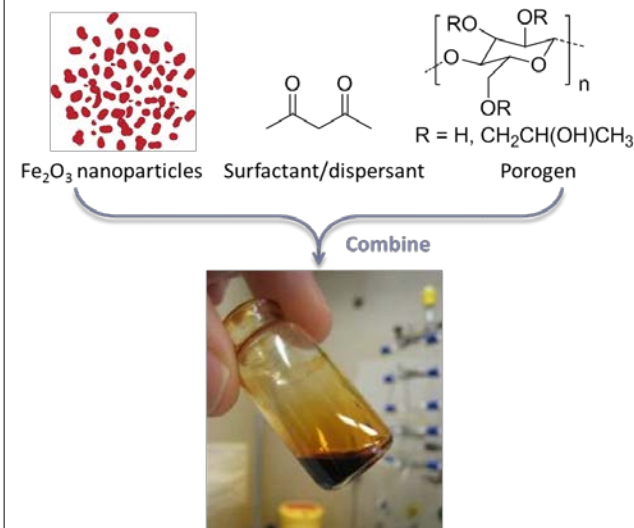


## Atmospheric pressure chemical vapor deposition.



**Optimization of residence time**  
*Angew. Chem.* **2010**, *49*, 6405.  
**Preferential orientation**  
*Chem. Vap. Dep.* **2010**, *16*, 291  
**Identification of champion nanostructures**  
*Nature mater.* **2013**, *12*, 842

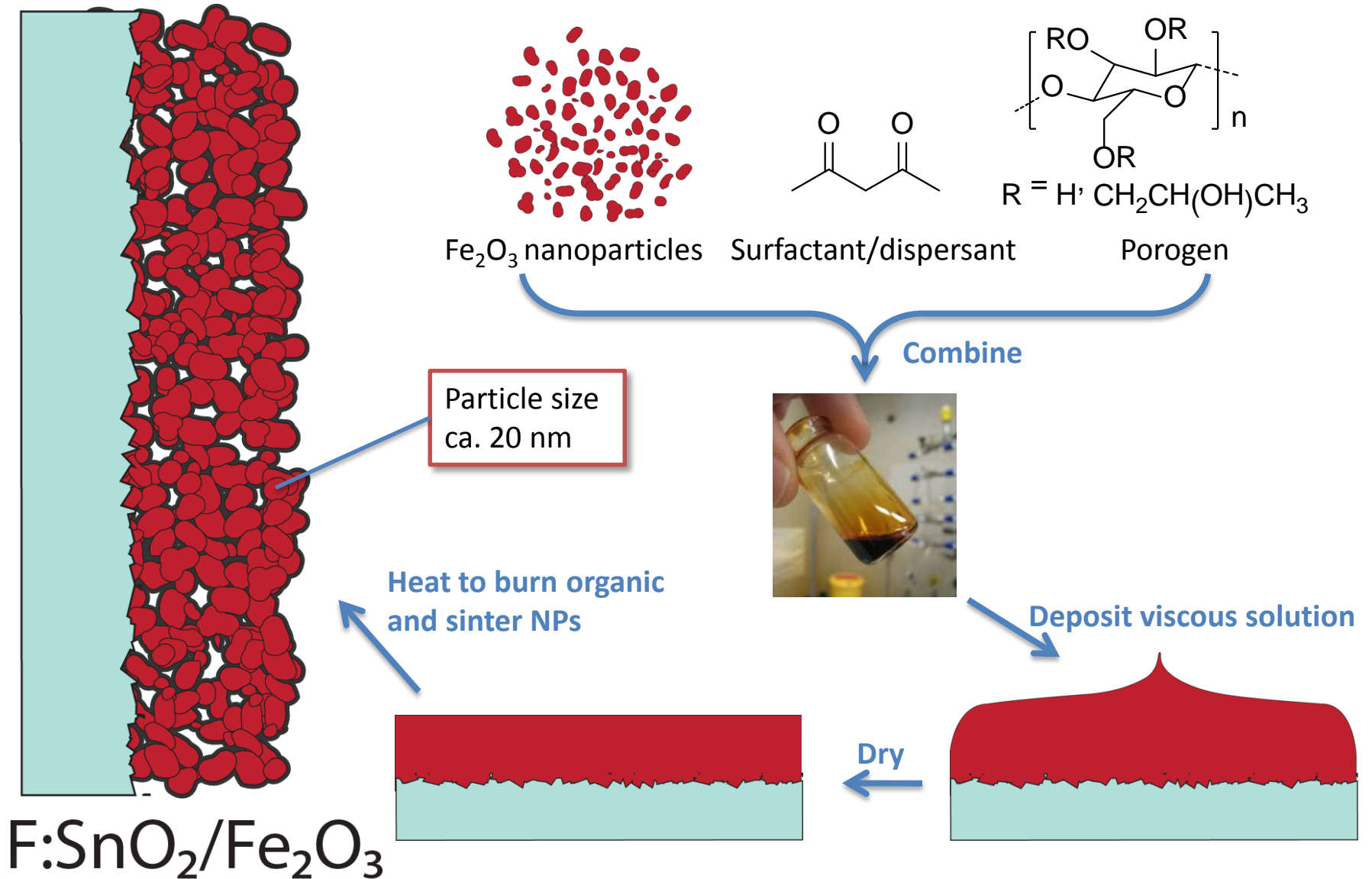
## Mesoporous films by colloidal approach



**Activation of dopant atoms**  
*J. Am. Chem. Soc.* **2010**, *132*, 7436.  
**New strategy to control feature size**  
*Nano Lett.* **2010**, *10*, 4155-4160.  
**Low Temperature Sn<sup>4+</sup> activation**  
*J. Mater. Chem.* **2012**, *22*, 23232.

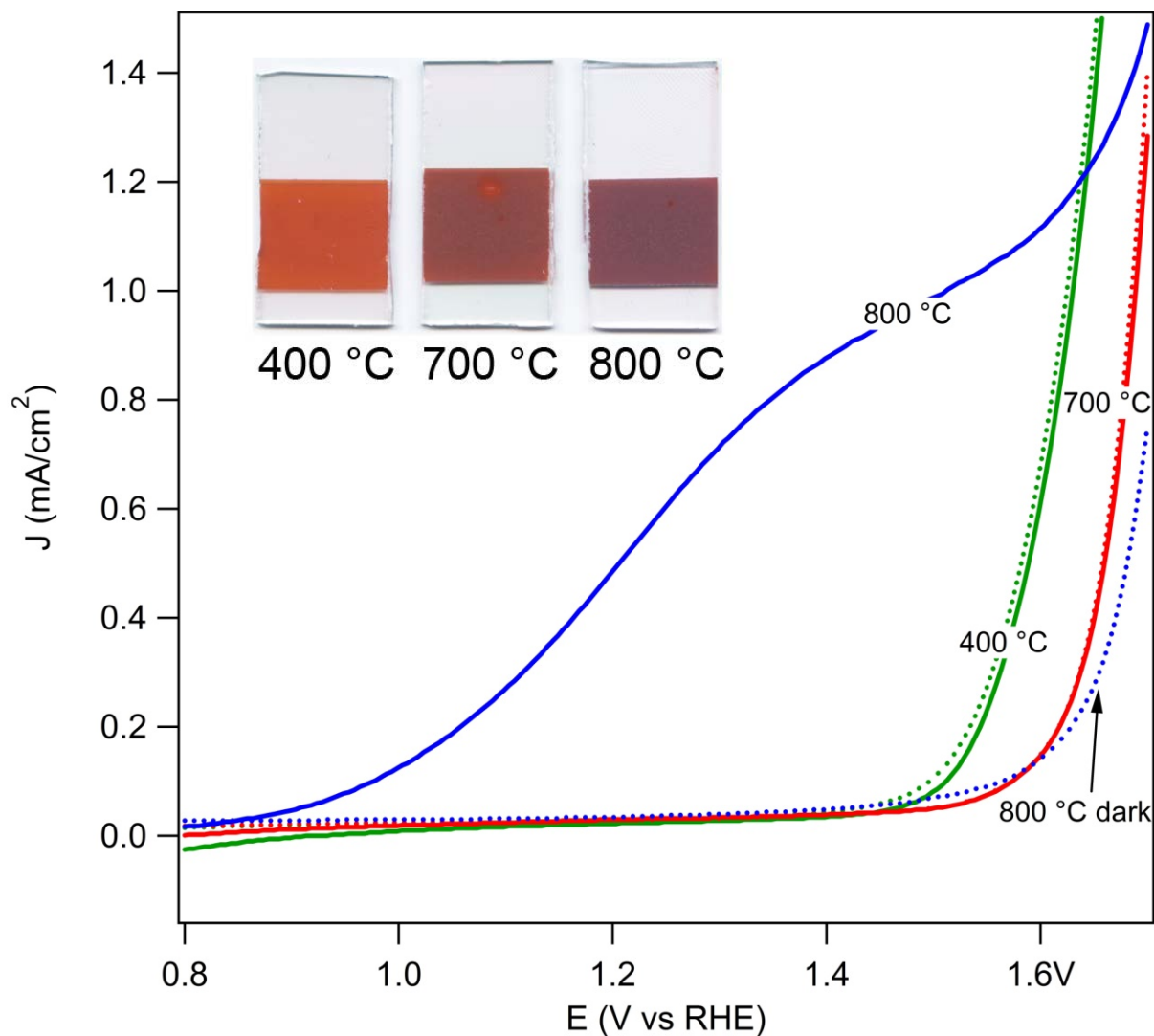
**Demonstration with WO<sub>3</sub> scaffold**  
*Chem. Mater.* **2009**, *21*, 2862.  
**Employing buffer layers to enhance performance**  
*Adv. Funct. Mater.* **2010**, *20*, 1099.  
*Adv. Mater.* **2012**, *24*, 2699.  
**Nb:SnO<sub>2</sub> Host**  
*Nano Lett.* **2012**, *12*, 5431.

# Mesoporous films by colloidal approach

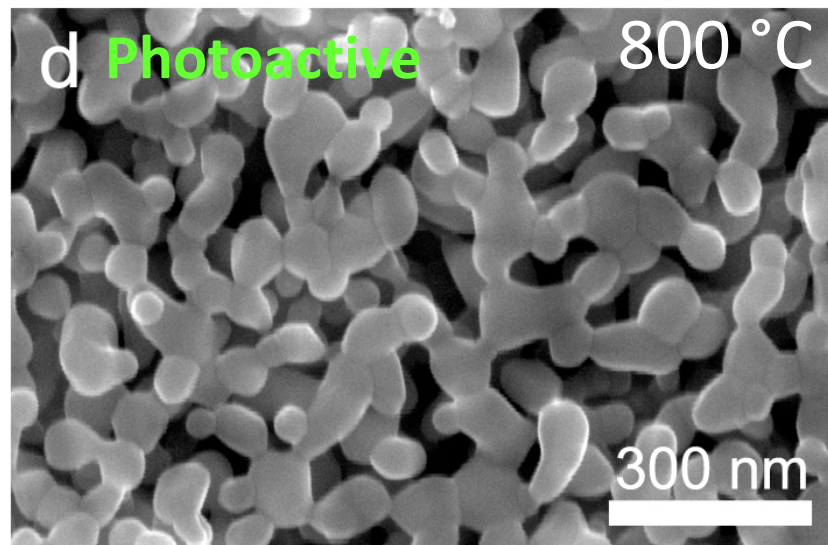
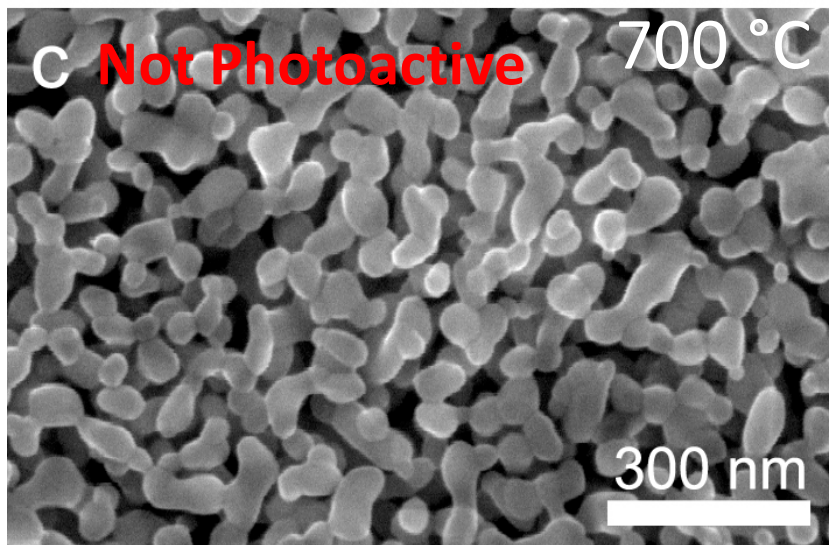
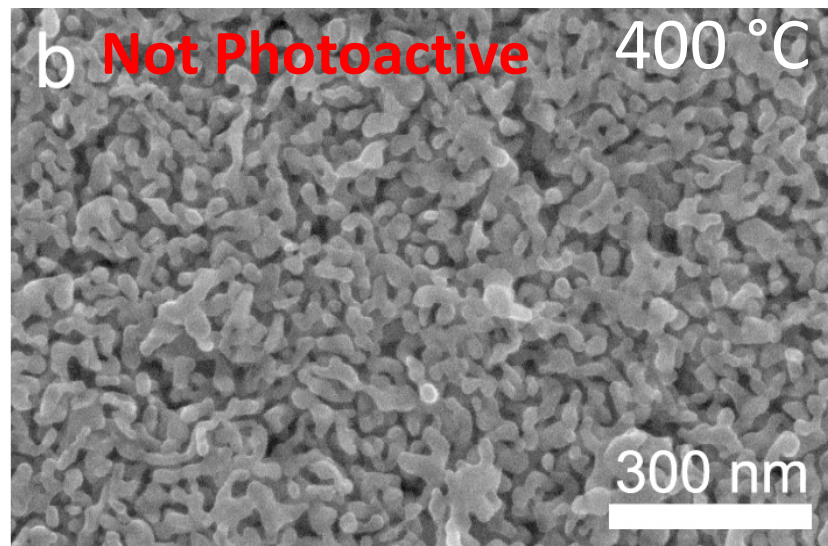
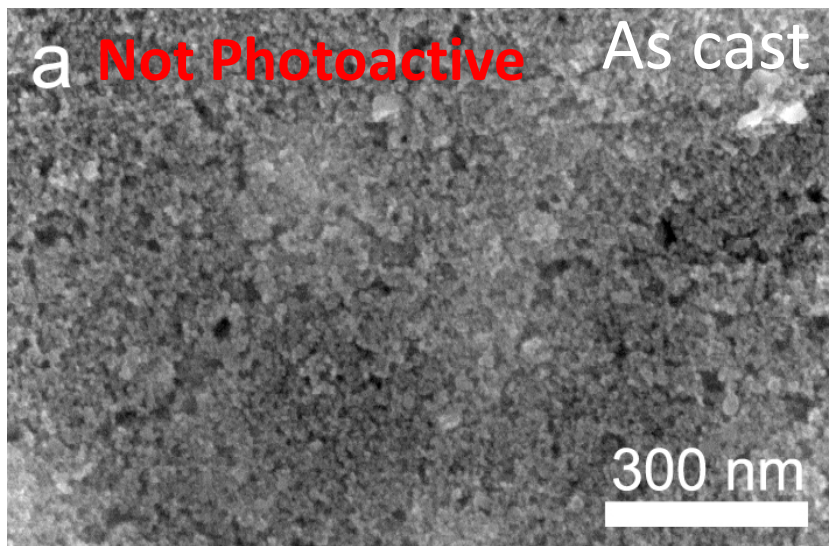




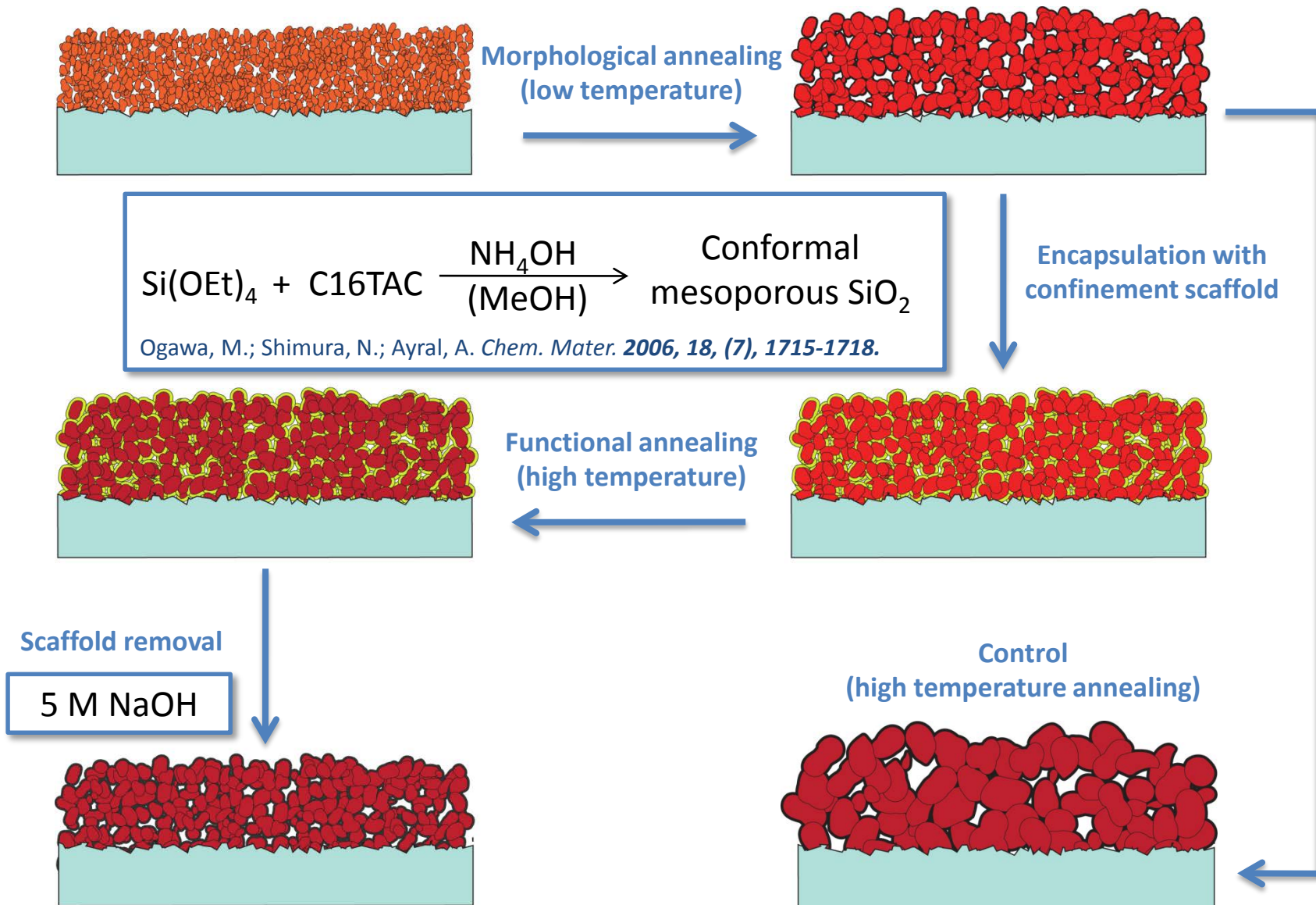
# High temp sintering induces photo-activity



# Mesoporous morphology



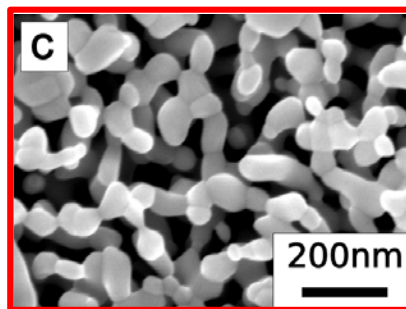
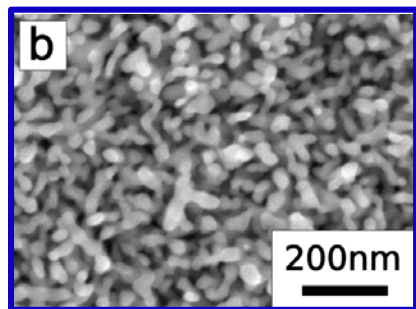
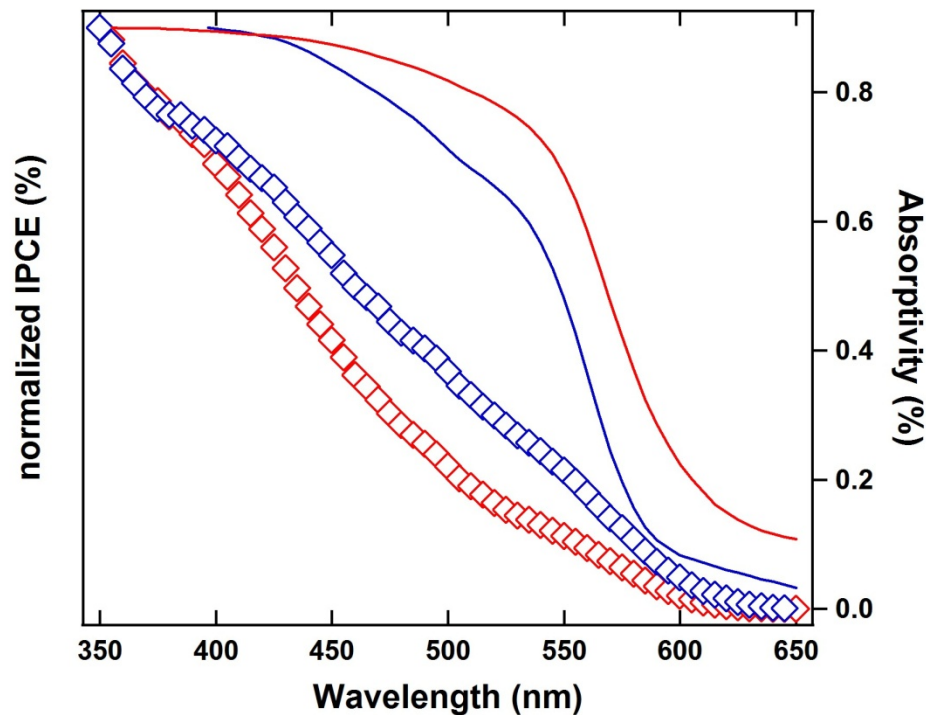
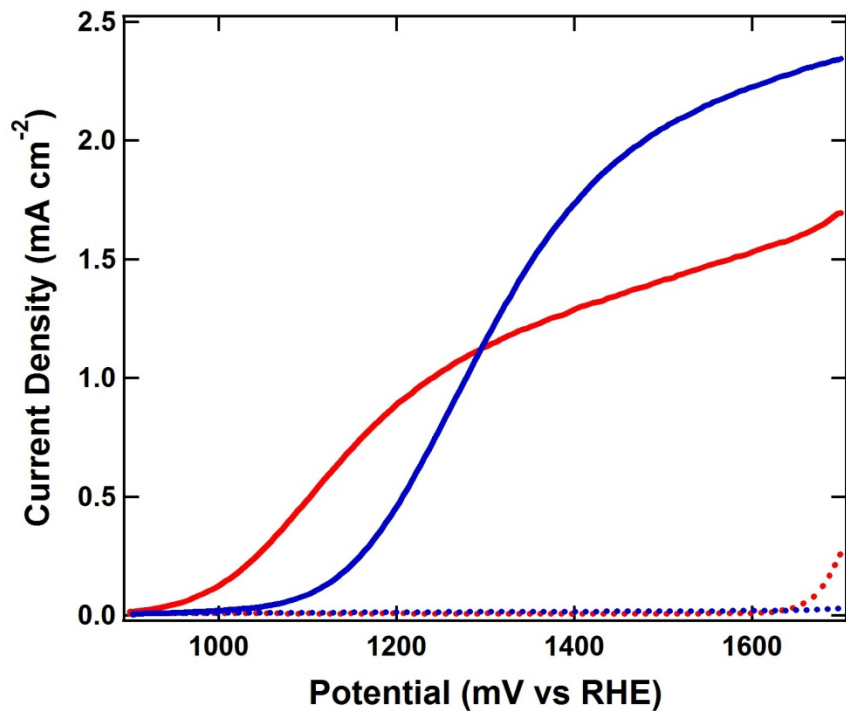
# New confinement strategy

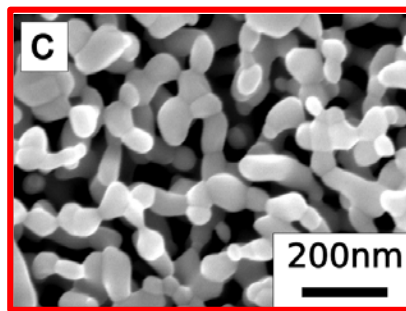
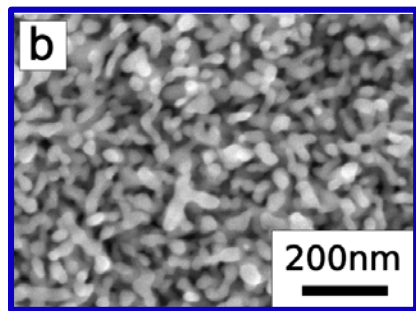
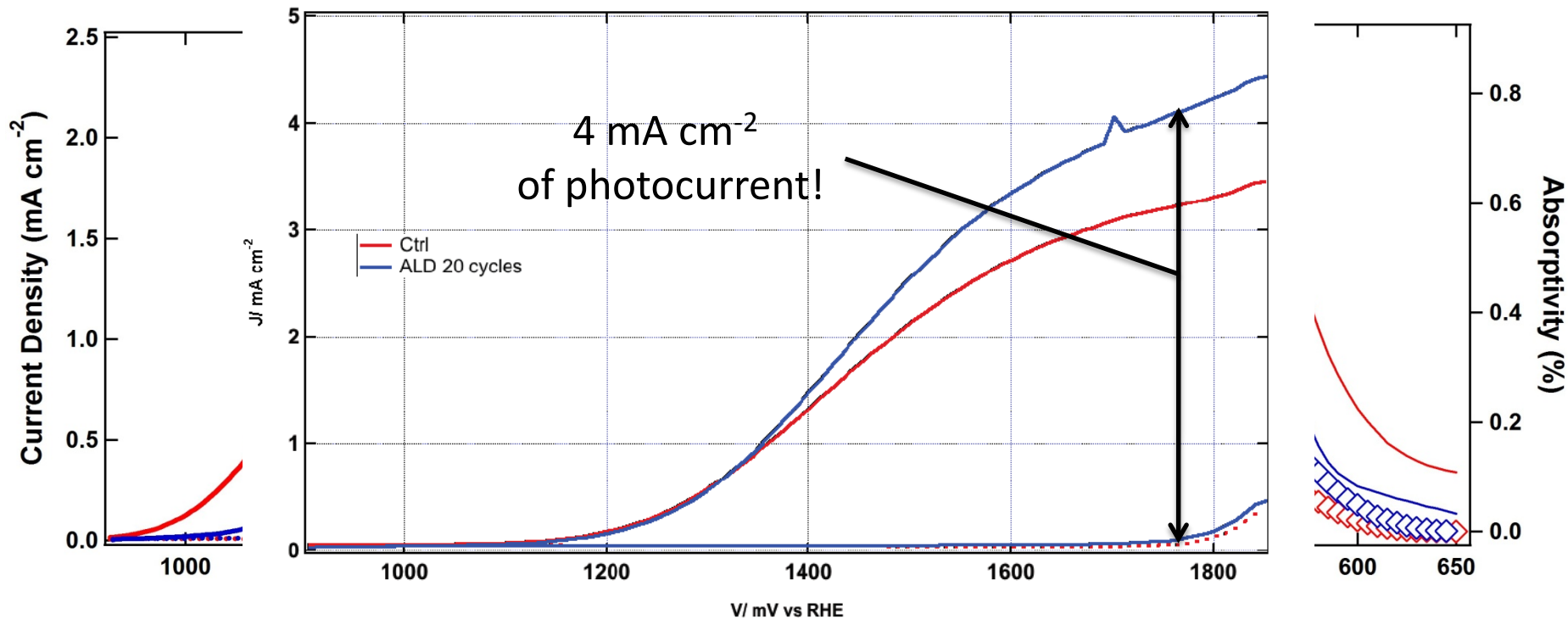






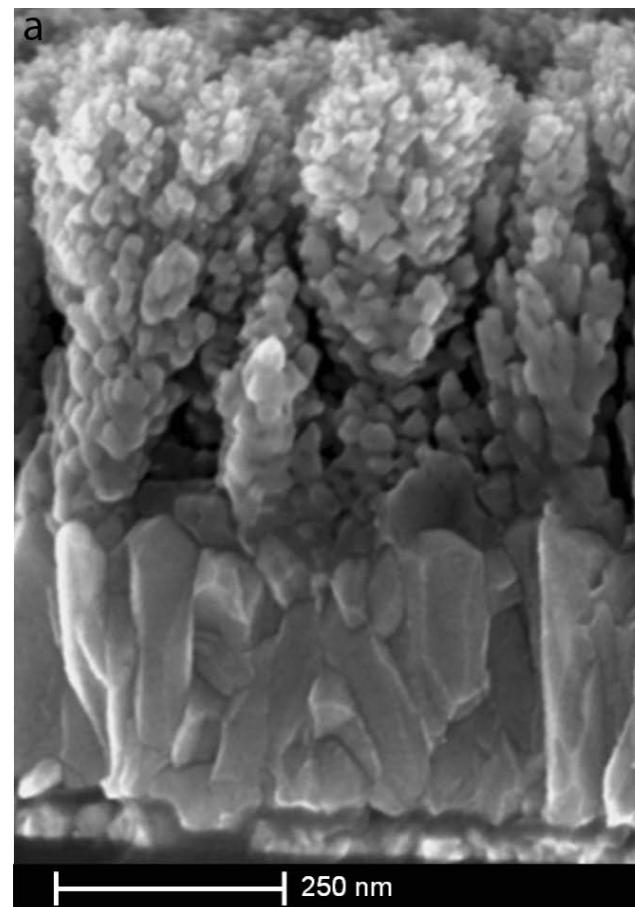
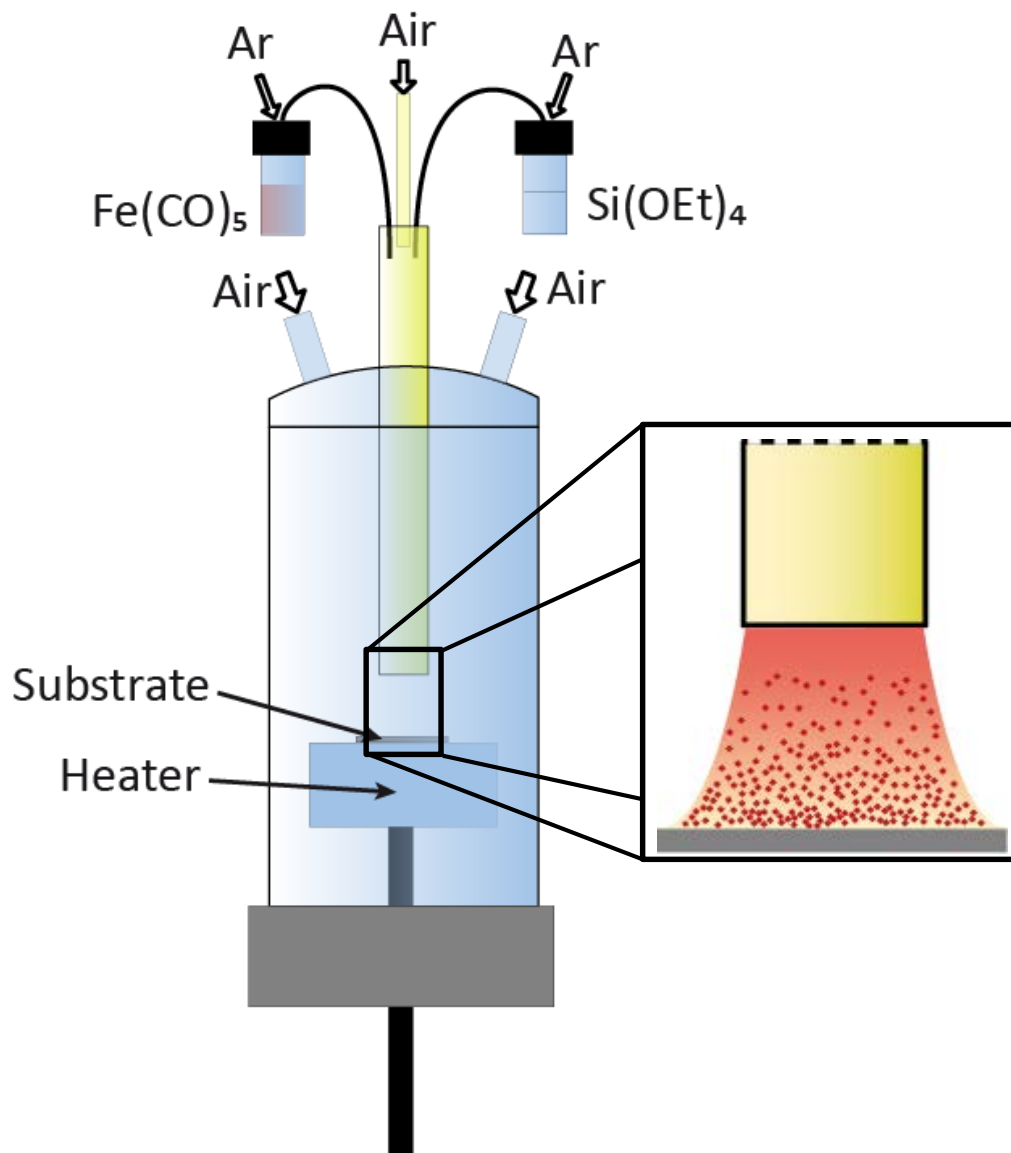
# Photoelectrochemical characterization

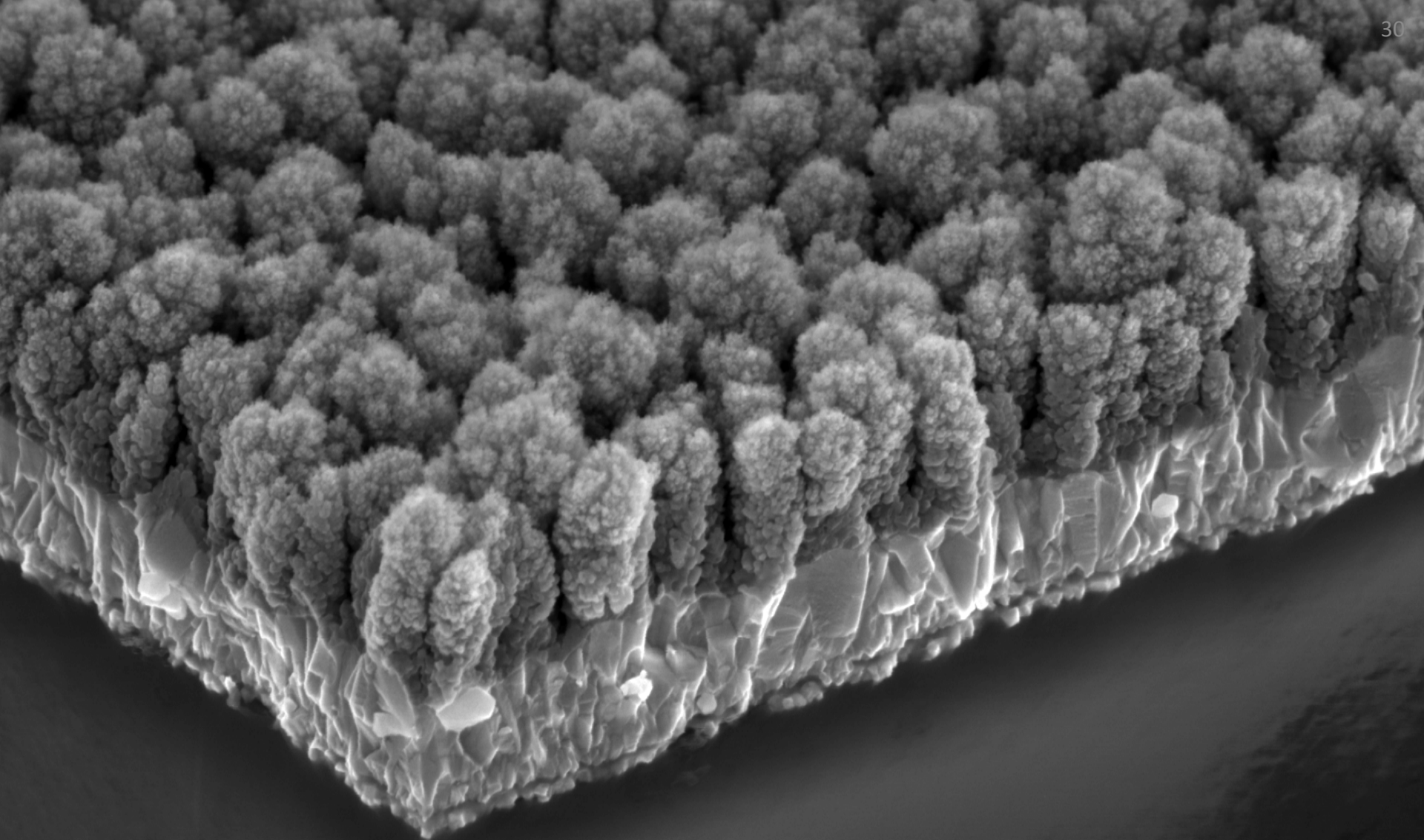






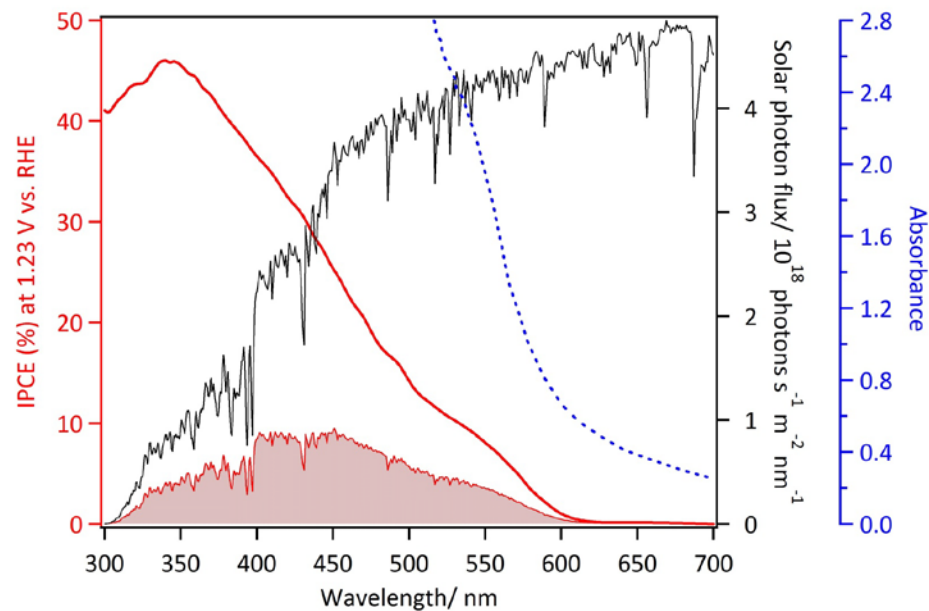
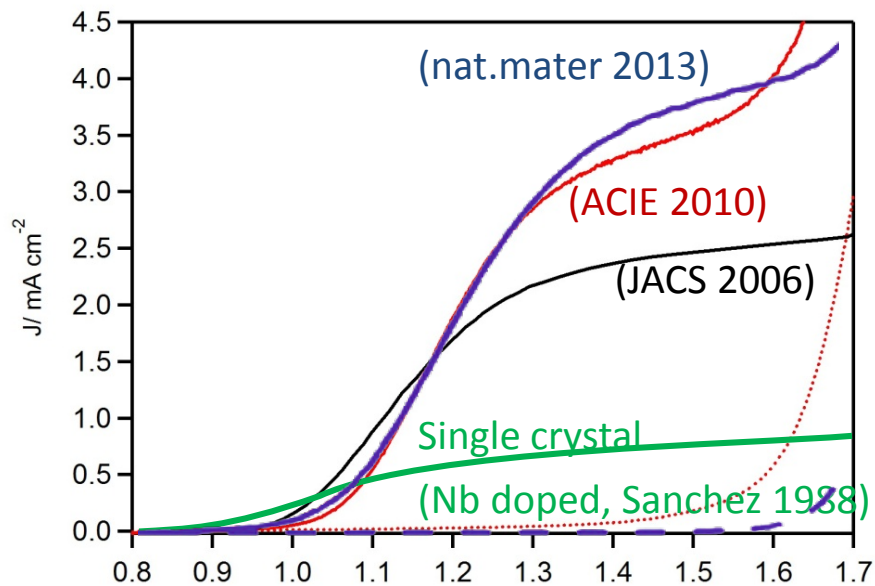
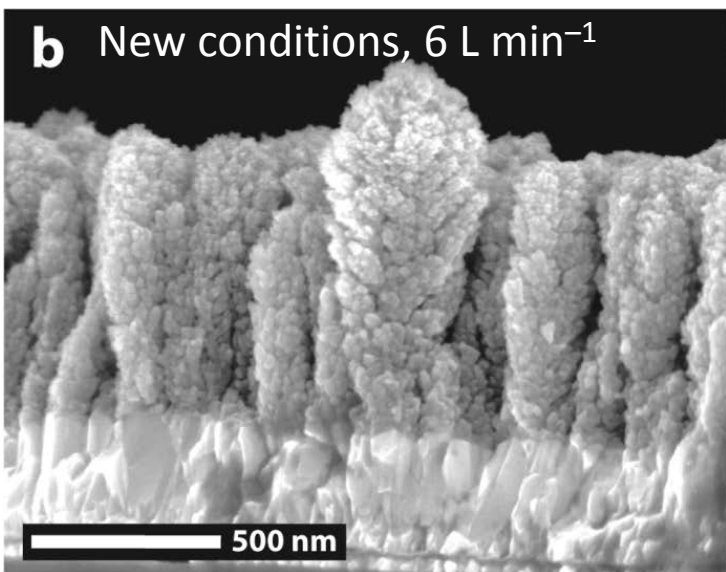
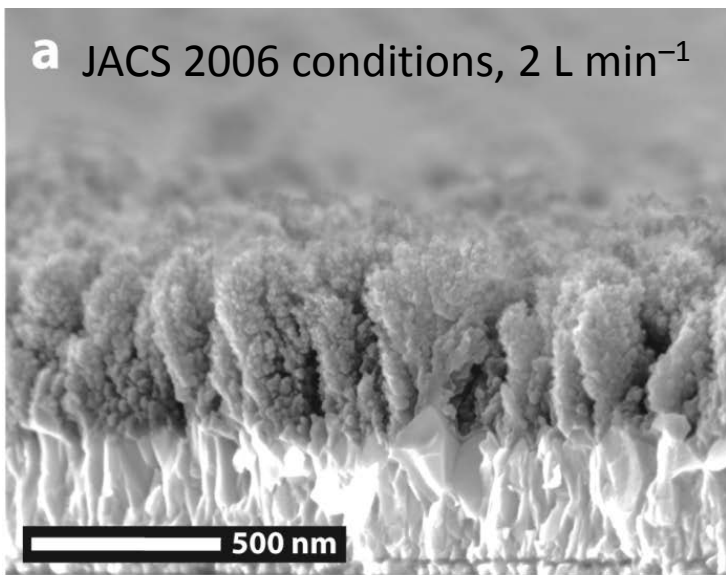
# Nanostructured films by APCVD



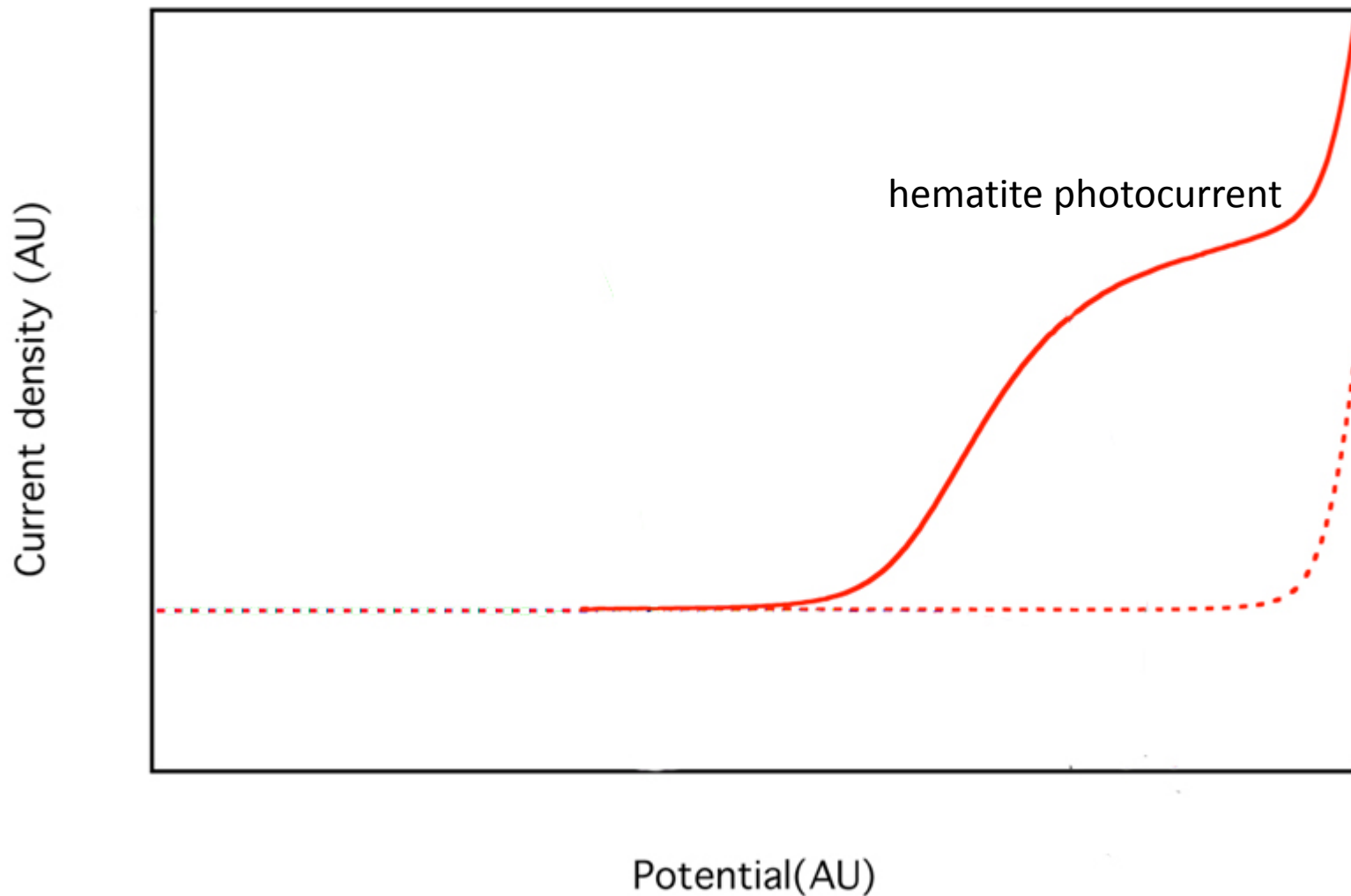


Acc.V Spot Magn Det WD Exp |-----| 1  $\mu$ m  
5.00 kV 3.0 35000x TLD 6.1 1

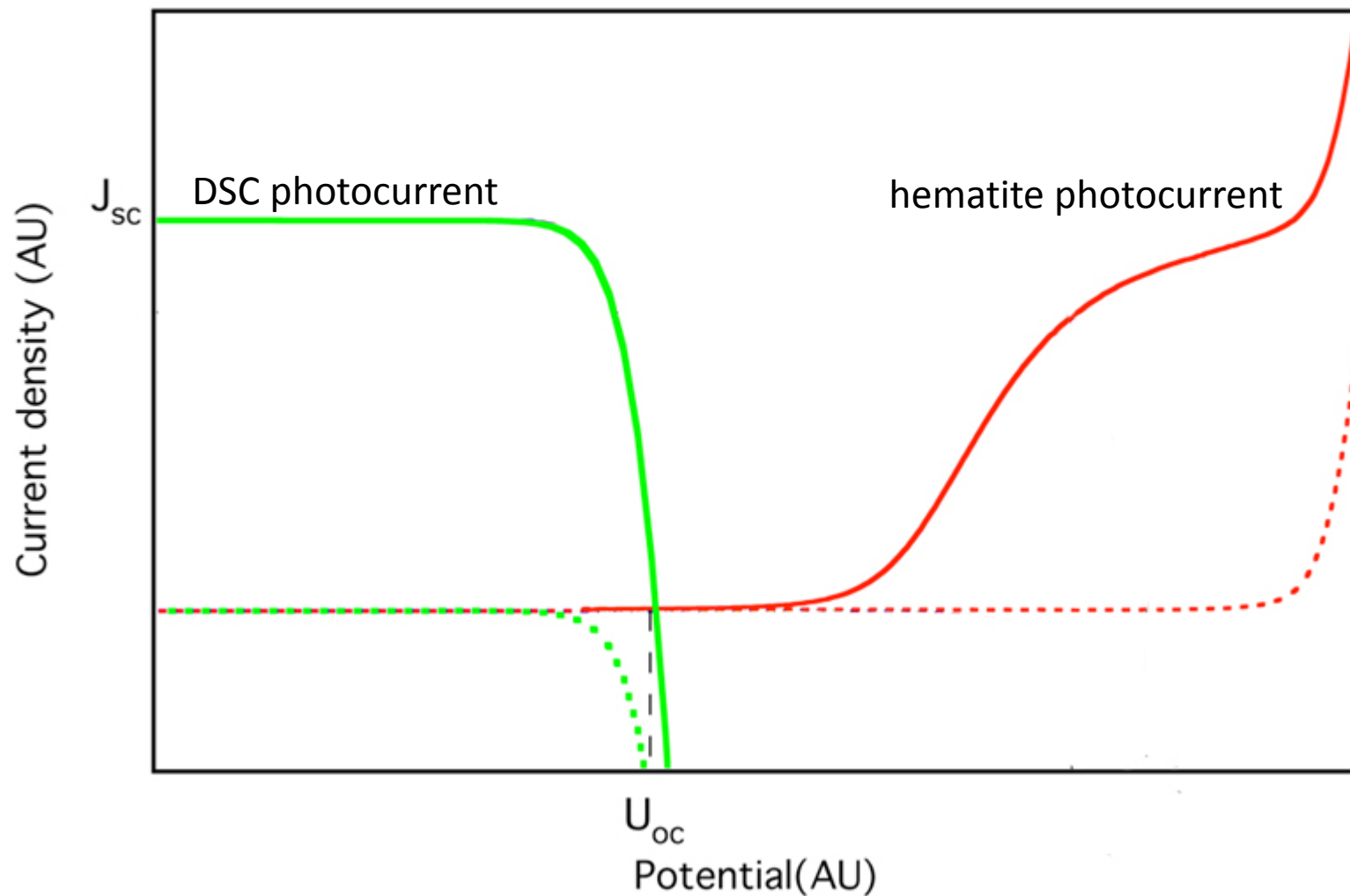
# Controlling the particle/precursor ratio



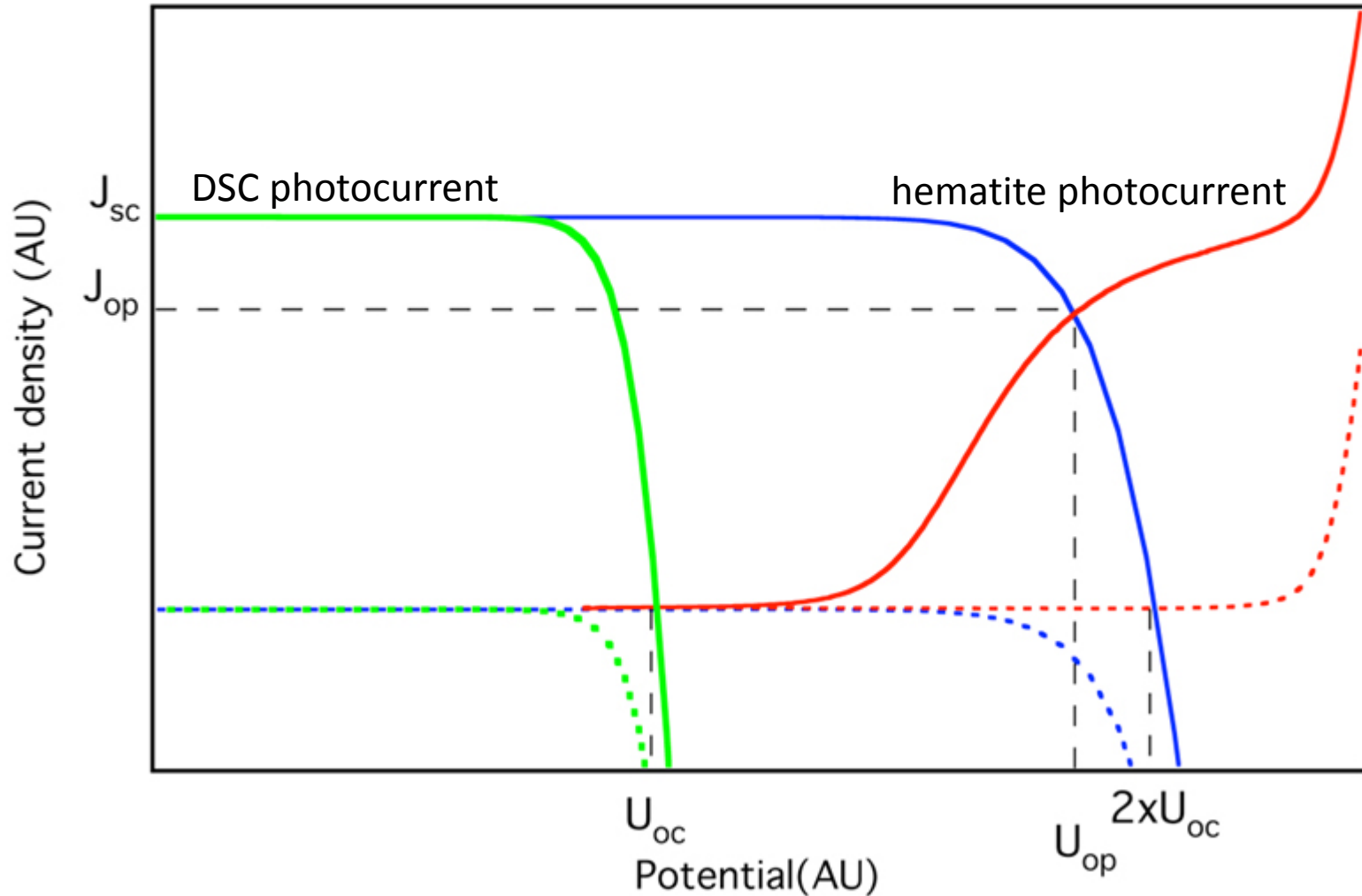
# Photoanode/DSC tandem device



# Photoanode/DSC tandem device

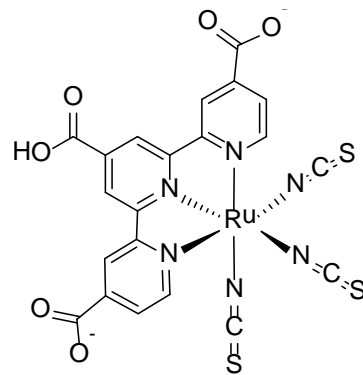
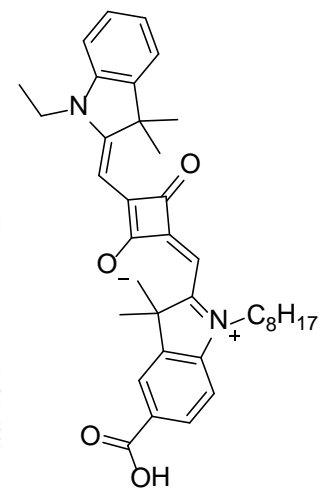
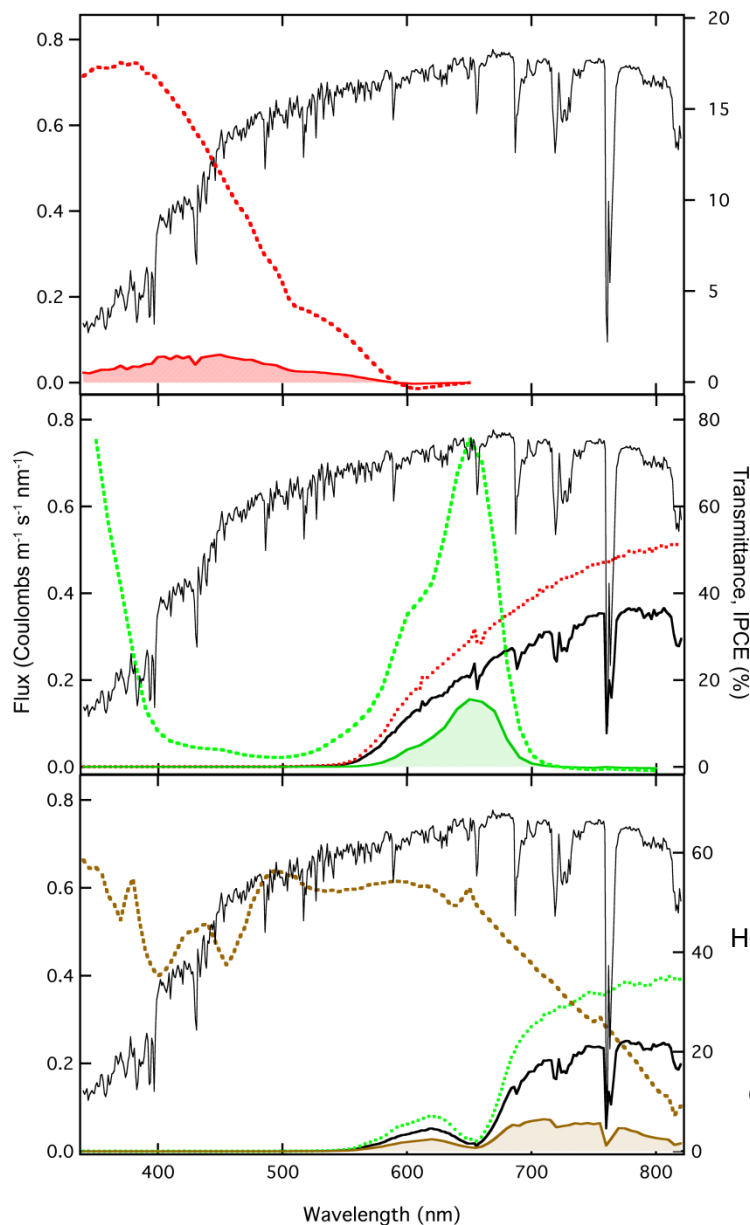
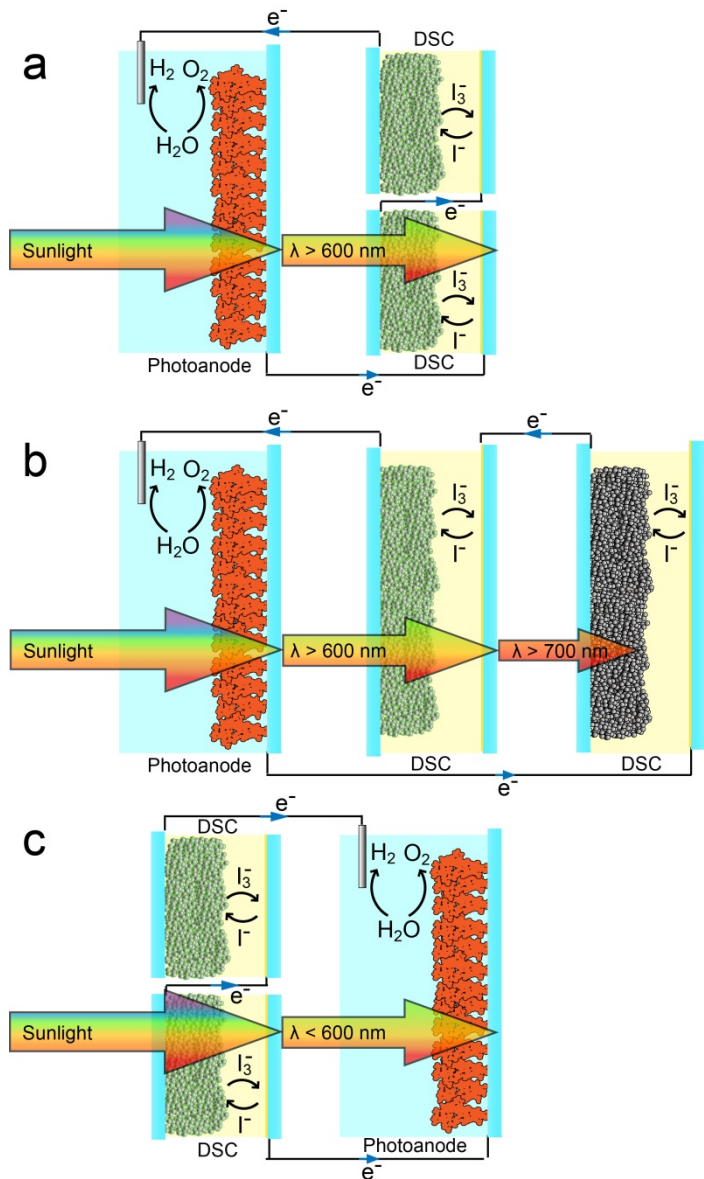


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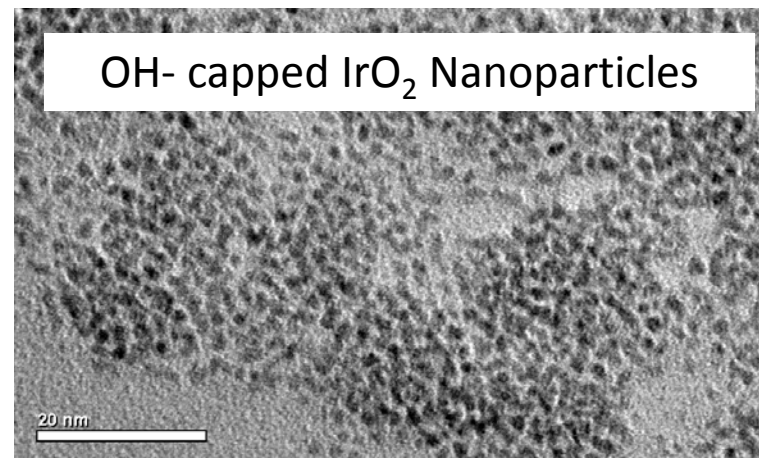
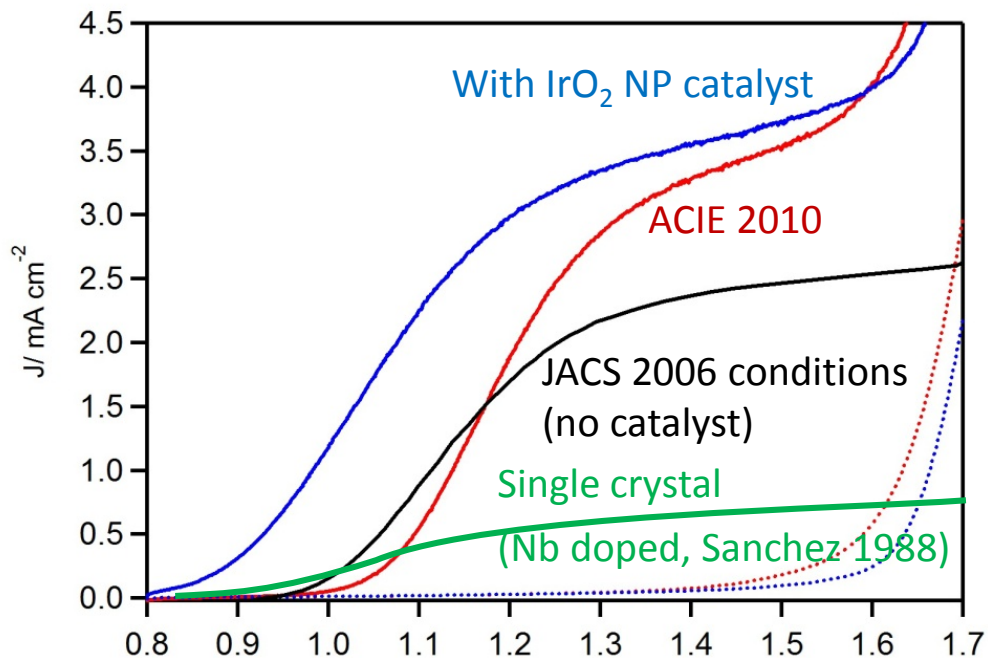
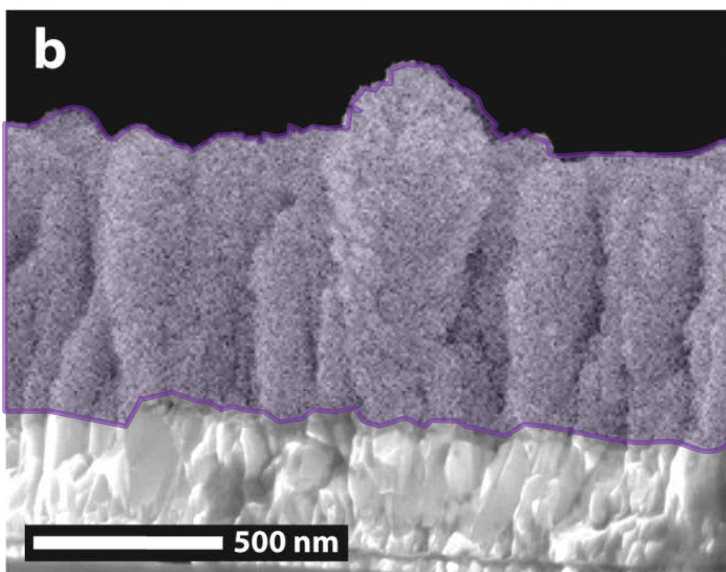
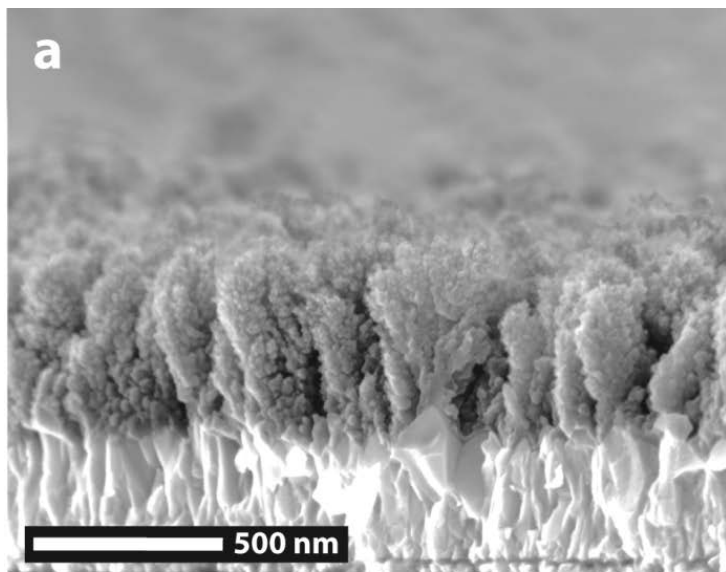




# T6 tandem devices

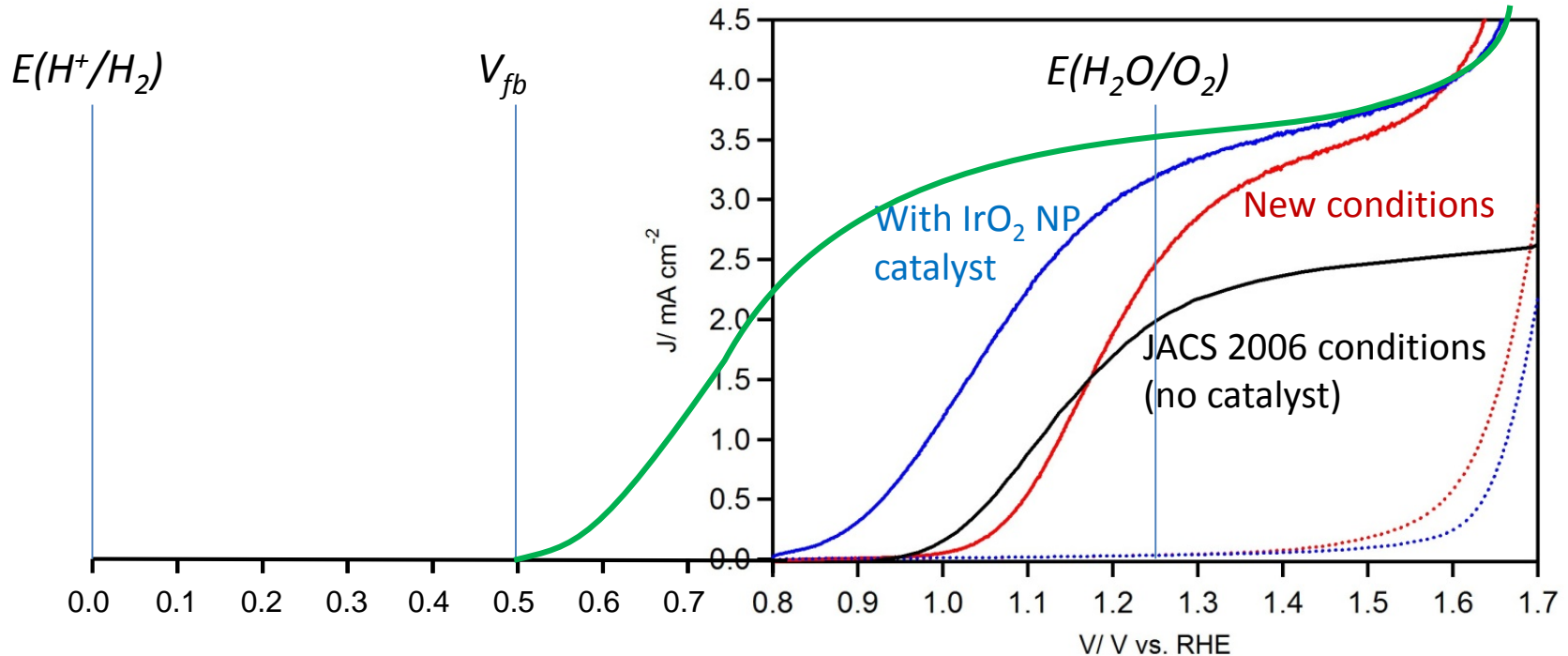


# Adding IrO<sub>2</sub> NP catalyst



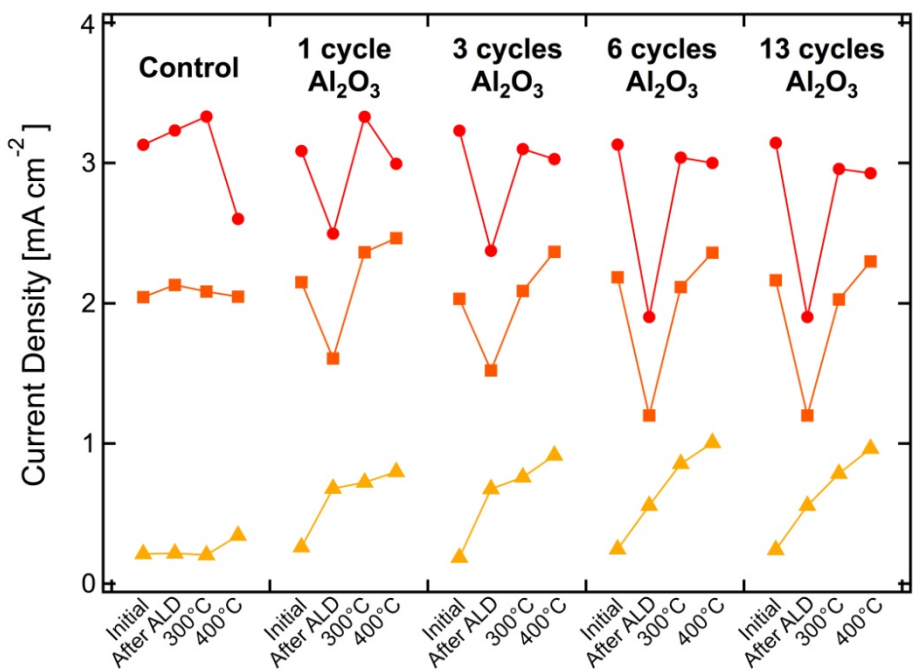
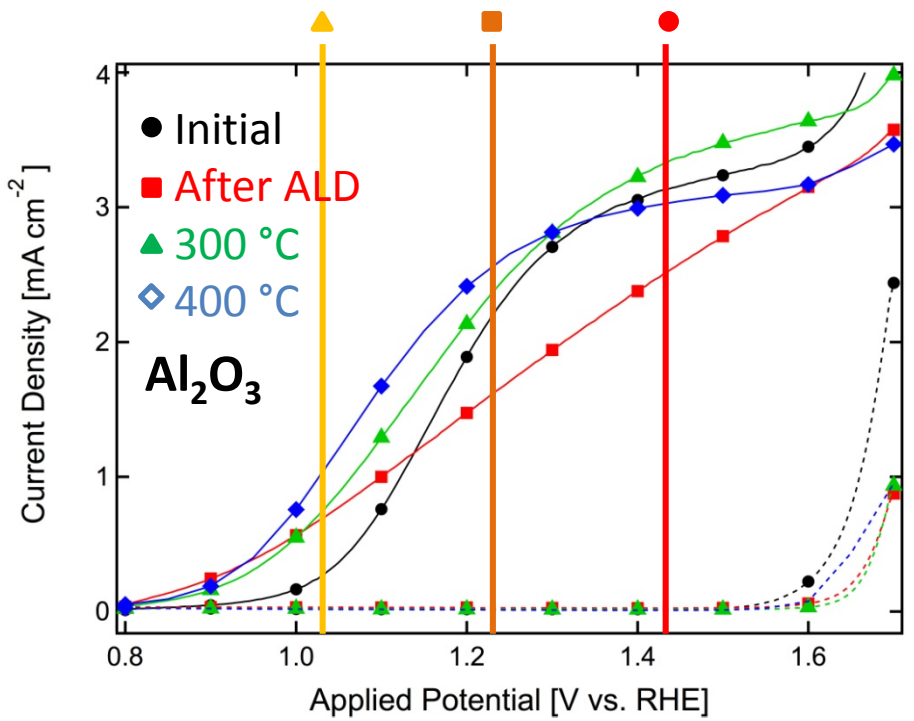
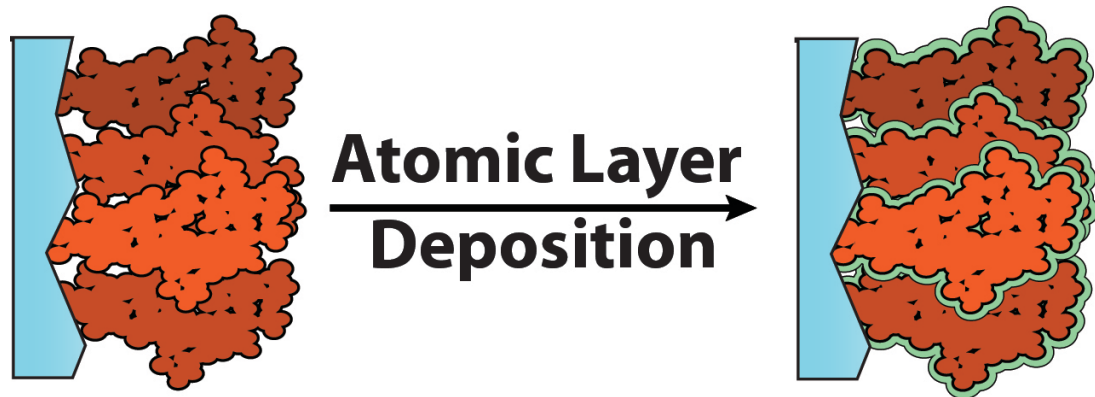


# A large overpotential remains

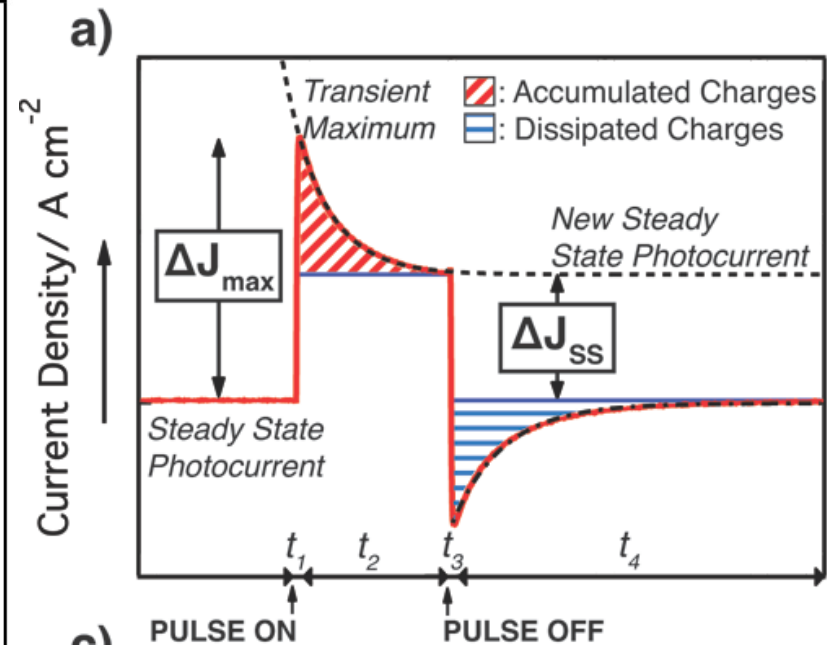
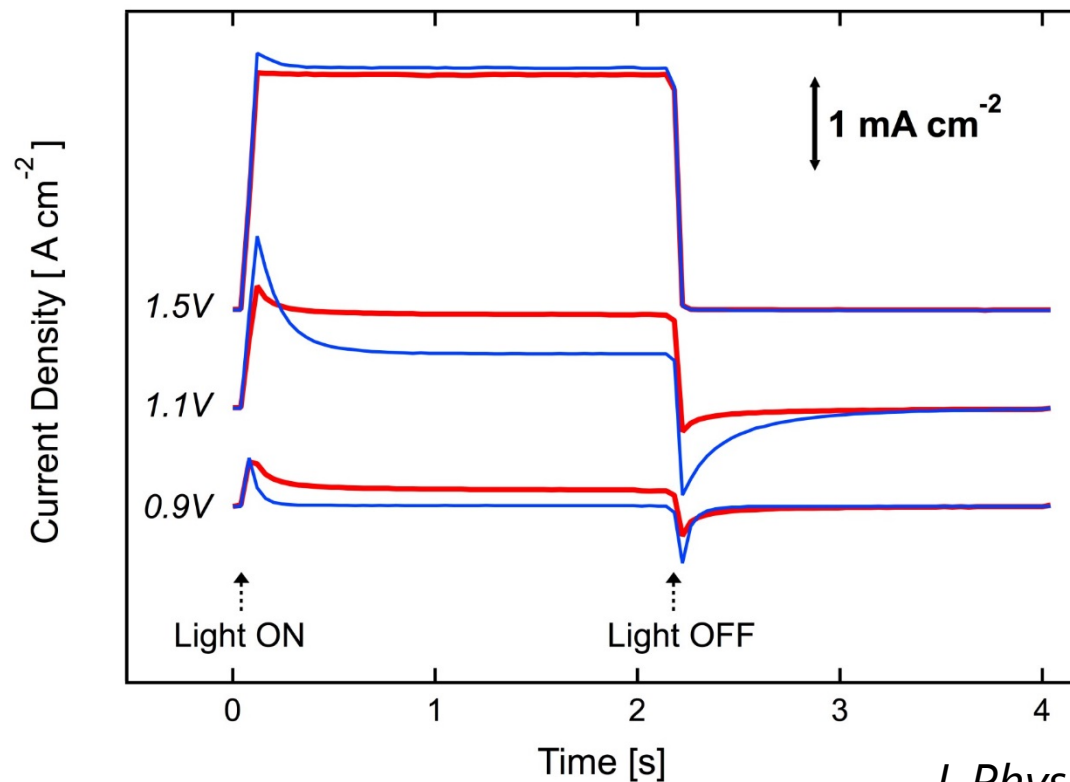
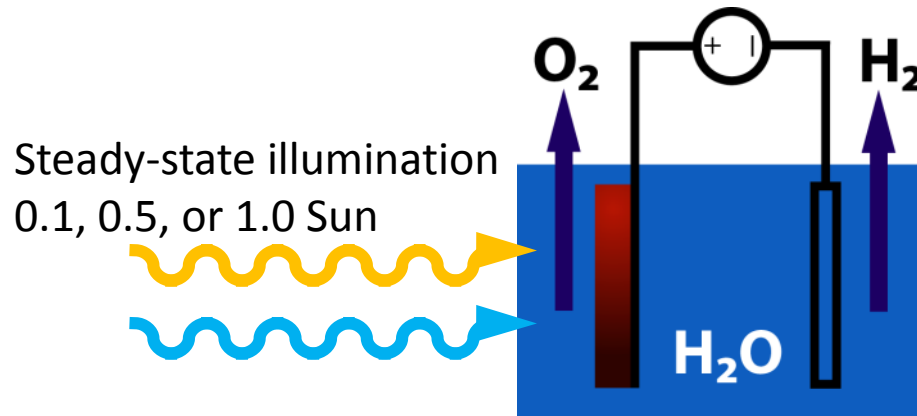


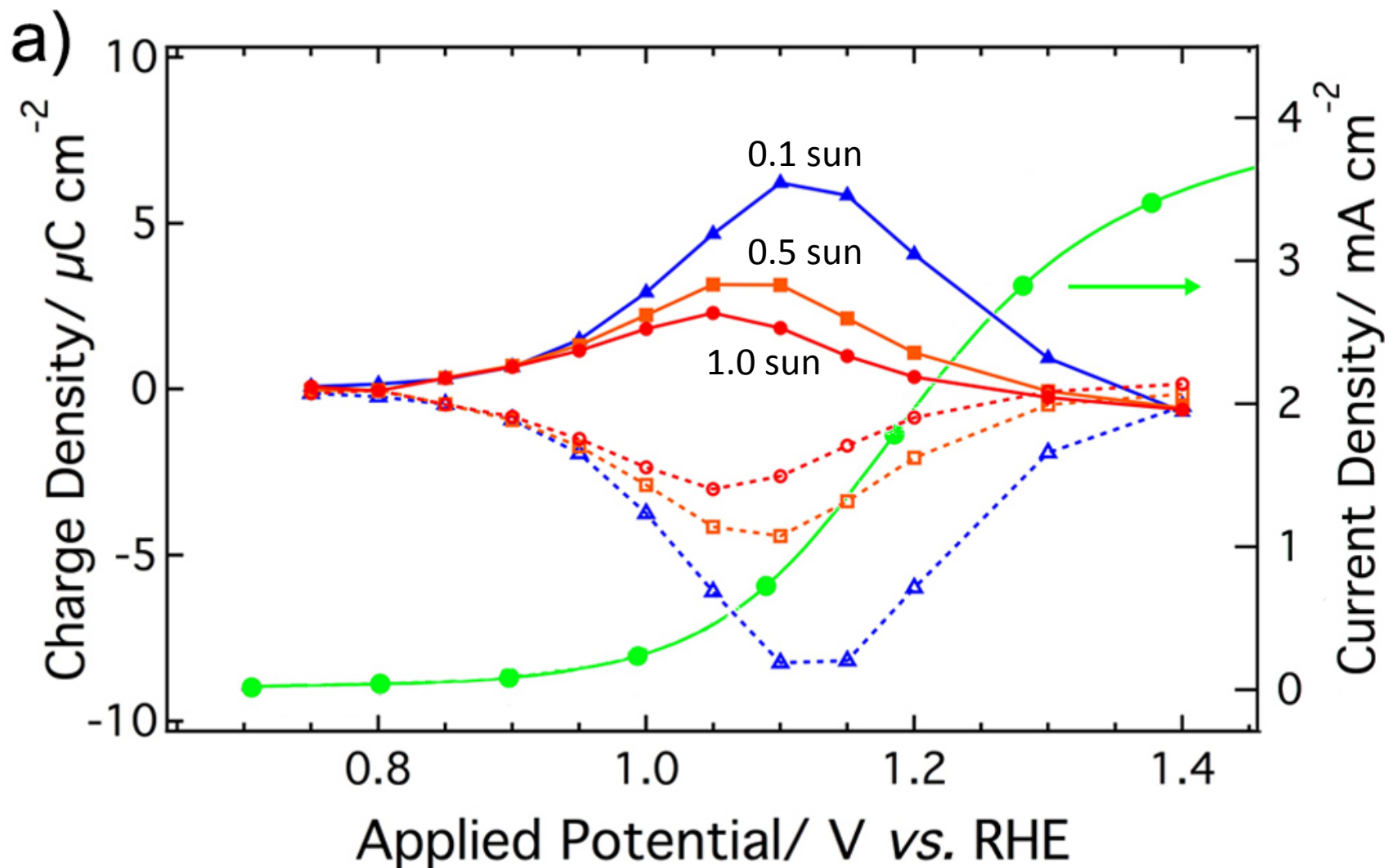
- Overpotential of 500 mV remains even with state of the art OER catalyst
- What else could be limiting the overpotential?

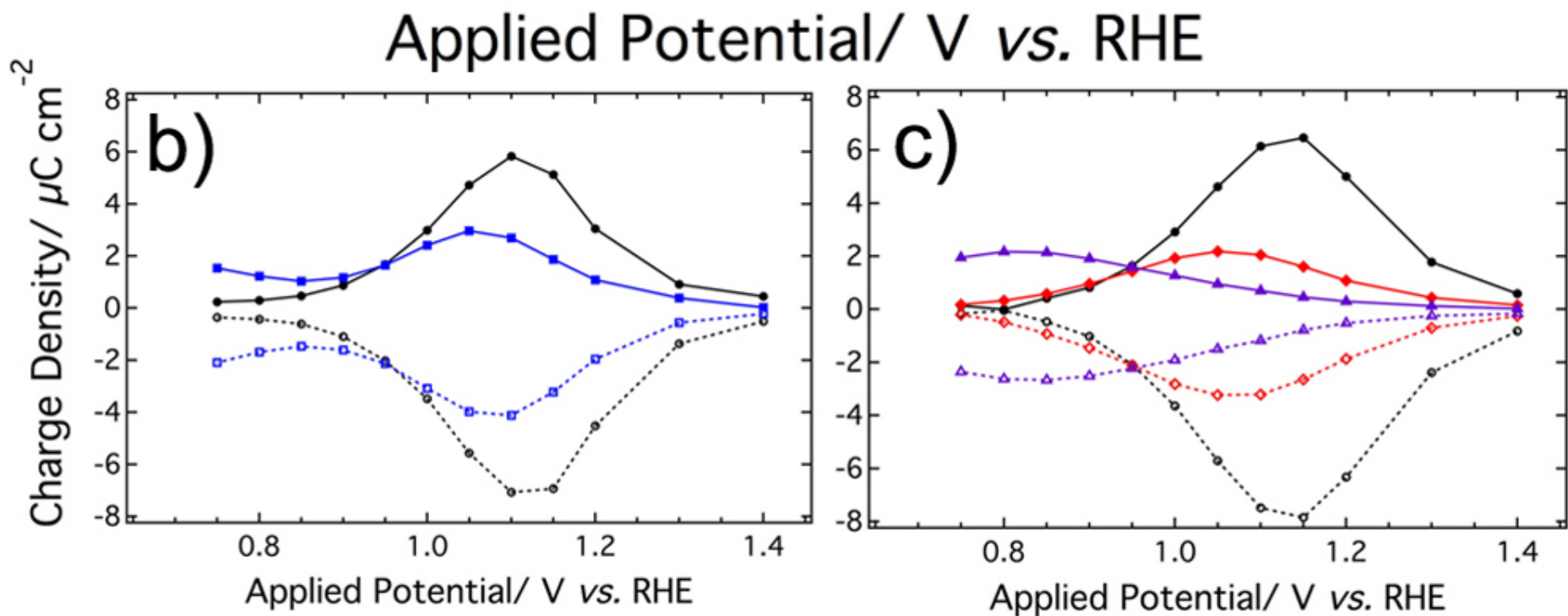
# ALD surface treatment



# Transient photocurrent analysis

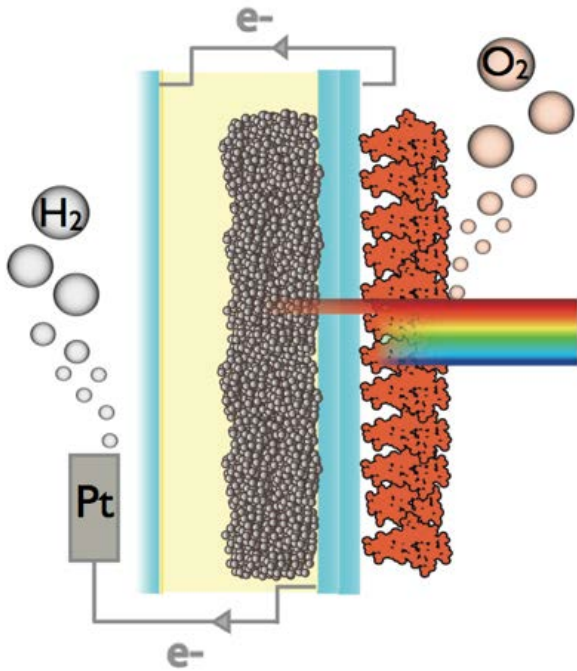






- Indicates that 2 separate processes are causing the large overpotential in hematite photoanodes
- Suggests that surface electron traps are contributing to the large overpotential through “Fermi level pinning.”

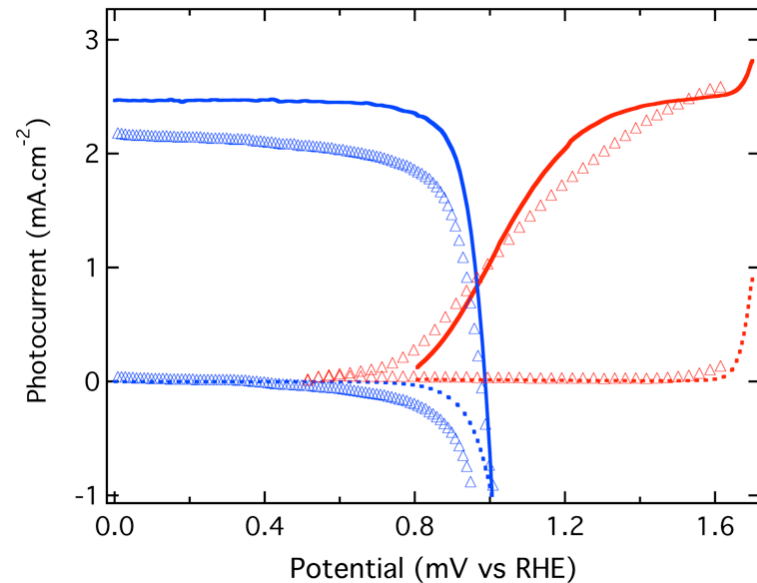
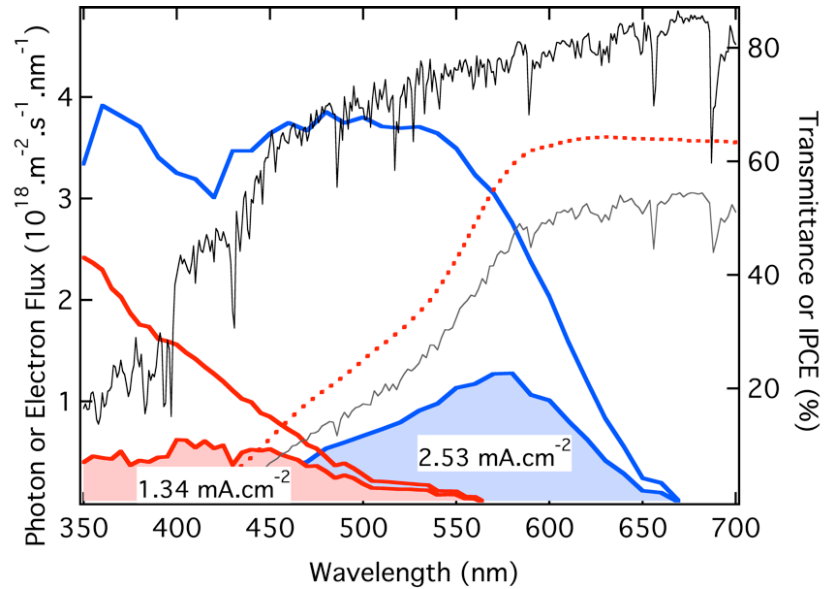
# A D4 tandem cell with Hematite/DSC



## Fe<sub>2</sub>O<sub>3</sub> - DSC tandem cell

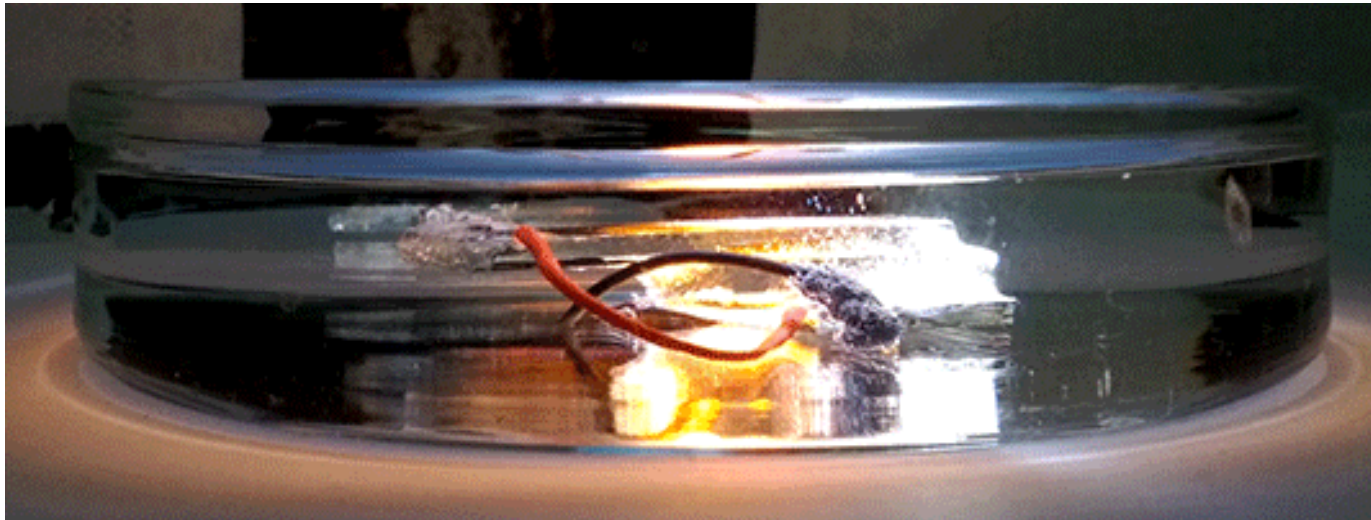
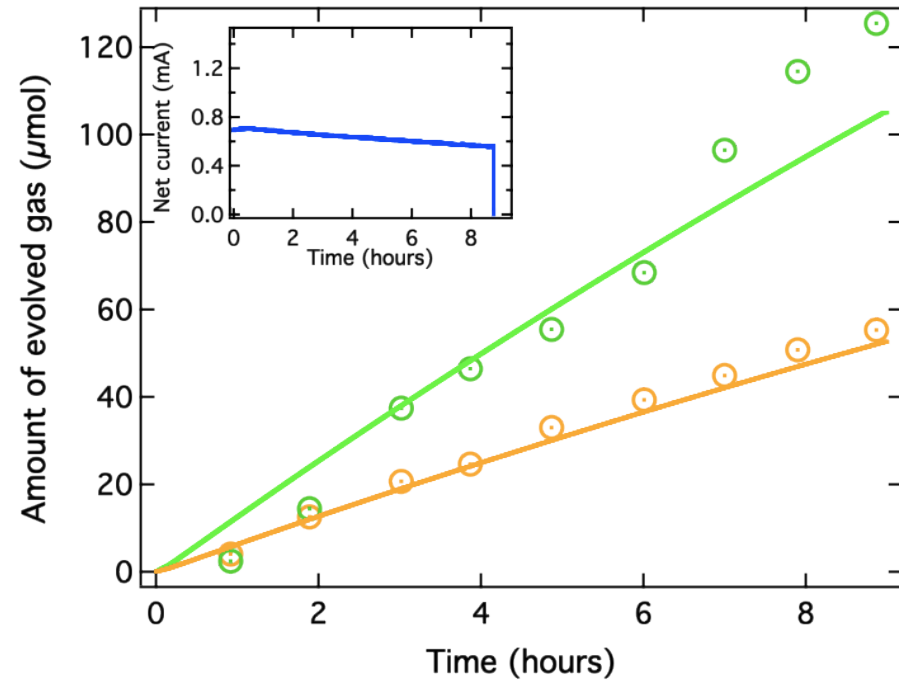
- Predicted by calculation: **0.61 mA.cm<sup>-2</sup>**
- Measurement *in situ* : **0.78 mA.cm<sup>-2</sup>**
- Measured with ammeter: **0.95 mA.cm<sup>-2</sup>**

**Efficiency: 1.4 %STH**

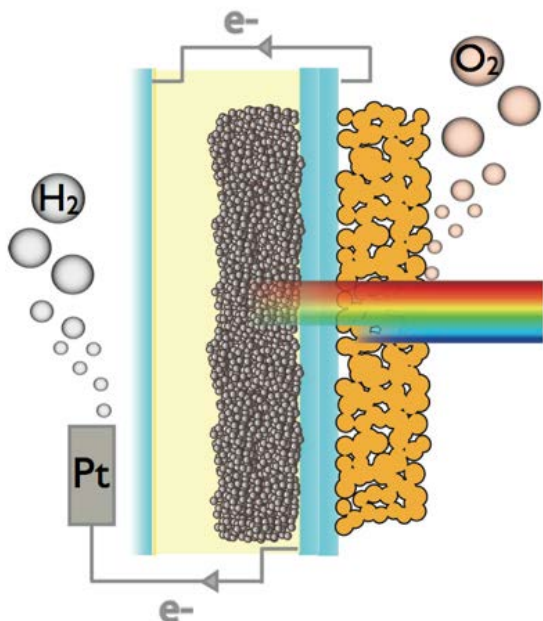




# Tandem cell with $\text{Fe}_2\text{O}_3$ anode under operation



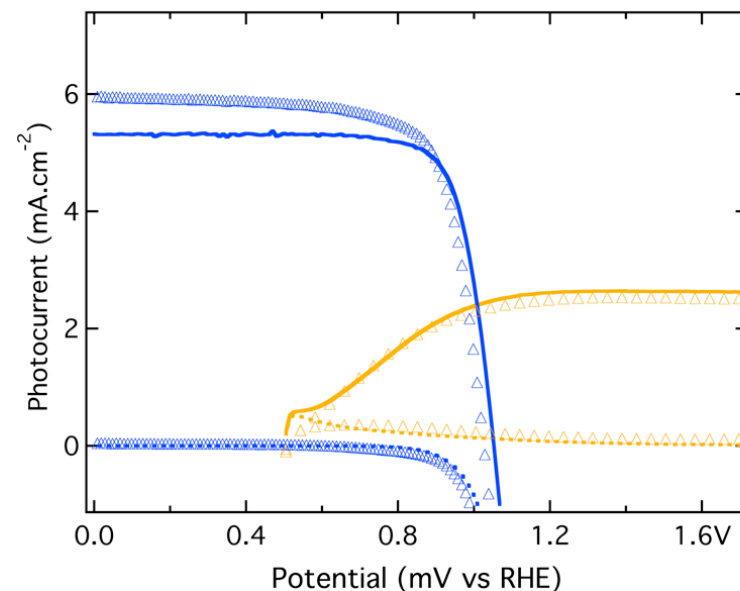
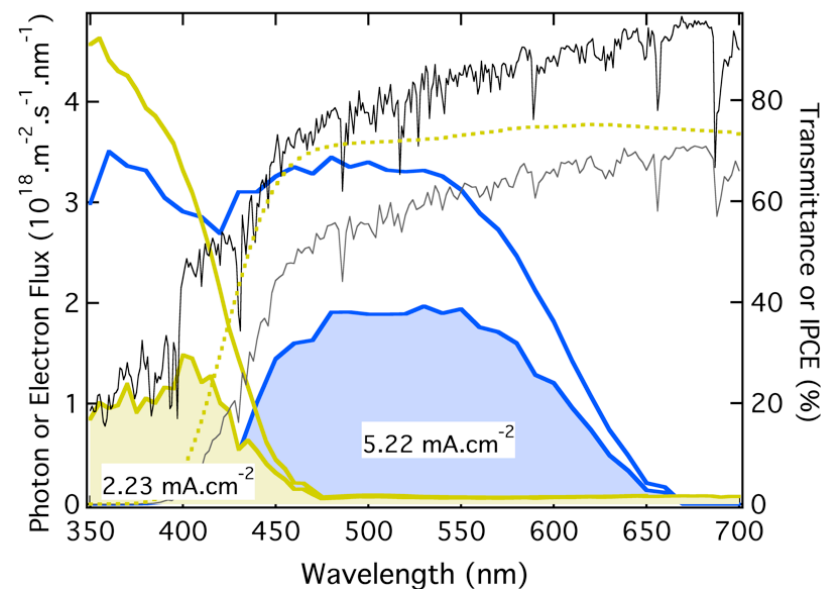
# WO<sub>3</sub> tandem device



## WO<sub>3</sub> - DSC tandem cell

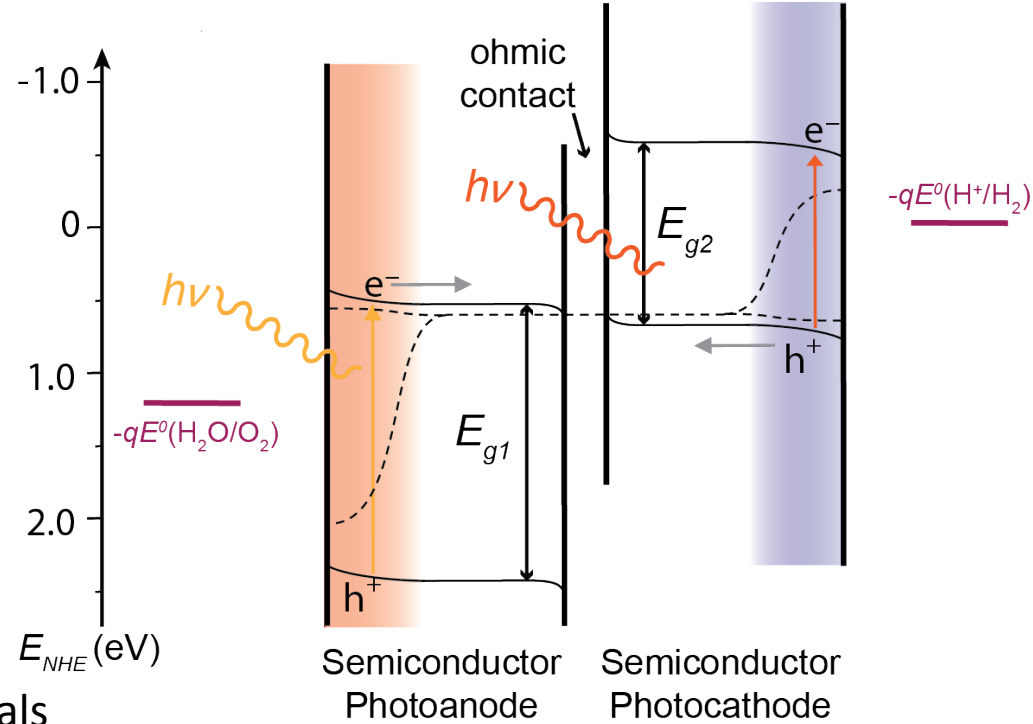
- Predicted by calculation: **2.35 mA.cm<sup>-2</sup>**
- Calculation validated by in situ-measurement
- Measured with ammeter: **2.52 mA.cm<sup>-2</sup>**

**Efficiency: 3.6 %STH**

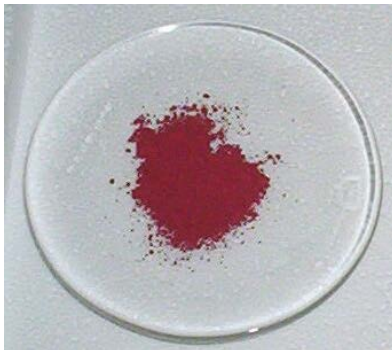




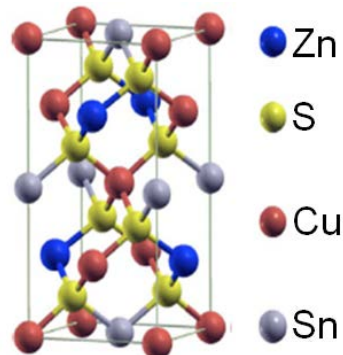
# Photocathodes for hydrogen evolution



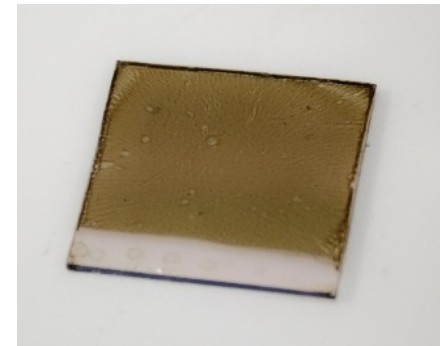
Photocathode materials



Copper(I) oxide

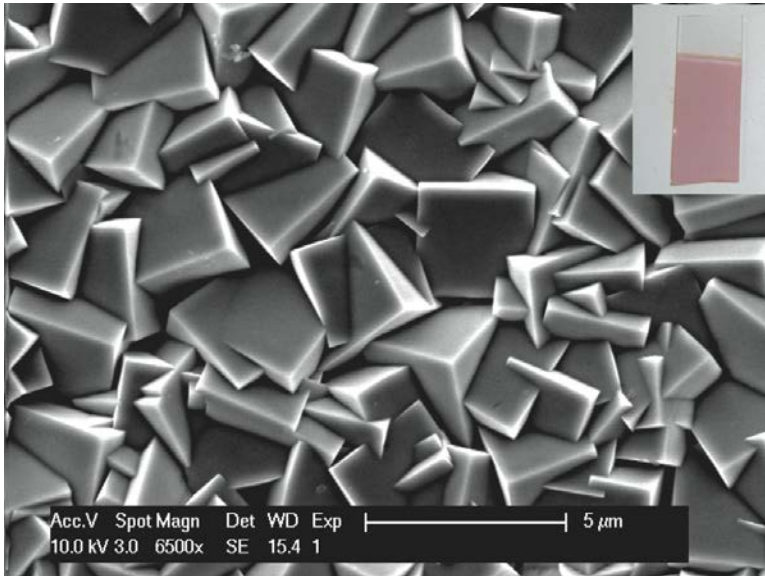


$\text{Cu}_2\text{ZnSnS}_4$



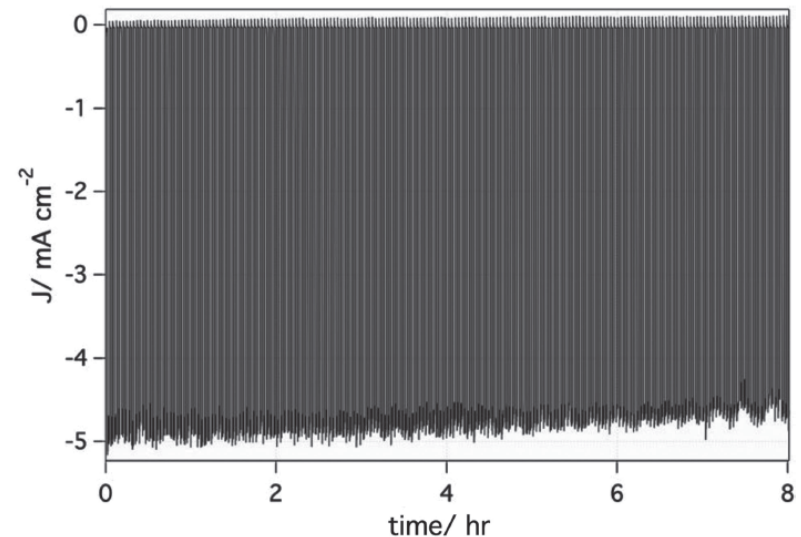
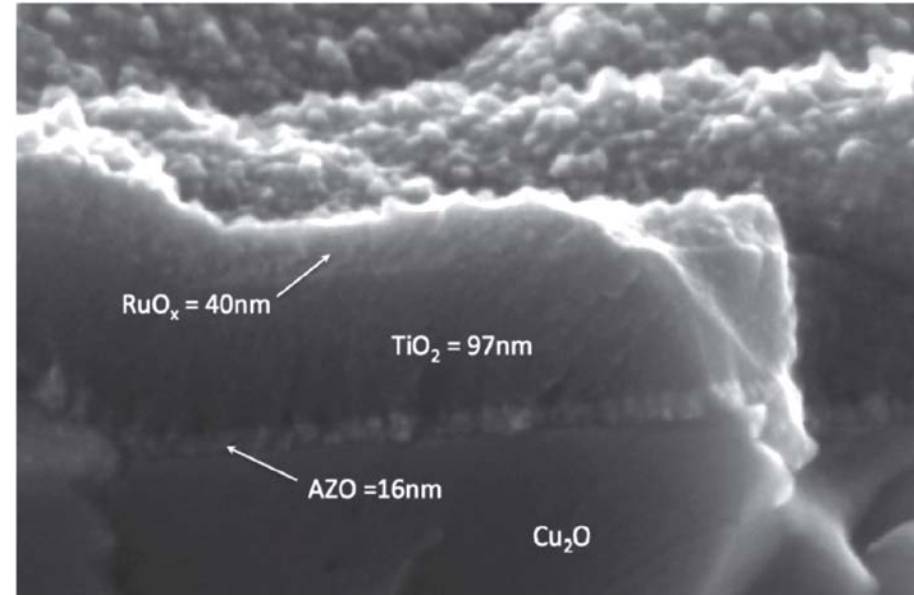
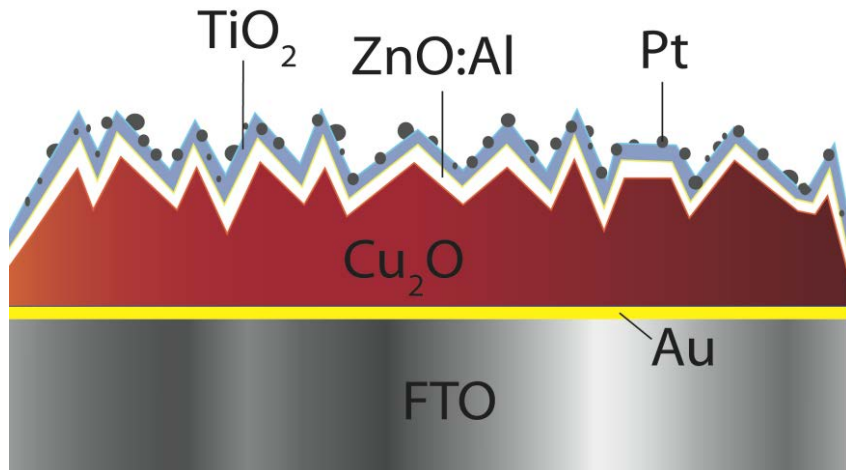
$\text{CuFeO}_2$

# Protective layers enhance stability



Electrodeposition (0.2 M  $\text{CuSO}_4$ , 3 M lactic acid with 0.5 M  $\text{K}_2\text{HPO}_4$  buffer, pH 12, 2 M KOH)

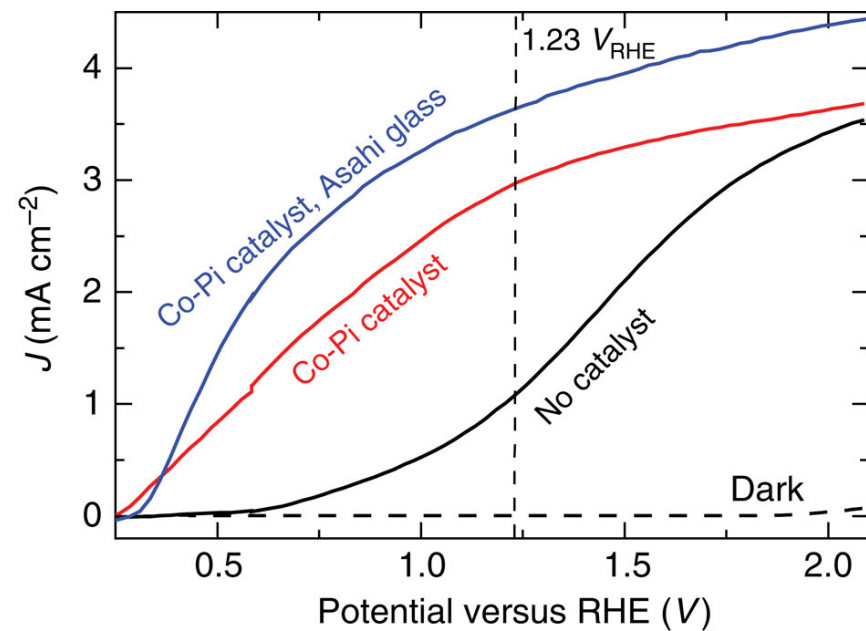
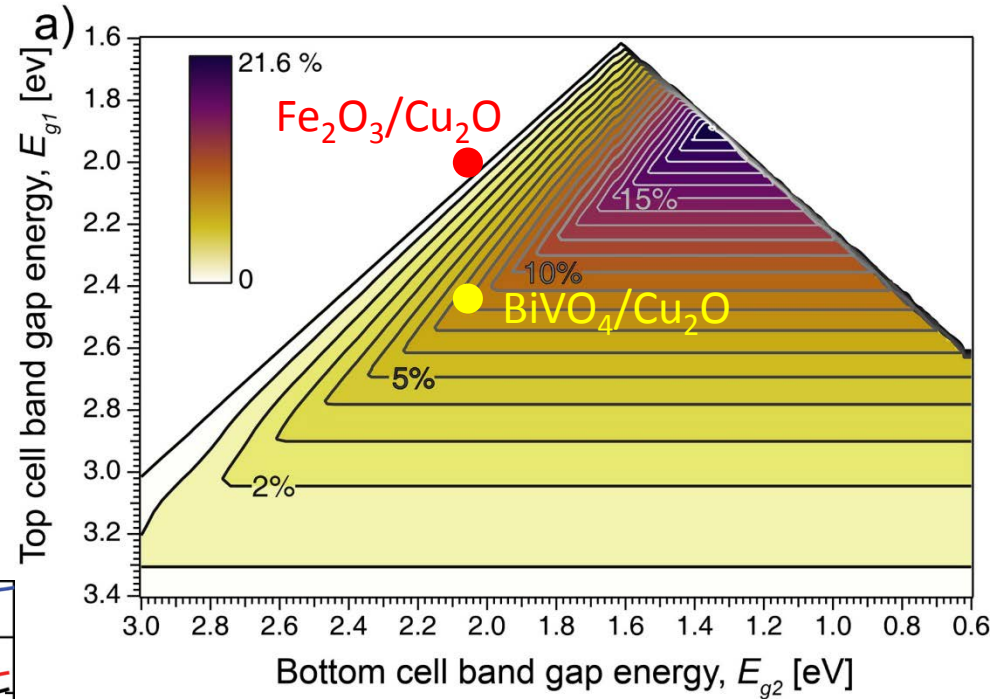
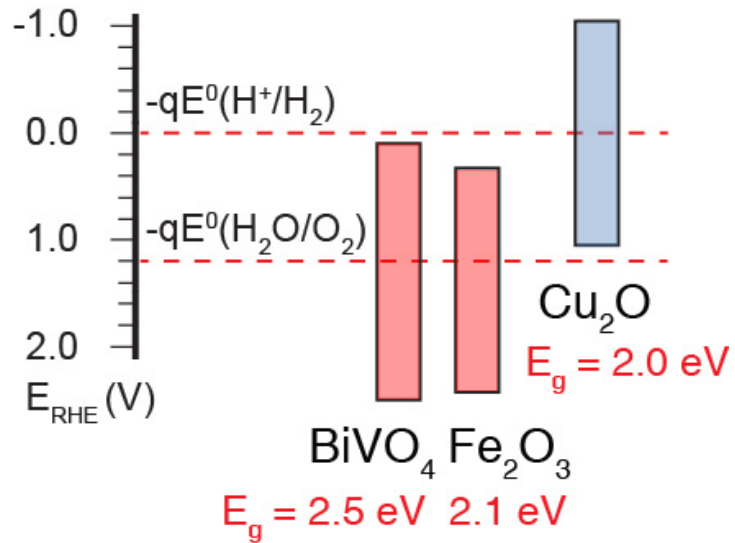
ALD protective layers



*Nature Materials* **2011**, *10*, 456-461.

S. David Tilley et al. *Adv. Funct. Mater.* **2014**, *24* (3), 303-311.

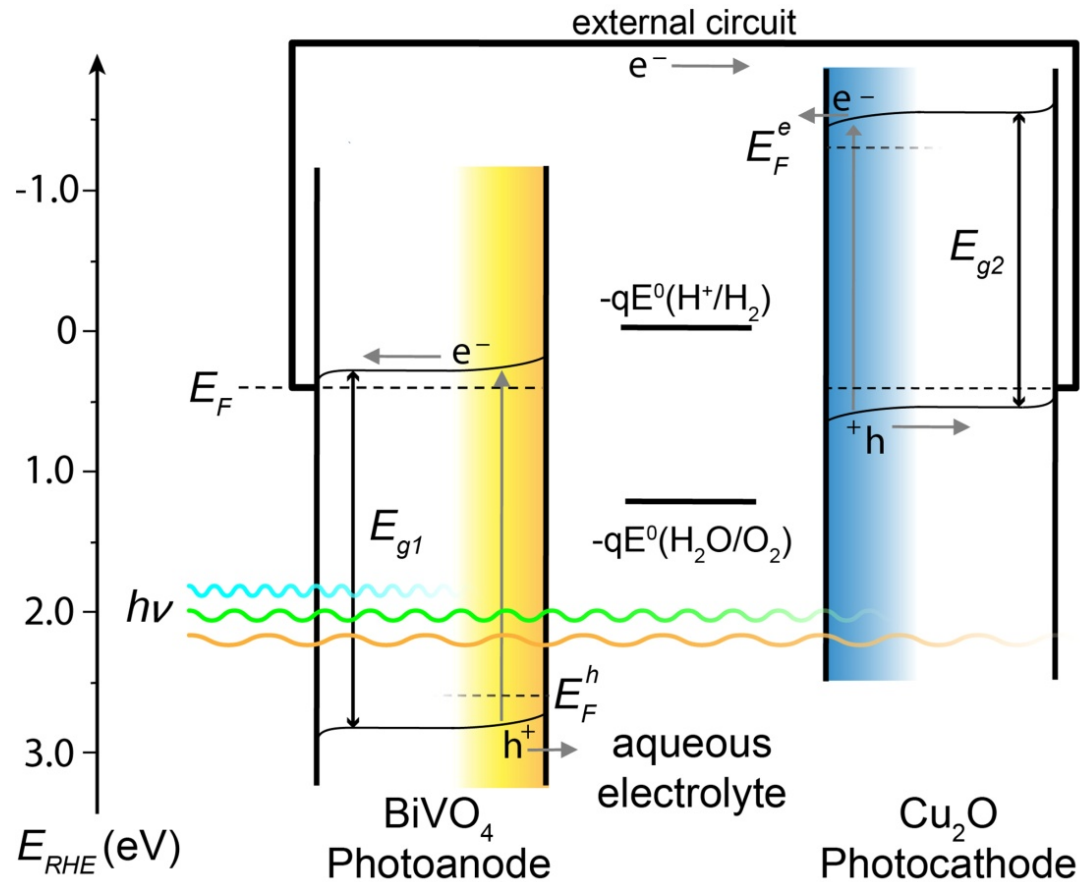
# Copper oxide based tandem cells



$\text{BiVO}_4$

F.F. Abdi, R. van der Krol et al.  
*Nature communications*  
**2013**, 4, 2195

# W:BiVO<sub>4</sub> | Cu<sub>2</sub>O Tandem cell configuration



**FTO/W:BiVO<sub>4</sub>/Co-Pi**

W:BiVO<sub>4</sub> deposited by spray pyrolysis

Cat: Co-Pi potentiostatic photodeposition

*van de Krol's group*

**FTO/Au/Cu<sub>2</sub>O/Al:ZnO/TiO<sub>2</sub>/RuO<sub>x</sub>**

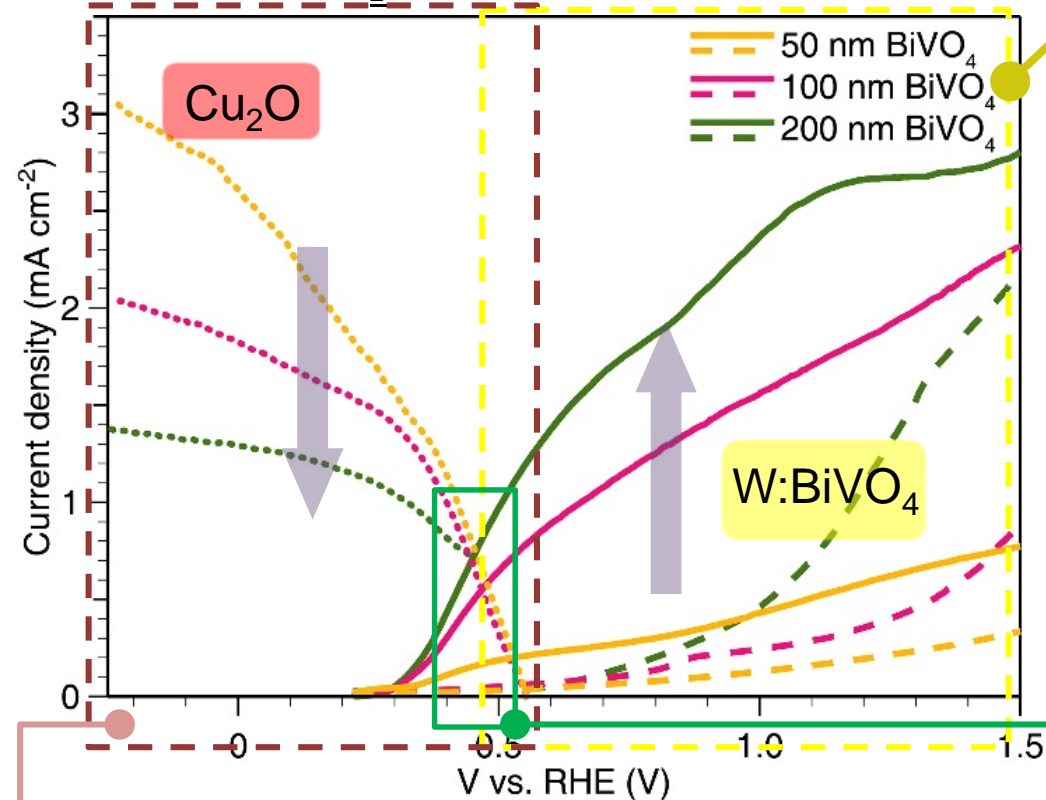
Electrodeposited Cu<sub>2</sub>O

AZO and TiO<sub>2</sub> Atomic Layer deposition

Cat: RuO<sub>x</sub> galvanostatic photodeposition

# W:BiVO<sub>4</sub> | Cu<sub>2</sub>O Tandem cell analysis

Performance of Cu<sub>2</sub>O with light restrictions imposed by W:BiVO<sub>4</sub>



## J-V (3-electrode cell)

- Thicker films give rise to higher activity (better light harvesting)
- CoPi deposition drastically enhances the photocurrents
- Onset photocurrent :+ 0.3 V vs RHE (E<sub>fb</sub>=0.1 V)

Expected operating current density (intersection)

## J-V (3-electrode cell)

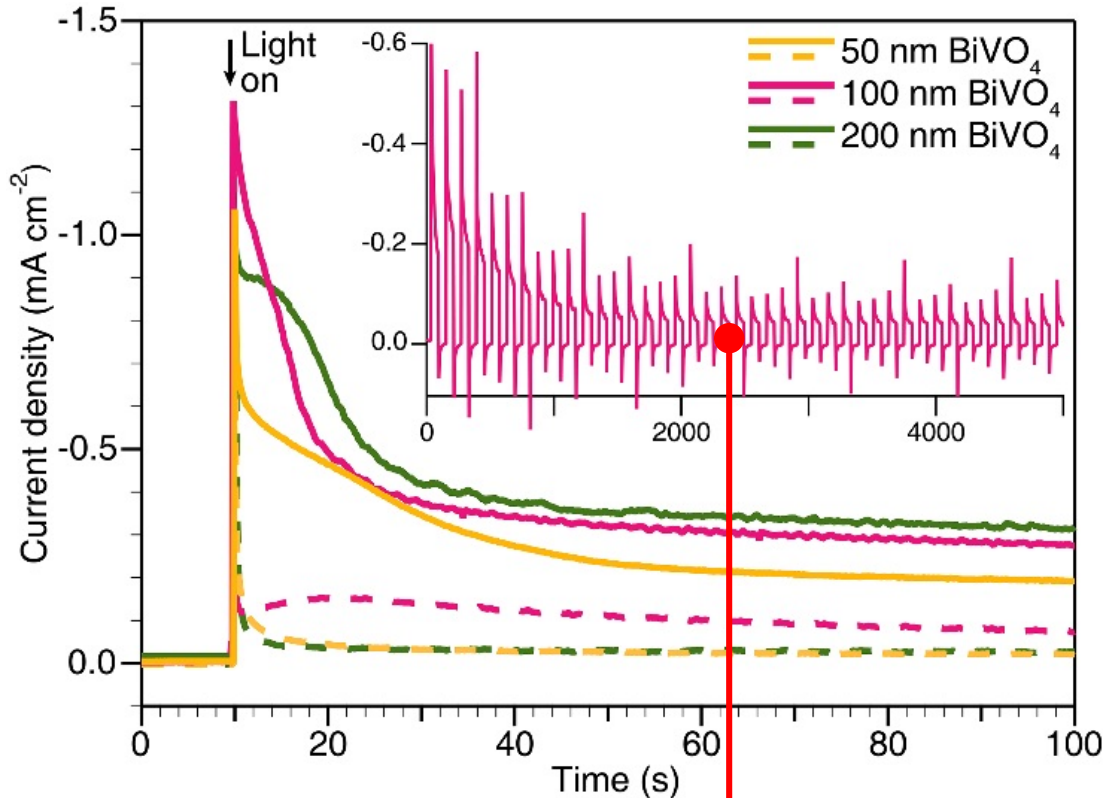
- The thicker the BiVO<sub>4</sub> layer, the lower the performance (limited light transmission)
- Onset photocurrent :+ 0.5 V vs RHE (E<sub>fb</sub>=0.8 V)

Thickness BiVO <sub>4</sub>	50 nm	100 nm	200 nm
J <sub>sc</sub> / mAcm <sup>-2</sup>	0.20	0.55	0.71
STH / %	0.25	0.68	0.87



# W:BiVO<sub>4</sub> | Cu<sub>2</sub>O Tandem cell performance

## Performance of a (2-electrode) TANDEM cell



### Without Co-Pi

Spikes decay fast, low currents  
**Fast recombination**

### With Co-Pi

Slower spike decay, higher steady currents.

**Improved charge separation kinetics**

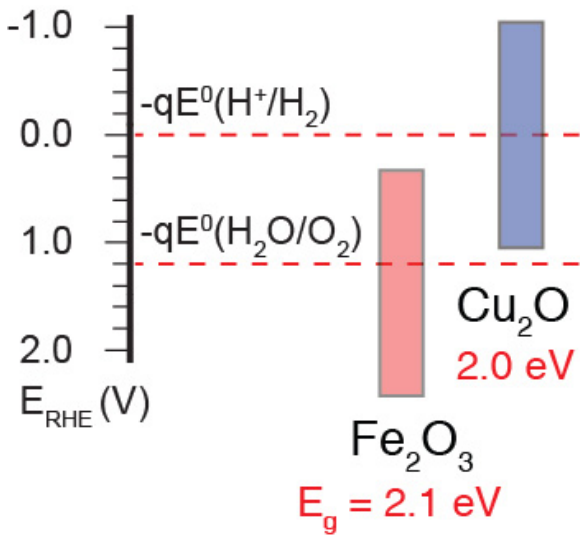
### Stability issues

Decrease in photocurrent due to *dissolution of Co-Pi overlayer*

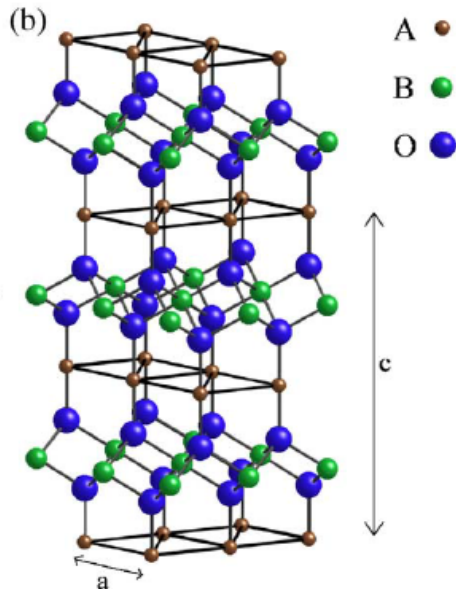
Co-Pi **stable** only at high operating voltages ( $\sim 1$  V vs RHE) in pH 6 electrolyte (Nocera and co workers *J. Am. Chem. Soc.* **2012**, *134*, 6326-6336.)

Co-Pi *repair mechanism* (oxidation and reposition of liberated Co<sup>2+</sup>), the lower the voltage the slower the rate (dissolution favoured).

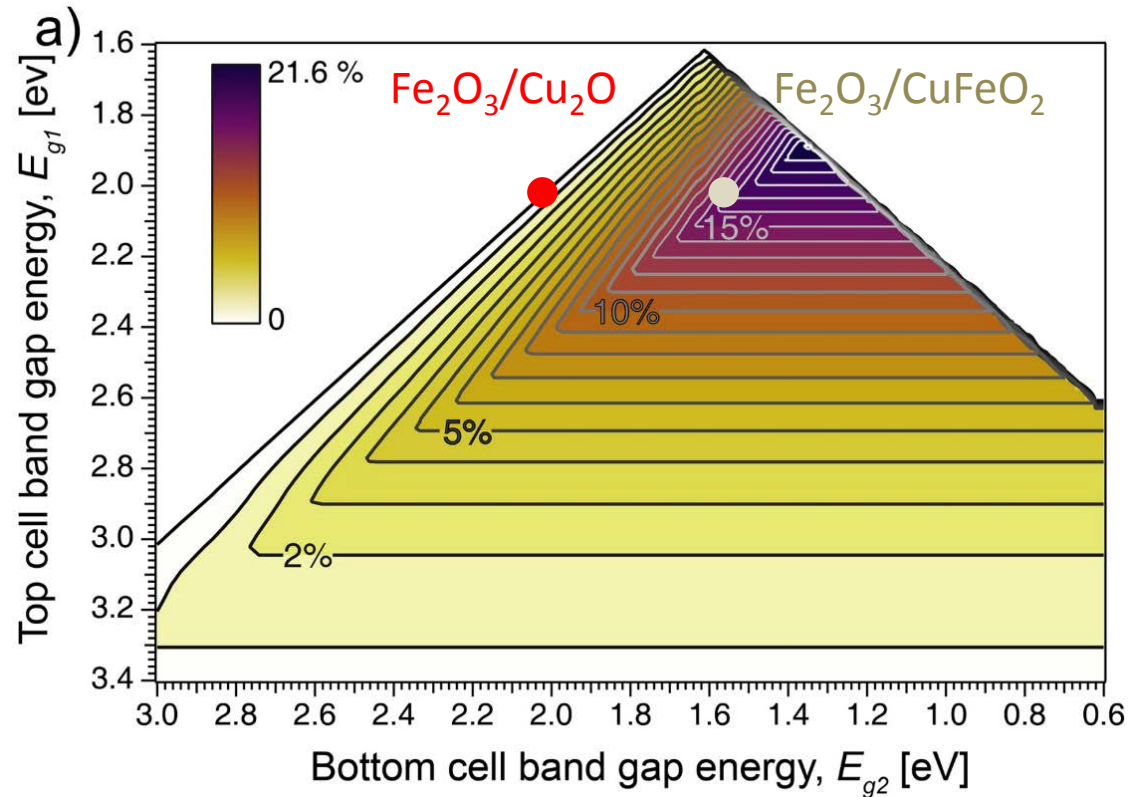
# Photoanode/photocathode tandem cells



## Delafossites



*Thin Solid Films*, 2006, 496, 146.



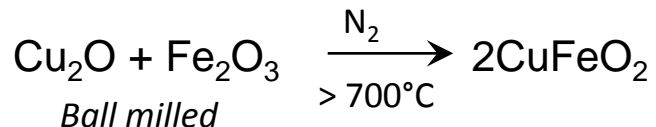
Advantages  
of  $\text{CuFeO}_2$

- Strong light absorption (Band-gap 1.5 eV)
- Made of inexpensive materials
- Robust, high stability (protection not needed)
- $E_{fb}$ : +0.95-1.01V vs RHE

Weakness  $\rightarrow$  Difficulties in processing

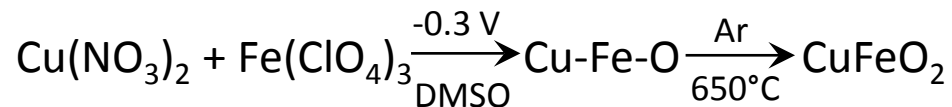
# CuFeO<sub>2</sub> preparation: *the prospect of solution processability*

## Solid state reaction



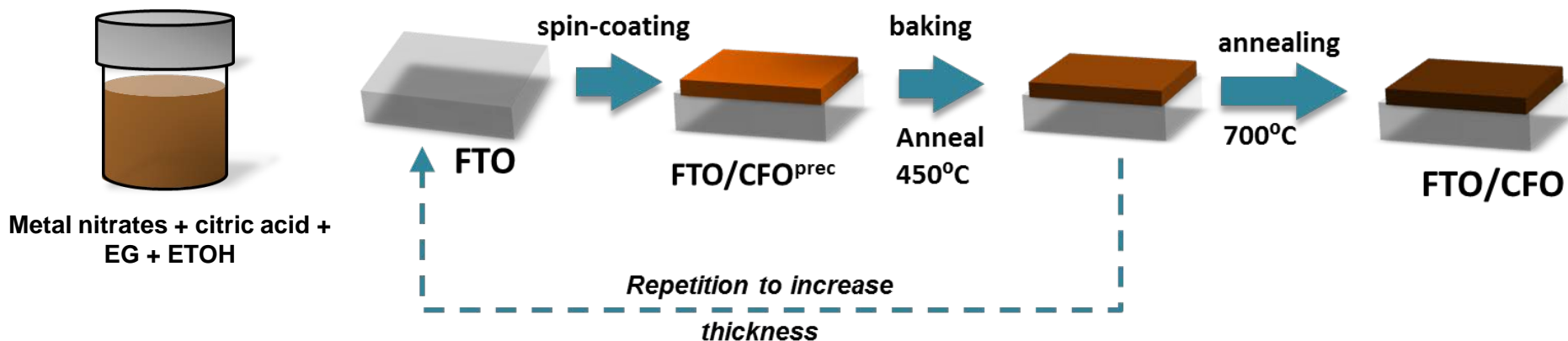
*Difficult processing of the CuFeO<sub>2</sub> powder for preparing films*

## Electrodeposition



*Electrode thickness limited by the electroactivity of the substrate and deposited precursor*

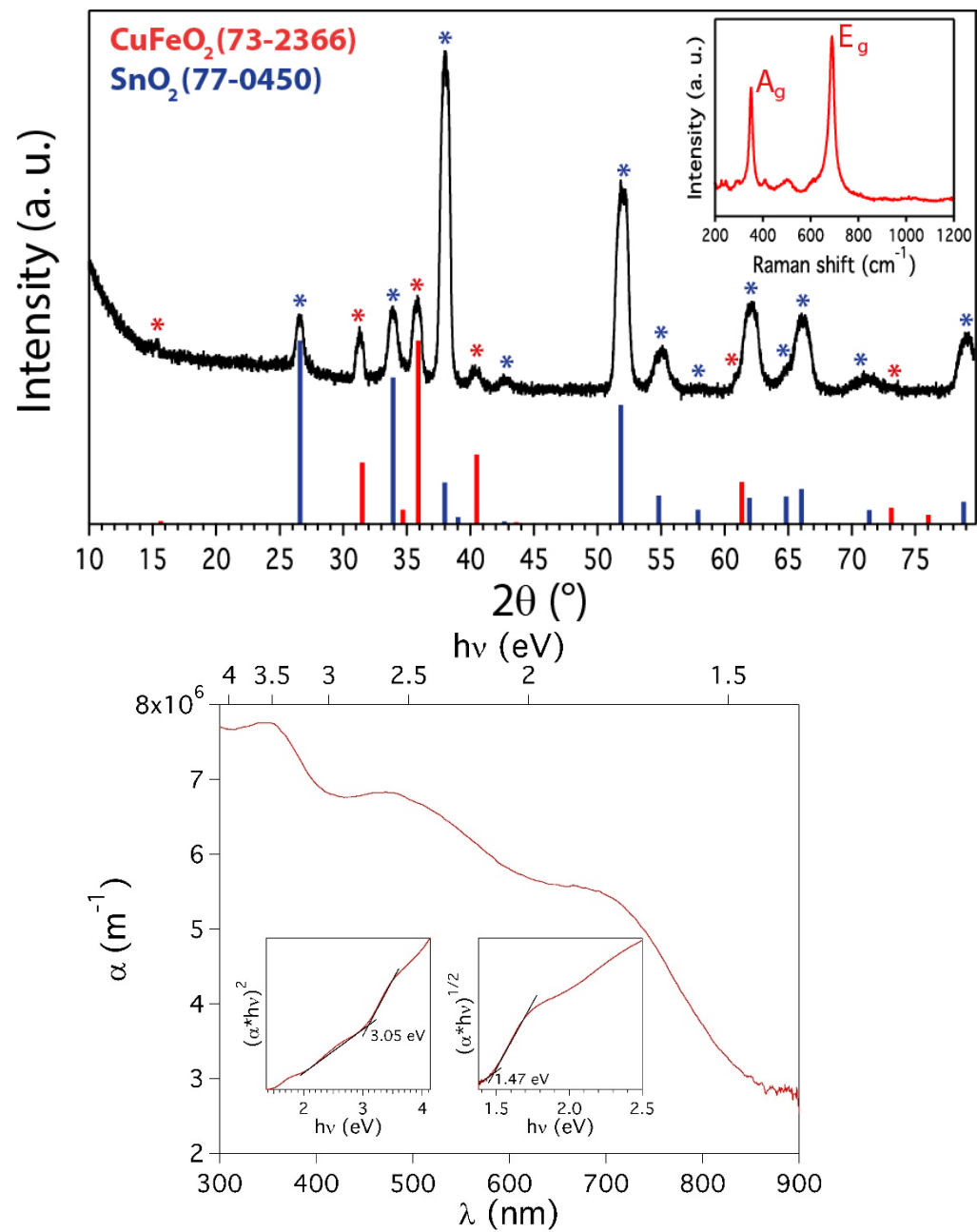
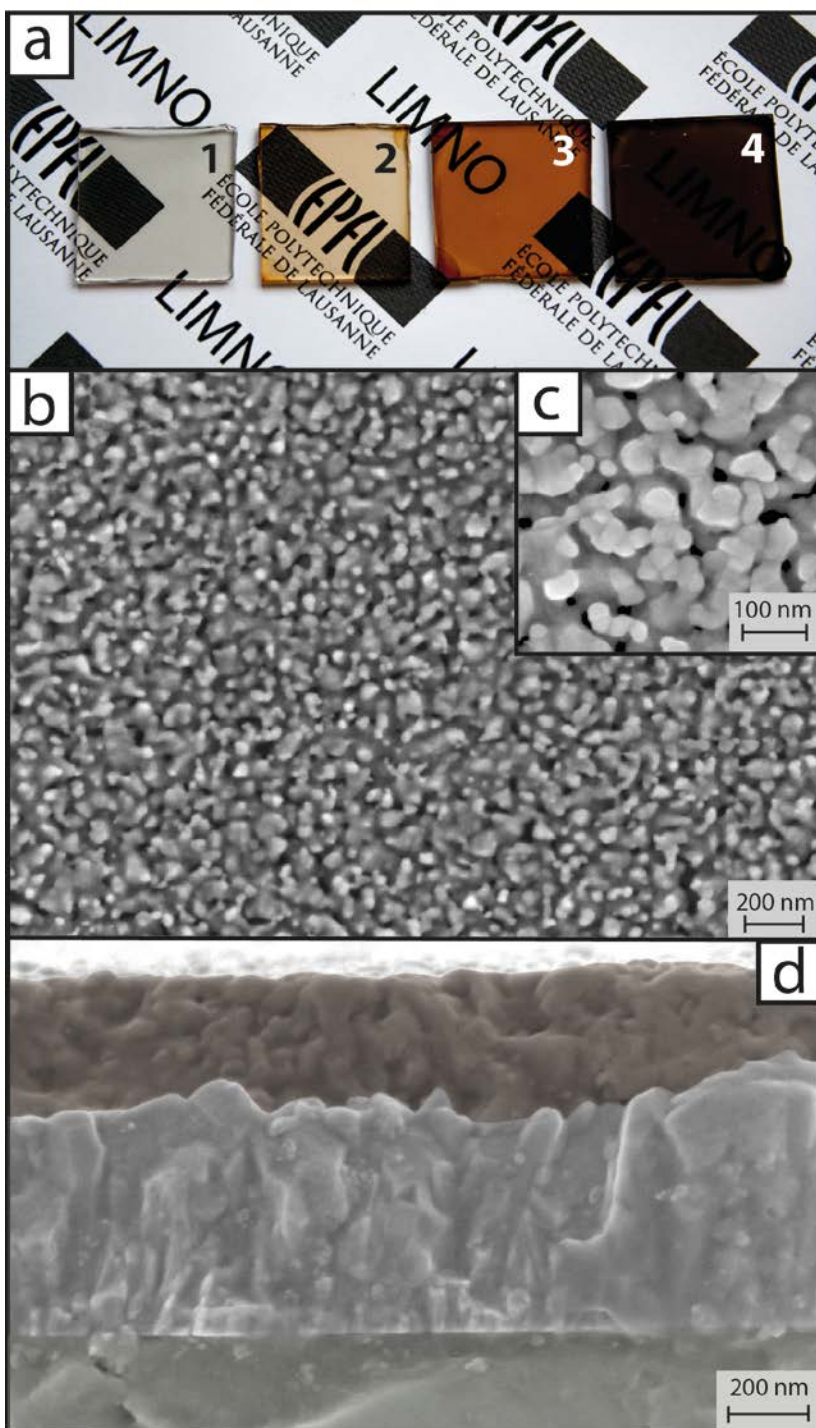
## SOL-GEL approach



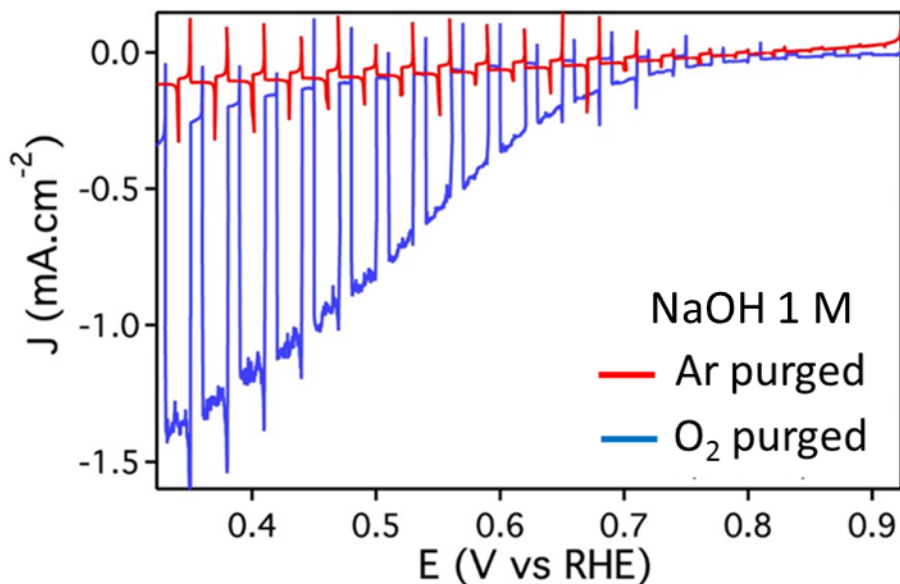
*Straightforward scaled up, solution processable and easy control on the film thickness*



# CuFeO<sub>2</sub> characterization



# CuFeO<sub>2</sub> PEC performance



## Optimum 6-layer sample

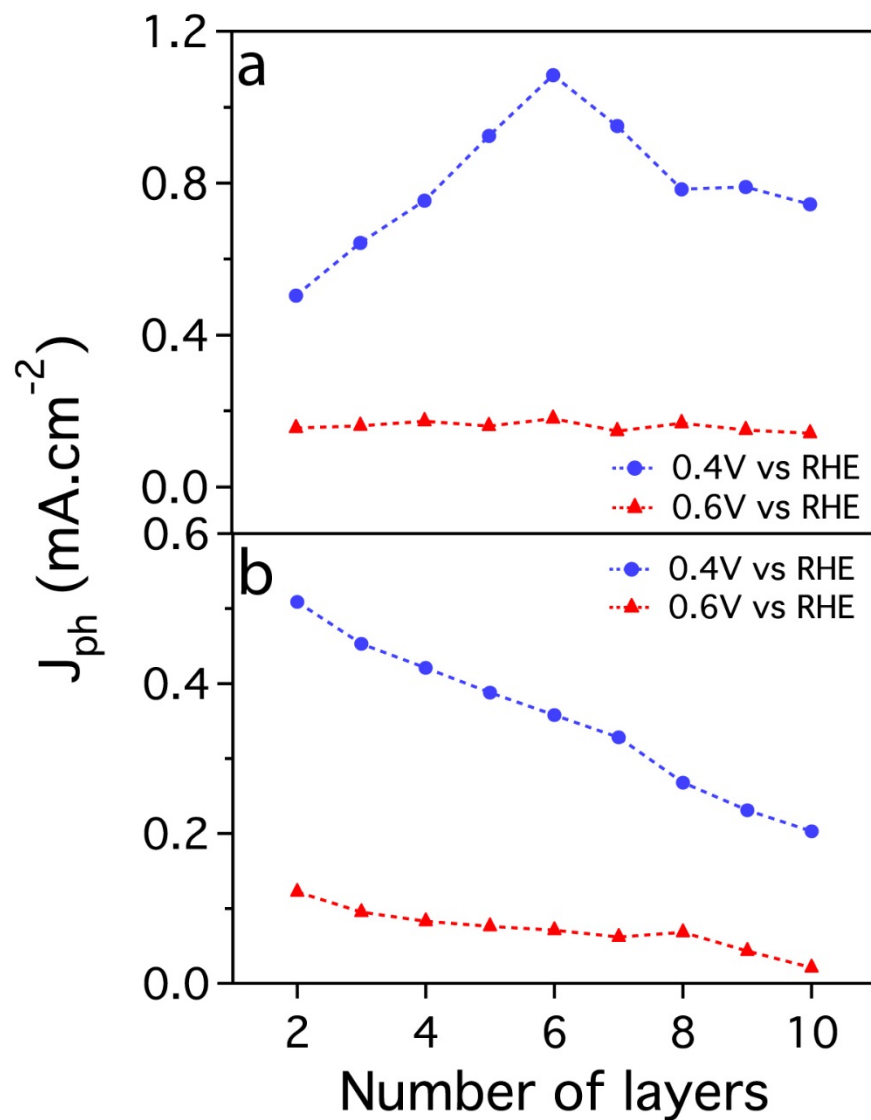
### Ar-purged electrolyte

- Poor charge injection into electrolyte
- Surface modification with co-catalyst is necessary

### With O<sub>2</sub> (good electron scavenger)

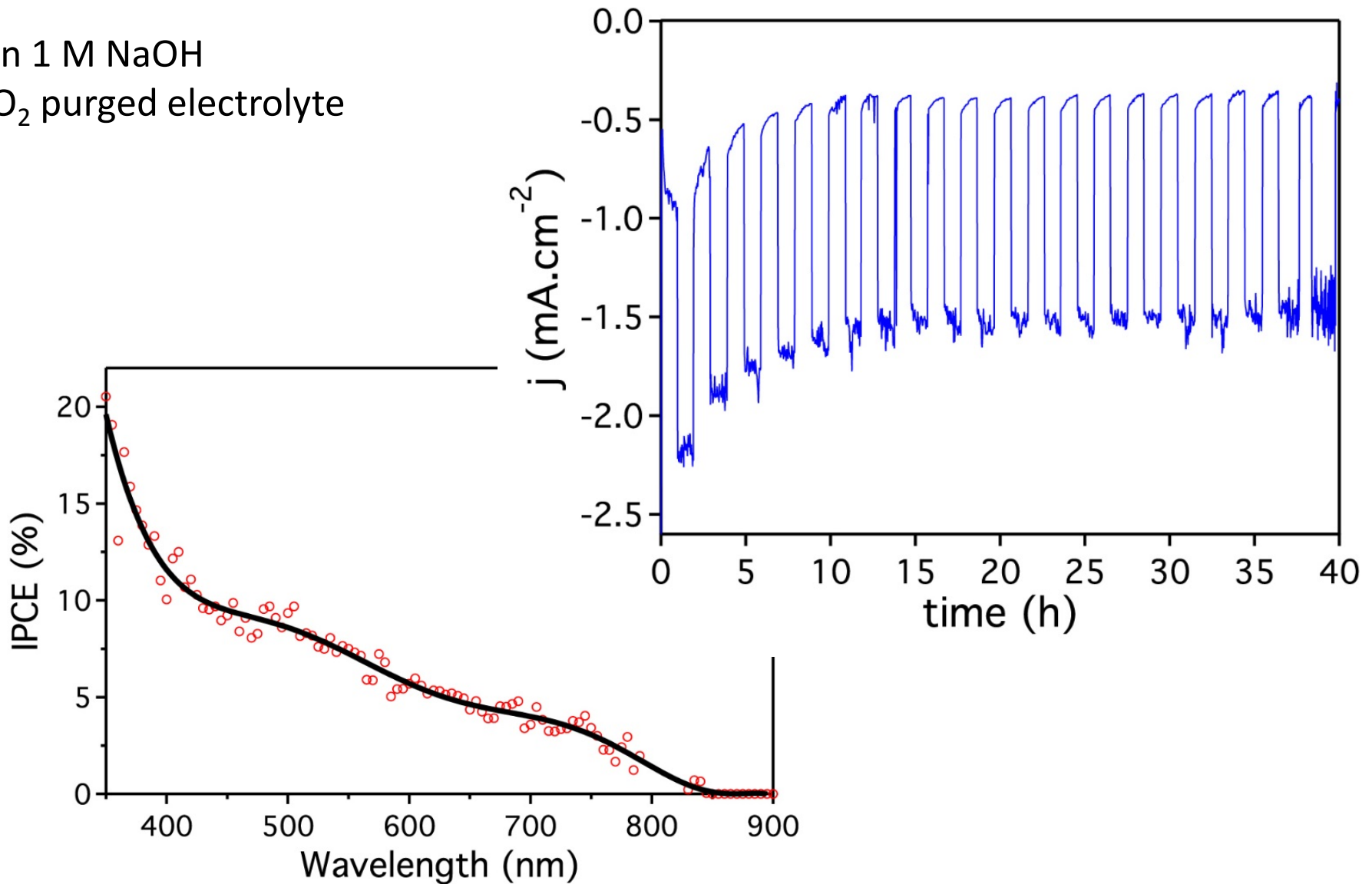
- Photocurrents larger than 1.0 mA cm<sup>-2</sup> at 0.4 V vs RHE

Onset photocurrent of 0.9 V vs RHE

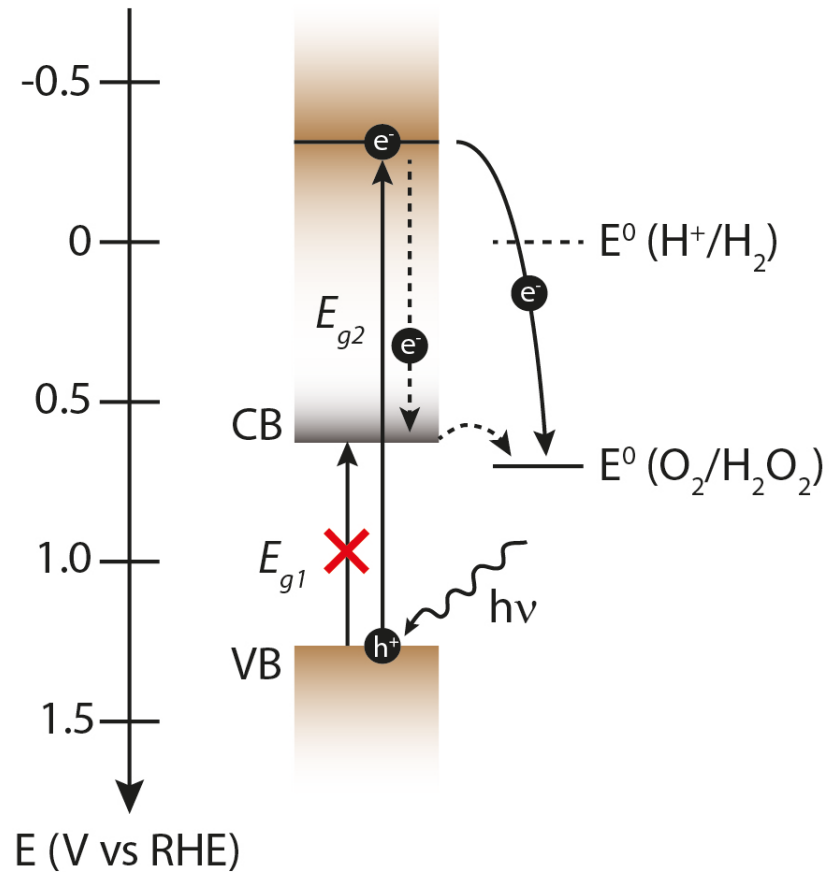
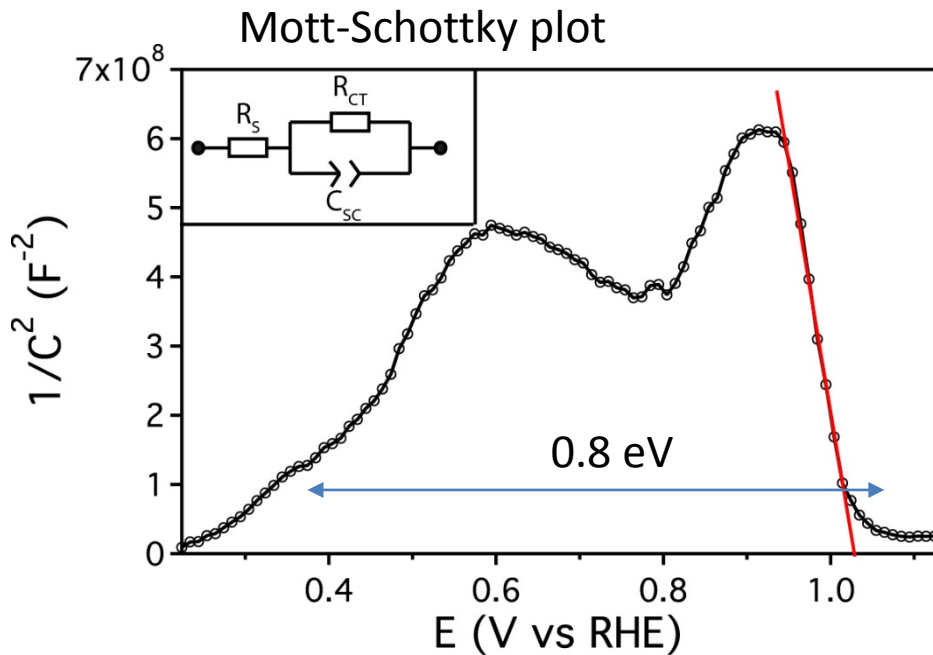


# CuFeO<sub>2</sub> PEC performance

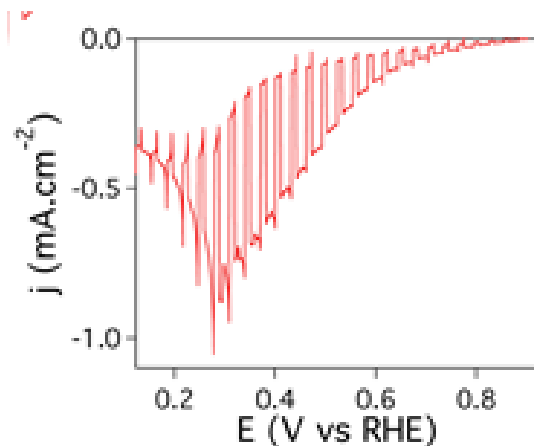
In 1 M NaOH  
O<sub>2</sub> purged electrolyte



# CuFeO<sub>2</sub> Electronic structure



Anomalous photocurrent behavior



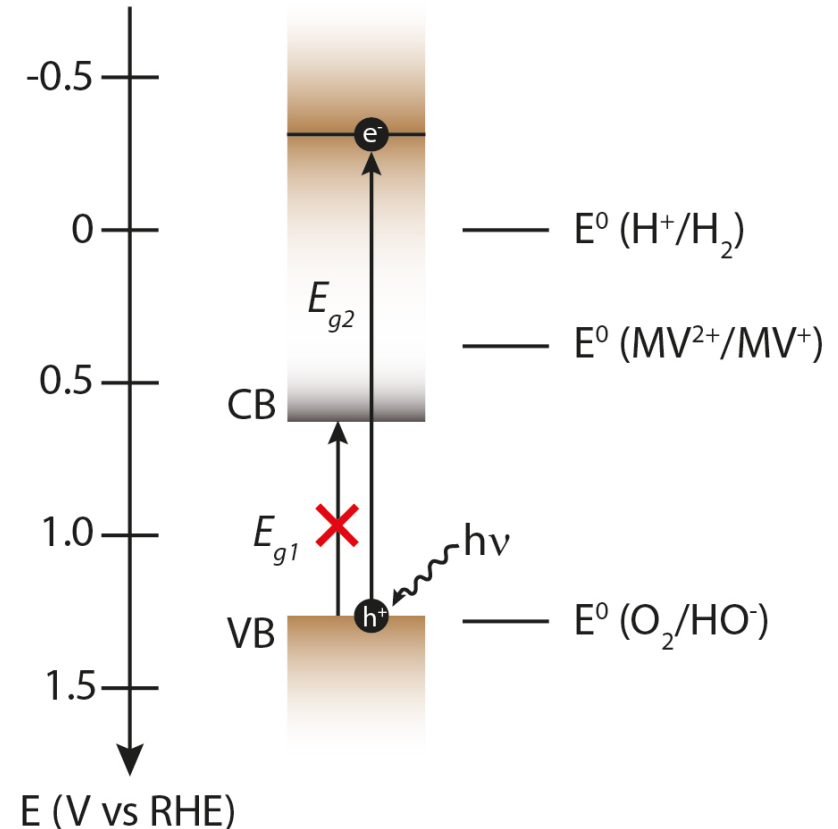
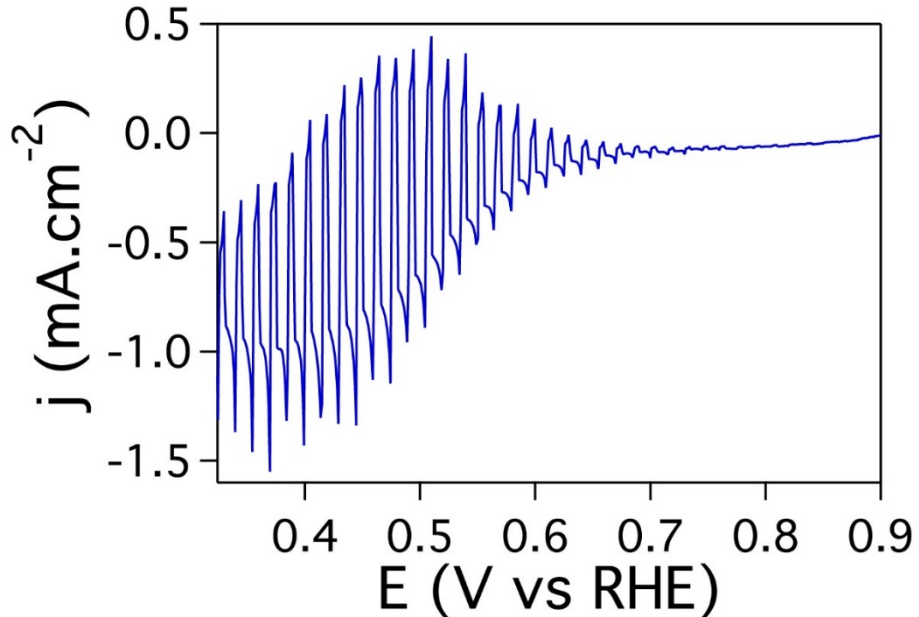
**Optically forbidden gap previously predicted by DFT calculations**

K. P. Ong, K. Bai, P. Blaha and P. Wu, *Chemistry of Materials*, 2007, **19**, 634-640.

# CuFeO<sub>2</sub> Electronic structure

With MV<sup>2+</sup> (Methyl viologen)

Ar purged electrolyte



## CuFeO<sub>2</sub> conclusions

- Feasible solution-based approach for preparing p-type CuFeO<sub>2</sub> photocathodes.
- **Highly robust**, onset at **+0.9 V vs RHE**, photocurrent above 1 mAcm<sup>-2</sup> at 0.4 V<sub>vs RHE</sub>
- Low photocurrent in absence of electron scavenger (Mv<sup>2+</sup> or O<sub>2</sub>)
- Improve performance by extrinsic doping or nanostructuring



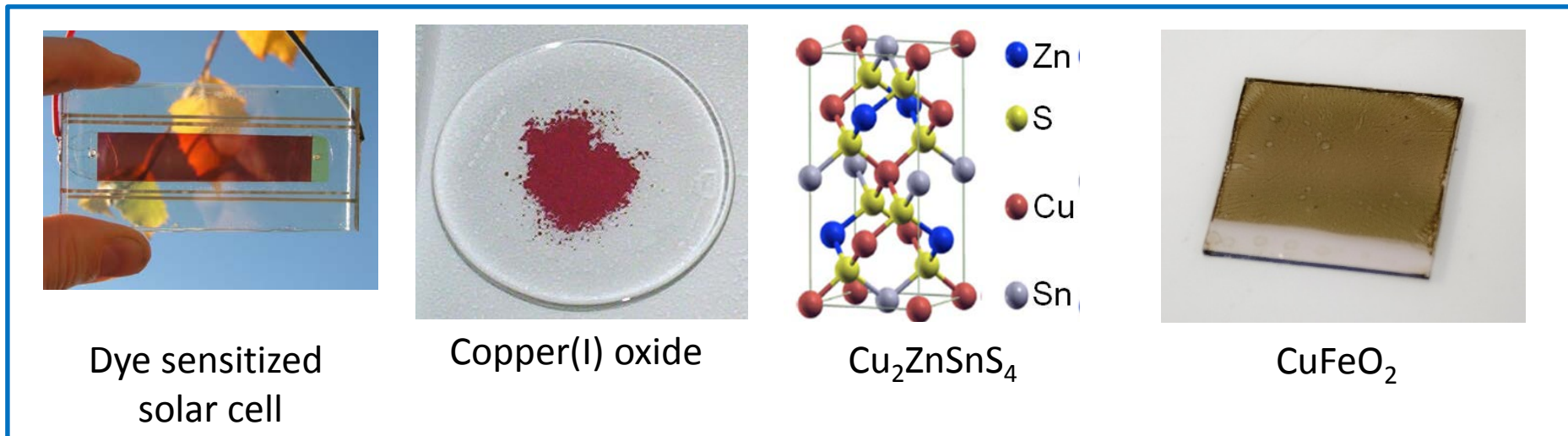
# Materials for the tandem cell

## Photoanode



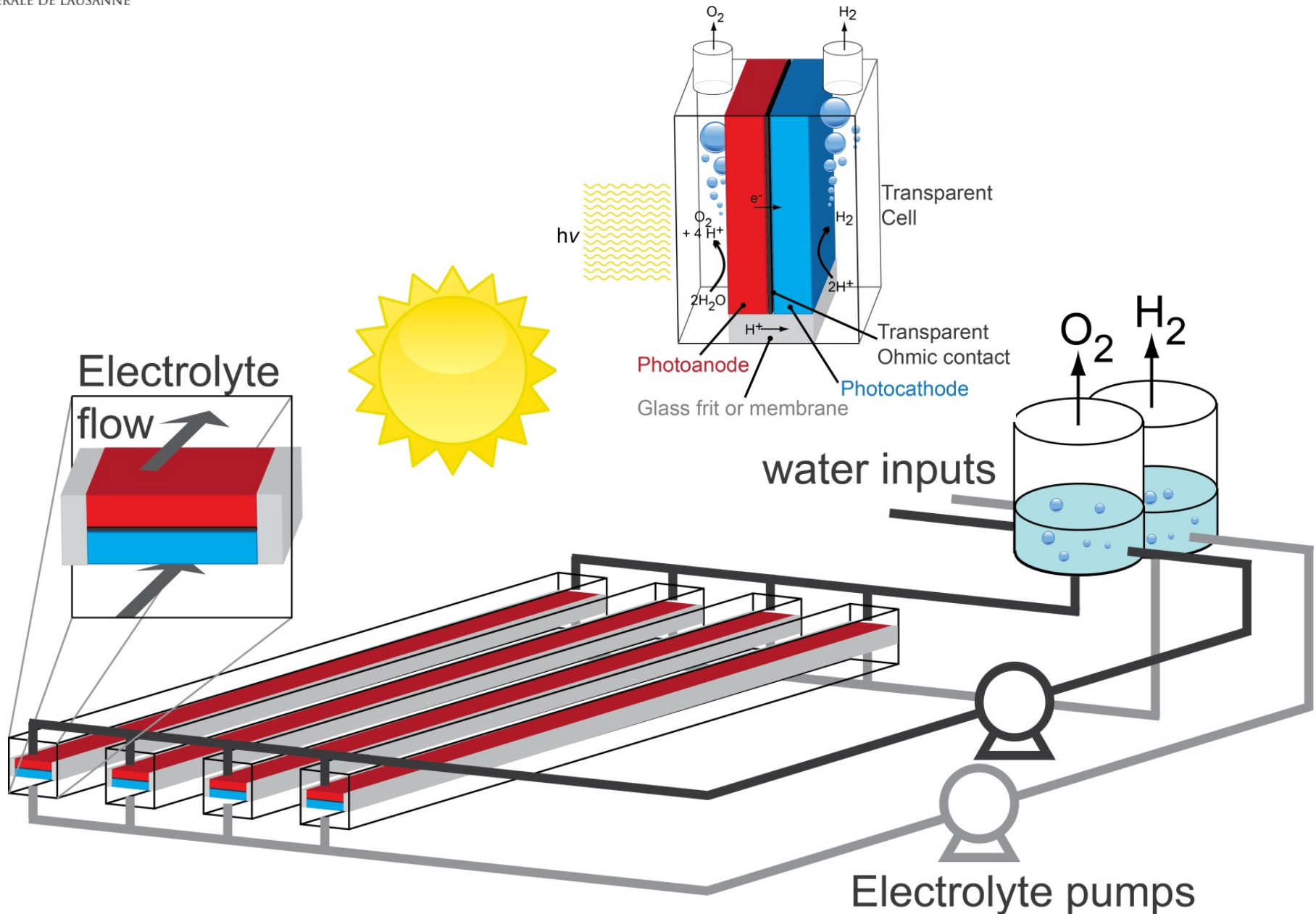
Solution based  
processing  
Cost = \$10/m<sup>2</sup>

## Photocathode





# Scalable energy conversion systems



# Acknowledgements

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M. Gratzel (LPI)

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- Takashi Hisatomi

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- Elijah Thimsen (UMN)
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